

PIC16C5X

EPROM/ROM-Based 8-bit CMOS Microcontroller Series

Devices Included in this Data Sheet:

- PIC16C54
- PIC16CR54
- PIC16C55
- PIC16C56
- PIC16CR56
- PIC16C57
- PIC16CR57
- PIC16C58
- PIC16CR58

Note:	PIC16C5X refers to all revisions of the part								
	(i.e., PIC16C54 refers to PIC16C54,								
	PIC16C54A, and PIC16C54C), unless								
	specifically called out otherwise.								

High-Performance RISC CPU:

- Only 33 single word instructions to learn
- All instructions are single cycle except for program branches which are two-cycle
- Operating speed: DC 40 MHz clock input DC - 100 ns instruction cycle

Device	Pins	I/O	EPROM/ ROM	RAM
PIC16C54	18	12	512	25
PIC16C54A	18	12	512	25
PIC16C54C	18	12	512	25
PIC16CR54A	18	12	512	25
PIC16CR54C	18	12	512	25
PIC16C55	28	20	512	24
PIC16C55A	28	20	512	24
PIC16C56	18	12	1K	25
PIC16C56A	18	12	1K	25
PIC16CR56A	18	12	1K	25
PIC16C57	28	20	2K	72
PIC16C57C	28	20	2K	72
PIC16CR57C	28	20	2K	72
PIC16C58B	18	12	2K	73
PIC16CR58B	18	12	2K	73

- 12-bit wide instructions
- 8-bit wide data path
- · Seven or eight special function hardware registers
- Two-level deep hardware stack
- Direct, indirect and relative addressing modes for data and instructions

Peripheral Features:

- 8-bit real time clock/counter (TMR0) with 8-bit programmable prescaler
- Power-on Reset (POR)
- Device Reset Timer (DRT)
- Watchdog Timer (WDT) with its own on-chip RC oscillator for reliable operation
- Programmable Code Protection
- Power saving SLEEP mode
- Selectable oscillator options:
 - RC: Low cost RC oscillator
 - XT: Standard crystal/resonator
 - HS: High speed crystal/resonator
 - LP: Power saving, low frequency crystal

CMOS Technology:

- Low power, high speed CMOS EPROM/ROM technology
- Fully static design
- Wide operating voltage and temperature range:
 - EPROM Commercial/Industrial 2.0V to 6.25V
 - ROM Commercial/Industrial 2.0V to 6.25V
 - EPROM Extended 2.5V to 6.0V
 - ROM Extended 2.5V to 6.0V
- Low power consumption
 - < 2 mA typical @ 5V, 4 MHz
 - 15 μA typical @ 3V, 32 kHz
 - < 0.6 μA typical standby current (with WDT disabled) @ 3V, 0°C to 70°C

Note: In this document, figure and table titles refer to all varieties of the part number indicated, (i.e., The title "Figure 15-1: Load Conditions For Device Timing Specifications - PIC16C54A", also refers to PIC16LC54A and PIC16LV54A parts), unless specifically called out otherwise.

Pin Diagrams



Device Differences

Device	Voltage Range	Oscillator Selection (Program)	Oscillator	Process Technology (Microns)	ROM Equivalent	MCLR Filter
PIC16C54	2.5-6.25	Factory	See Note 1	1.2	PIC16CR54A	No
PIC16C54A	2.0-6.25	User	See Note 1	0.9	—	No
PIC16C54C	2.5-5.5	User	See Note 1	0.7	PIC16CR54C	Yes
PIC16C55	2.5-6.25	Factory	See Note 1	1.7	—	No
PIC16C55A	2.5-5.5	User	See Note 1	0.7	—	Yes
PIC16C56	2.5-6.25	Factory	See Note 1	1.7	—	No
PIC16C56A	2.5-5.5	User	See Note 1	0.7	PIC16CR56A	Yes
PIC16C57	2.5-6.25	Factory	See Note 1	1.2	—	No
PIC16C57C	2.5-5.5	User	See Note 1	0.7	PIC16CR57C	Yes
PIC16C58B	2.5-5.5	User	See Note 1	0.7	PIC16CR58B	Yes
PIC16CR54A	2.5-6.25	Factory	See Note 1	1.2	N/A	Yes
PIC16CR54C	2.5-5.5	Factory	See Note 1	0.7	N/A	Yes
PIC16CR56A	2.5-5.5	Factory	See Note 1	0.7	N/A	Yes
PIC16CR57C	2.5-5.5	Factory	See Note 1	0.7	N/A	Yes
PIC16CR58B	2.5-5.5	Factory	See Note 1	0.7	N/A	Yes

Note 1: If you change from this device to another device, please verify oscillator characteristics in your application.

Note: The table shown above shows the generic names of the PIC16C5X devices. For device varieties, please refer to Section 2.0.

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NOTES:



PIC16C5X

8-Bit EPROM/ROM-Based CMOS Microcontrollers

1.0 GENERAL DESCRIPTION

The PIC16C5X from Microchip Technology is a family of low cost, high performance, 8-bit fully static, EPROM/ROM-based CMOS microcontrollers. It employs a RISC architecture with only 33 single word/ single cycle instructions. All instructions are single cycle except for program branches which take two cycles. The PIC16C5X delivers performance in an order of magnitude higher than its competitors in the same price category. The 12-bit wide instructions are highly symmetrical resulting in 2:1 code compression over other 8-bit microcontrollers in its class. The easy to use and easy to remember instruction set reduces development time significantly.

The PIC16C5X products are equipped with special features that reduce system cost and power requirements. The Power-on Reset (POR) and Device Reset Timer (DRT) eliminate the need for external RESET circuitry. There are four oscillator configurations to choose from, including the power saving LP (Low Power) oscillator and cost saving RC oscillator. Power saving SLEEP mode, Watchdog Timer and Code Protection features improve system cost, power and reliability.

The UV erasable CERDIP packaged versions are ideal for code development, while the cost effective One Time Programmable (OTP) versions are suitable for production in any volume. The customer can take full advantage of Microchip's price leadership in OTP microcontrollers, while benefiting from the OTP's flexibility.

The PIC16C5X products are supported by a full featured macro assembler, a software simulator, an in-circuit emulator, a low cost development programmer and a full featured programmer. All the tools are supported on IBM[®] PC and compatible machines.

1.1 Applications

The PIC16C5X series fits perfectly in applications ranging from high speed automotive and appliance motor control to low power remote transmitters/receivers, pointing devices and telecom processors. The EPROM technology makes customizing application programs (transmitter codes, motor speeds, receiver frequencies, etc.) extremely fast and convenient. The small footprint packages, for through hole or surface mounting, make this microcontroller series perfect for applications with space limitations. Low cost, low power, high performance ease of use and I/O flexibility make the PIC16C5X series very versatile even in areas where no microcontroller use has been considered before (e.g., timer functions, replacement of "glue" logic in larger systems, co-processor applications).

TABLE 1-1: PIC16C5X FAMILY OF DEVICES

Features	PIC16C54	PIC16CR54	PIC16C55	PIC16C56	PIC16CR56
Maximum Operation Frequency	40 MHz	20 MHz	40 MHz	40 MHz	20 MHz
EPROM Program Memory (x12 words)	512	_	512	1K	
ROM Program Memory (x12 words)		512	_	_	1K
RAM Data Memory (bytes)	25	25	24	25	25
Timer Module(s)	TMR0	TMR0	TMR0	TMR0	TMR0
I/O Pins	12	12	20	12	12
Number of Instructions	33	33	33	33	33
Packages	18-pin DIP, SOIC; 20-pin SSOP	18-pin DIP, SOIC; 20-pin SSOP	28-pin DIP, SOIC; 28-pin SSOP	18-pin DIP, SOIC; 20-pin SSOP	18-pin DIP, SOIC; 20-pin SSOP

PIC16C58 Features **PIC16C57** PIC16CR57 PIC16CR58 Maximum Operation Frequency 20 MHz 40 MHz 40 MHz 20 MHz EPROM Program Memory (x12 words) 2K 2K ____ _ ROM Program Memory (x12 words) 2K 2K _ _ RAM Data Memory (bytes) 72 72 73 73 Timer Module(s) TMR0 TMR0 TMR0 TMR0 I/O Pins 20 20 12 12 Number of Instructions 33 33 33 33 28-pin DIP, SOIC; 28-pin DIP, SOIC; 18-pin DIP, SOIC; 18-pin DIP, SOIC; Packages 28-pin SSOP 28-pin SSOP 20-pin SSOP 20-pin SSOP All PIC® Family devices have Power-on Reset, selectable Watchdog Timer, selectable Code Protect and high I/O current capability.

2.0 PIC16C5X DEVICE VARIETIES

A variety of frequency ranges and packaging options are available. Depending on application and production requirements, the proper device option can be selected using the information in this section. When placing orders, please use the PIC16C5X Product Identification System at the back of this data sheet to specify the correct part number.

For the PIC16C5X family of devices, there are four device types, as indicated in the device number:

- 1. **C**, as in PIC16**C**54C. These devices have EPROM program memory and operate over the standard voltage range.
- LC, as in PIC16LC54A. These devices have EPROM program memory and operate over an extended voltage range.
- 3. **CR**, as in PIC16**CR**54A. These devices have ROM program memory and operate over the standard voltage range.
- 4. LCR, as in PIC16LCR54A. These devices have ROM program memory and operate over an extended voltage range.

2.1 UV Erasable Devices (EPROM)

The UV erasable versions offered in CERDIP packages, are optimal for prototype development and pilot programs.

UV erasable devices can be programmed for any of the four oscillator configurations. Microchip's

PICSTART[®] Plus⁽¹⁾ and PRO MATE[®] programmers both support programming of the PIC16C5X. Third party programmers also are available. Refer to the Third Party Guide (DS00104) for a list of sources.

2.2 One-Time-Programmable (OTP) Devices

The availability of OTP devices is especially useful for customers expecting frequent code changes and updates, or small volume applications.

The OTP devices, packaged in plastic packages, permit the user to program them once. In addition to the program memory, the configuration bits must be programmed.

Note 1: PIC16LC54C and PIC16C54A devices require OSC2 not to be connected while programming with PICSTART[®] Plus programmer.

2.3 Quick-Turnaround-Production (QTP) Devices

Microchip offers a QTP Programming Service for factory production orders. This service is made available for users who choose not to program a medium to high quantity of units and whose code patterns have stabilized. The devices are identical to the OTP devices but with all EPROM locations and configuration bit options already programmed by the factory. Certain code and prototype verification procedures apply before production shipments are available. Please contact your Microchip Technology sales office for more details.

2.4 Serialized Quick-Turnaround-Production (SQTPSM) Devices

Microchip offers the unique programming service where a few user defined locations in each device are programmed with different serial numbers. The serial numbers may be random, pseudo-random or sequential. The devices are identical to the OTP devices but with all EPROM locations and configuration bit options already programmed by the factory.

Serial programming allows each device to have a unique number which can serve as an entry code, password or ID number.

2.5 Read Only Memory (ROM) Devices

Microchip offers masked ROM versions of several of the highest volume parts, giving the customer a low cost option for high volume, mature products. NOTES:

3.0 ARCHITECTURAL OVERVIEW

The high performance of the PIC16C5X family can be attributed to a number of architectural features commonly found in RISC microprocessors. To begin with, the PIC16C5X uses a Harvard architecture in which program and data are accessed on separate buses. This improves bandwidth over traditional von Neumann architecture where program and data are fetched on the same bus. Separating program and data memory further allows instructions to be sized differently than the 8-bit wide data word. Instruction opcodes are 12 bits wide making it possible to have all single word instructions. A 12-bit wide program memory access bus fetches a 12-bit instruction in a single cycle. A twostage pipeline overlaps fetch and execution of instructions. Consequently, all instructions (33) execute in a single cycle except for program branches.

The PIC16C54/CR54 and PIC16C55 address 512 x 12 of program memory, the PIC16C56/CR56 address 1K x 12 of program memory, and the PIC16C57/CR57 and PIC16C58/CR58 address 2K x 12 of program memory. All program memory is internal.

The PIC16C5X can directly or indirectly address its register files and data memory. All special function registers including the program counter are mapped in the data memory. The PIC16C5X has a highly orthogonal (symmetrical) instruction set that makes it possible to carry out any operation on any register using any addressing mode. This symmetrical nature and lack of 'special optimal situations' make programming with the PIC16C5X simple yet efficient. In addition, the learning curve is reduced significantly. The PIC16C5X device contains an 8-bit ALU and working register. The ALU is a general purpose arithmetic unit. It performs arithmetic and Boolean functions between data in the working register and any register file.

The ALU is 8 bits wide and capable of addition, subtraction, shift and logical operations. Unless otherwise mentioned, arithmetic operations are two's complement in nature. In two-operand instructions, typically one operand is the W (working) register. The other operand is either a file register or an immediate constant. In single operand instructions, the operand is either the W register or a file register.

The W register is an 8-bit working register used for ALU operations. It is not an addressable register.

Depending on the instruction executed, the ALU may affect the values of the Carry (C), Digit Carry (DC), and Zero (Z) bits in the STATUS register. The C and DC bits operate as a borrow and digit borrow out bit, respectively, in subtraction. See the SUBWF and ADDWF instructions for examples.

A simplified block diagram is shown in Figure 3-1, with the corresponding device pins described in Table 3-1 (for PIC16C54/56/58) and Table 3-2 (for PIC16C55/57).



FIGURE 3-1: PIC16C5X SERIES BLOCK DIAGRAM

Pi	n Numb	er	Pin	Buffer	Description	
DIP	SOIC	SSOP	Туре	Туре	Description	
17	17	19	I/O	TTL	Bi-directional I/O port	
18	18	20	I/O	TTL		
1	1	1	I/O	TTL		
2	2	2	I/O	TTL		
6	6	7	I/O	TTL	Bi-directional I/O port	
7	7	8	I/O	TTL		
8	8	9	I/O	TTL		
9	9	10	I/O	TTL		
10	10	11	I/O	TTL		
11	11	12	I/O	TTL		
12	12	13	I/O	TTL		
13	13	14	I/O	TTL		
3	3	3	Ι	ST	Clock input to Timer0. Must be tied to Vss or VDD, if not in	
					use, to reduce current consumption.	
4	4	4	Ι	ST	Master clear (RESET) input/programming voltage input.	
					This pin is an active low RESET to the device. Voltage on	
					the MCLR/VPP pin must not exceed VDD to avoid unin-	
					tended entering of Programming mode.	
16	16	18	I	ST	Oscillator crystal input/external clock source input.	
15	15	17	0	_	Oscillator crystal output. Connects to crystal or resonator	
					in crystal Oscillator mode. In RC mode, OSC2 pin outputs	
					CLKOUT, which has 1/4 the frequency of OSC1 and	
					denotes the instruction cycle rate.	
14	14	15,16	Р	_	Positive supply for logic and I/O pins.	
5	5	5,6	Р	—	Ground reference for logic and I/O pins.	
	Pi DIP 17 18 1 2 6 7 8 9 10 11 12 13 3 4 16 15 14	Pin Numb DIP SOIC 17 17 18 18 1 1 2 2 6 6 7 7 8 8 9 9 10 10 11 11 12 12 13 13 3 3 4 4 16 16 15 15 14 14	Pin Number DIP SOIC SSOP 17 17 19 18 18 20 1 1 1 2 2 2 6 6 7 7 7 8 8 8 9 9 9 10 10 10 11 11 11 12 12 12 13 13 13 14 3 3 3 4 4 4 15 15 17 14 14 15,16	Pin Pin DIP SOIC SSOP Type 17 17 19 I/O 18 18 20 I/O 1 1 1 I/O 2 2 2 I/O 6 6 7 I/O 7 7 8 I/O 8 9 I/O I/O 9 9 10 I/O 10 10 11 I/O 11 11 12 I/O 12 12 13 I/O 13 13 14 I/O 3 3 3 I 16 16 18 I 15 15 17 O 14 14 15,16 P	Pin Buffer DIP SOIC SSOP Type Type 17 17 19 I/O TTL 18 18 20 I/O TTL 1 1 1/O TTL 2 2 2 I/O TTL 6 6 7 I/O TTL 7 7 8 I/O TTL 9 9 10 I/O TTL 10 10 11 I/O TTL 11 11 12 I/O TTL 9 9 10 I/O TTL 10 10 11 I/O TTL 12 12 13 I/O TTL 13 13 14 I/O TTL 3 3 3 I ST 16 16 18 I ST 15 15 17 <td< td=""></td<>	

TABLE 3-1:PINOUT DESCRIPTION - PIC16C54, PIC16CR54, PIC16C56, PIC16CR56, PIC16CR58,
PIC16CR58

Legend: I = input, O = output, I/O = input/output, P = power, — = Not Used, TTL = TTL input, ST = Schmitt Trigger input

Pin Name	Pin Number			Pin	Buffer	Description
Pin Name	DIP	SOIC	SSOP	Туре	Туре	Description
RA0	6	6	5	I/O	TTL	Bi-directional I/O port
RA1	7	7	6	I/O	TTL	
RA2	8	8	7	I/O	TTL	
RA3	9	9	8	I/O	TTL	
RB0	10	10	9	I/O	TTL	Bi-directional I/O port
RB1	11	11	10	I/O	TTL	
RB2	12	12	11	I/O	TTL	
RB3	13	13	12	I/O	TTL	
RB4	14	14	13	I/O	TTL	
RB5	15	15	15	I/O	TTL	
RB6	16	16	16	I/O	TTL	
RB7	17	17	17	I/O	TTL	
RC0	18	18	18	I/O	TTL	Bi-directional I/O port
RC1	19	19	19	I/O	TTL	
RC2	20	20	20	I/O	TTL	
RC3	21	21	21	I/O	TTL	
RC4	22	22	22	I/O	TTL	
RC5	23	23	23	I/O	TTL	
RC6	24	24	24	I/O	TTL	
RC7	25	25	25	I/O	TTL	
TOCKI	1	1	2	Ι	ST	Clock input to Timer0. Must be tied to Vss or VDD, if not in use, to reduce current consumption.
MCLR	28	28	28	I	ST	Master clear (RESET) input. This pin is an active low RESET to the device.
OSC1/CLKIN	27	27	27	I	ST	Oscillator crystal input/external clock source input.
OSC2/CLKOUT	26	26	26	0	_	Oscillator crystal output. Connects to crystal or resonator in crystal Oscillator mode. In RC mode, OSC2 pin outputs CLKOUT which has 1/4 the frequency of OSC1, and denotes the instruction cycle rate.
Vdd	2	2	3,4	Р	_	Positive supply for logic and I/O pins.
Vss	4	4	1,14	Р		Ground reference for logic and I/O pins.
N/C	3,5	3,5		_		Unused, do not connect.

TABLE 3-2: PINOUT DESCRIPTION - PIC16C55, PIC16C57, PIC16CR57

Legend: I = input, O = output, I/O = input/output, P = power, — = Not Used, TTL = TTL input, ST = Schmitt Trigger input

3.1 **Clocking Scheme/Instruction** Cycle

The clock input (OSC1/CLKIN pin) is internally divided by four to generate four non-overlapping quadrature clocks, namely Q1, Q2, Q3 and Q4. Internally, the program counter is incremented every Q1 and the instruction is fetched from program memory and latched into the instruction register in Q4. It is decoded and executed during the following Q1 through Q4. The clocks and instruction execution flow are shown in Figure 3-2 and Example 3-1.

3.2 Instruction Flow/Pipelining

An Instruction Cycle consists of four Q cycles (Q1, Q2, Q3 and Q4). The instruction fetch and execute are pipelined such that fetch takes one instruction cycle, while decode and execute takes another instruction cycle. However, due to the pipelining, each instruction effectively executes in one cycle. If an instruction causes the program counter to change (e.g., GOTO), then two cycles are required to complete the instruction (Example 3-1).

A fetch cycle begins with the program counter (PC) incrementing in Q1.

In the execution cycle, the fetched instruction is latched into the Instruction Register in cycle Q1. This instruction is then decoded and executed during the Q2, Q3 and Q4 cycles. Data memory is read during Q2 (operand read) and written during Q4 (destination write).



FIGURE 3-2: **CLOCK/INSTRUCTION CYCLE**

EXAMPLE 3-1: INSTRUCTION PIPELINE FLOW



is "flushed" from the pipeline, while the new instruction is being fetched and then executed.

NOTES:

4.0 OSCILLATOR CONFIGURATIONS

4.1 Oscillator Types

PIC16C5Xs can be operated in four different oscillator modes. The user can program two configuration bits (FOSC1:FOSC0) to select one of these four modes:

- 1. LP: Low Power Crystal
- 2. XT: Crystal/Resonator
- 3. HS: High Speed Crystal/Resonator
- 4. RC: Resistor/Capacitor

Note: Not all oscillator selections available for all parts. See Section 9.1.

4.2 Crystal Oscillator/Ceramic Resonators

In XT, LP or HS modes, a crystal or ceramic resonator is connected to the OSC1/CLKIN and OSC2/CLKOUT pins to establish oscillation (Figure 4-1). The PIC16C5X oscillator design requires the use of a parallel cut crystal. Use of a series cut crystal may give a frequency out of the crystal manufacturers specifications. When in XT, LP or HS modes, the device can have an external clock source drive the OSC1/CLKIN pin (Figure 4-2).

FIGURE 4-1: CRYSTAL/CERAMIC RESONATOR OPERATION (HS, XT OR LP OSC CONFIGURATION)



FIGURE 4-2:

EXTERNAL CLOCK INPUT OPERATION (HS, XT OR LP OSC CONFIGURATION)



TABLE 4-1: CAPACITOR SELECTION FOR CERAMIC RESONATORS -PIC16C5X, PIC16CR5X

Osc Type	Resonator Freq	Cap. Range C1	Cap. Range C2
XT	455 kHz	68-100 pF	68-100 pF
	2.0 MHz	15-33 pF	15-33 pF
	4.0 MHz	10-22 pF	10-22 pF
HS	8.0 MHz	10-22 pF	10-22 pF
	16.0 MHz	10 pF	10 pF

These values are for design guidance only. Since each resonator has its own characteristics, the user should consult the resonator manufacturer for appropriate values of external components.

TABLE 4-2: CAPACITOR SELECTION FOR CRYSTAL OSCILLATOR -PIC16C5X. PIC16CR5X

Osc Type	Crystal Freq	Cap.Range C1	Cap. Range C2						
LP	32 kHz ⁽¹⁾	15 pF	15 pF						
XT	100 kHz	15-30 pF	200-300 pF						
	200 kHz	15-30 pF	100-200 pF						
	455 kHz	15-30 pF	15-100 pF						
	1 MHz	15-30 pF	15-30 pF						
	2 MHz	15 pF	15 pF						
	4 MHz	15 pF	15 pF						
HS	4 MHz	15 pF	15 pF						
	8 MHz	15 pF	15 pF						
	20 MHz	15 pF	15 pF						

Note 1: For VDD > 4.5V, C1 = C2 \approx 30 pF is recommended.

These values are for design guidance only. Rs may be required in HS mode as well as XT mode to avoid overdriving crystals with low drive level specification. Since each crystal has its own characteristics, the user should consult the crystal manufacturer for appropriate values of external components.

Note: If you change from this device to another device, please verify oscillator characteristics in your application.

4.3 External Crystal Oscillator Circuit

Either a prepackaged oscillator or a simple oscillator circuit with TTL gates can be used as an external crystal oscillator circuit. Prepackaged oscillators provide a wide operating range and better stability. A welldesigned crystal oscillator will provide good performance with TTL gates. Two types of crystal oscillator circuits can be used: one with parallel resonance, or one with series resonance.

Figure 4-3 shows an implementation example of a parallel resonant oscillator circuit. The circuit is designed to use the fundamental frequency of the crystal. The 74AS04 inverter performs the 180-degree phase shift that a parallel oscillator requires. The 4.7 k Ω resistor provides the negative feedback for stability. The 10 k Ω potentiometers bias the 74AS04 in the linear region. This circuit could be used for external oscillator designs.

FIGURE 4-3: EXAMPLE OF EXTERNAL PARALLEL RESONANT CRYSTAL OSCILLATOR CIRCUIT (USING XT, HS OR LP OSCILLATOR MODE)



Figure 4-4 shows a series resonant oscillator circuit. This circuit is also designed to use the fundamental frequency of the crystal. The inverter performs a 180-degree phase shift in a series resonant oscillator circuit. The 330 k Ω resistors provide the negative feedback to bias the inverters in their linear region.



4.4 RC Oscillator

For timing insensitive applications, the RC device option offers additional cost savings. The RC oscillator frequency is a function of the supply voltage, the resistor (REXT) and capacitor (CEXT) values, and the operating temperature. In addition to this, the oscillator frequency will vary from unit to unit due to normal process parameter variation. Furthermore, the difference in lead frame capacitance between package types will also affect the oscillation frequency, especially for low CEXT values. The user also needs to take into account variation due to tolerance of external R and C components used.

Figure 4-5 shows how the R/C combination is connected to the PIC16C5X. For REXT values below 2.2 k Ω , the oscillator operation may become unstable, or stop completely. For very high REXT values (e.g., 1 M Ω) the oscillator becomes sensitive to noise, humidity and leakage. Thus, we recommend keeping REXT between 3 k Ω and 100 k Ω .

Although the oscillator will operate with no external capacitor (CEXT = 0 pF), we recommend using values above 20 pF for noise and stability reasons. With no or small external capacitance, the oscillation frequency can vary dramatically due to changes in external capacitances, such as PCB trace capacitance or package lead frame capacitance.

The Electrical Specifications sections show RC frequency variation from part to part due to normal process variation. The variation is larger for larger R (since leakage current variation will affect RC frequency more for large R) and for smaller C (since variation of input capacitance will affect RC frequency more).

Also, see the Electrical Specifications sections for variation of oscillator frequency due to VDD for given REXT/ CEXT values as well as frequency variation due to operating temperature for given R, C, and VDD values.

The oscillator frequency, divided by 4, is available on the OSC2/CLKOUT pin, and can be used for test purposes or to synchronize other logic.



Note: If you change from this device to another device, please verify oscillator characteristics in your application.

NOTES:

5.0 RESET

PIC16C5X devices may be RESET in one of the following ways:

- Power-On Reset (POR)
- MCLR Reset (normal operation)
- MCLR Wake-up Reset (from SLEEP)
- WDT Reset (normal operation)
- WDT Wake-up Reset (from SLEEP)

Table 5-1 shows these RESET conditions for the PCL and STATUS registers.

Some registers are not affected in any RESET condition. Their status is unknown on POR and unchanged in any other RESET. Most other registers are reset to a "RESET state" on Power-On Reset (POR), MCLR or WDT Reset. A MCLR or WDT wake-up from SLEEP also results in a device RESET, and not a continuation of operation before SLEEP. The $\overline{\text{TO}}$ and $\overline{\text{PD}}$ bits (STATUS <4:3>) are set or cleared depending on the different RESET conditions (Table 5-1). These bits may be used to determine the nature of the RESET.

Table 5-3 lists a full description of RESET states of all registers. Figure 5-1 shows a simplified block diagram of the On-chip Reset circuit.

TABLE 5-1: STATUS BITS AND THEIR SIGNIFICANCE

Condition	ТО	PD
Power-On Reset	1	1
MCLR Reset (normal operation)	u	u
MCLR Wake-up (from SLEEP)	1	0
WDT Reset (normal operation)	0	1
WDT Wake-up (from SLEEP)	0	0

Legend: u = unchanged, x = unknown, - = unimplemented read as '0'.

TABLE 5-2: SUMMARY OF REGISTERS ASSOCIATED WITH RESET

Address	Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	Value on POR	<u>Value</u> on MCLR and WDT Reset
03h	STATUS	PA2	PA1	PA0	TO	PD	Z	DC	С	0001 1xxx	000q quuu

Legend: u = unchanged, x = unknown, q = see Table 5-1 for possible values.

TABLE 5-3: RESET CONDITIONS FOR ALL REGISTERS

Register	Address	Power-On Reset	MCLR or WDT Reset
W	N/A	XXXX XXXX	uuuu uuuu
TRIS	N/A	1111 1111	1111 1111
OPTION	N/A	11 1111	11 1111
INDF	00h	XXXX XXXX	uuuu uuuu
TMR0	01h	XXXX XXXX	uuuu uuuu
PCL	02h	1111 1111	1111 1111
STATUS	03h	0001 1xxx	000q quuu
FSR ⁽¹⁾	04h	1xxx xxxx	luuu uuuu
PORTA	05h	xxxx	uuuu
PORTB	06h	XXXX XXXX	uuuu uuuu
PORTC ⁽²⁾	07h	XXXX XXXX	uuuu uuuu
General Purpose Register Files	07-7Fh	XXXX XXXX	սսսս սսսս

Legend: x = unknown u = unchanged - = unimplemented, read as '0'<math>q = see tables in Table 5-1 for possible values.

- Note 1: These values are valid for PIC16C57/CR57/CR58/CR58. For the PIC16C54/CR54/C55/C56/CR56, the value on RESET is 111x xxxx and for MCLR and WDT Reset, the value is 111u uuuu.
 - **2:** General purpose register file on PIC16C54/CR54/C56/CR56/C58/CR58.

FIGURE 5-1: SIMPLIFIED BLOCK DIAGRAM OF ON-CHIP RESET CIRCUIT



5.1 Power-On Reset (POR)

The PIC16C5X family incorporates on-chip Power-On Reset (POR) circuitry which provides an internal chip RESET for most power-up situations. To use this feature, the user merely ties the MCLR/VPP pin to VDD. A simplified block diagram of the on-chip Power-On Reset circuit is shown in Figure 5-1.

The Power-On Reset circuit and the Device Reset Timer (Section 5.2) circuit are closely related. On power-up, the RESET latch is set and the DRT is <u>RESET</u>. The DRT timer begins counting once it detects MCLR to be high. After the time-out period, which is typically 18 ms, it will RESET the reset latch and thus end the on-chip RESET signal.

A power-up example where MCLR is not tied to VDD is shown in Figure 5-3. VDD is allowed to rise and stabilize before bringing MCLR high. The chip will actually come out of reset TDRT msec after MCLR goes high.

In Figure 5-4, the on-chip Power-On Reset feature is being used (MCLR and VDD are tied together). The VDD is stable before the start-up timer times out and there is no problem in getting a proper RESET. However, Figure 5-5 depicts a problem situation where VDD rises too slowly. The time between when the DRT senses a high on the MCLR/VPP pin, and when the MCLR/VPP pin (and VDD) actually reach their full value, is too long. In this situation, when the start-up timer times out, VDD has not reached the VDD (min) value and the chip is, therefore, not guaranteed to function correctly. For such situations, we recommend that external RC circuits be used to achieve longer POR delay times (Figure 5-2).

Note: When the device starts normal operation (exits the RESET condition), device operating parameters (voltage, frequency, temperature, etc.) must be met to ensure operation. If these conditions are not met, the device must be held in RESET until the operating conditions are met.

For more information on PIC16C5X POR, see *Power-Up Considerations* - AN522 in the <u>Embedded Control Handbook</u>.

The POR circuit does not produce an internal RESET when VDD declines.

FIGURE 5-2:

EXTERNAL POWER-ON RESET CIRCUIT (FOR SLOW VDD POWER-UP)



- External Power-On Reset circuit is required only if VDD power-up is too slow. The diode D helps discharge the capacitor quickly when VDD powers down.
- R < 40 kΩ is recommended to make sure that voltage drop across R does not violate the device electrical specification.
- R1 = 100Ω to 1 k Ω will limit any current flowing into \overline{MCLR} from external capacitor C in the event of \overline{MCLR} pin breakdown due to Electrostatic Discharge (ESD) or Electrical Overstress (EOS).

PIC16C5X



FIGURE 5-4: TIME-OUT SEQUENCE ON POWER-UP (MCLR TIED TO VDD): FAST VDD RISE TIME



FIGURE 5-5: TIME-OUT SEQUENCE ON POWER-UP (MCLR TIED TO VDD): SLOW VDD RISE TIME



5.2 Device Reset Timer (DRT)

The Device Reset Timer (DRT) provides an 18 ms nominal time-out on RESET regardless of Oscillator mode used. The DRT operates on an internal RC oscillator. The processor is kept in RESET as long as the DRT is active. The DRT delay allows VDD to rise above VDD min., and for the oscillator to stabilize.

Oscillator circuits based on crystals or ceramic resonators require a certain time after power-up to establish a stable oscillation. The on-chip DRT keeps the device in a RESET condition for approximately 18 ms after the voltage on the MCLR/VPP pin has reached a logic high (VIH) level. Thus, external RC networks connected to the MCLR input are not required in most cases, allowing for savings in cost-sensitive and/or space restricted applications.

The Device Reset time delay will vary from chip to chip due to VDD, temperature, and process variation. See AC parameters for details.

The DRT will also be triggered upon a Watchdog Timer time-out. This is particularly important for applications using the WDT to wake the PIC16C5X from SLEEP mode automatically.

5.3 Reset on Brown-Out

A brown-out is a condition where device power (VDD) dips below its minimum value, but not to zero, and then recovers. The device should be RESET in the event of a brown-out.

To RESET PIC16C5X devices when a brown-out occurs, external brown-out protection circuits may be built, as shown in Figure 5-6, Figure 5-7 and Figure 5-8.





FIGURE 5-7:

EXTERNAL BROWN-OUT PROTECTION CIRCUIT 2



This brown-out circuit is less expensive, although less accurate. Transistor Q1 turns off when VDD is below a certain level such that:

$$V_{DD} \bullet \frac{R1}{R1 + R2} = 0.7V$$

FIGURE 5-8:

EXTERNAL BROWN-OUT PROTECTION CIRCUIT 3



This brown-out protection circuit employs Microchip Technology's MCP809 microcontroller supervisor. The MCP8XX and MCP1XX families of supervisors provide push-pull and open collector outputs with both "active high and active low" RESET pins. There are 7 different trip point selections to accommodate 5V and 3V systems. NOTES:

6.0 MEMORY ORGANIZATION

PIC16C5X memory is organized into program memory and data memory. For devices with more than 512 bytes of program memory, a paging scheme is used. Program memory pages are accessed using one or two STATUS Register bits. For devices with a data memory register file of more than 32 registers, a banking scheme is used. Data memory banks are accessed using the File Selection Register (FSR).

6.1 Program Memory Organization

The PIC16C54, PIC16CR54 and PIC16C55 have a 9bit Program Counter (PC) capable of addressing a 512 x 12 program memory space (Figure 6-1). The PIC16C56 and PIC16CR56 have a 10-bit Program Counter (PC) capable of addressing a 1K x 12 program memory space (Figure 6-2). The PIC16CR57, PIC16C58 and PIC16CR58 have an 11-bit Program Counter capable of addressing a 2K x 12 program memory space (Figure 6-3). Accessing a location above the physically implemented address will cause a wraparound.

A NOP at the RESET vector location will cause a restart at location 000h. The RESET vector for the PIC16C54, PIC16CR54 and PIC16C55 is at 1FFh. The RESET vector for the PIC16C56 and PIC16CR56 is at 3FFh. The RESET vector for the PIC16C57, PIC16CR57, PIC16C58, and PIC16CR58 is at 7FFh. See Section 6.5 for additional information using CALL and GOTO instructions.

FIGURE 6-1: PIC16C54/CR54/C55 PROGRAM MEMORY MAP AND STACK



FIGURE 6-2:

PIC16C56/CR56 PROGRAM MEMORY MAP AND STACK



FIGURE 6-3:

PIC16C57/CR57/C58/ CR58 PROGRAM MEMORY MAP AND STACK



6.2 Data Memory Organization

Data memory is composed of registers, or bytes of RAM. Therefore, data memory for a device is specified by its register file. The register file is divided into two functional groups: Special Function Registers and General Purpose Registers.

The Special Function Registers include the TMR0 register, the Program Counter (PC), the Status Register, the I/O registers (ports) and the File Select Register (FSR). In addition, Special Purpose Registers are used to control the I/O port configuration and prescaler options.

The General Purpose Registers are used for data and control information under command of the instructions.

For the PIC16C54, PIC16CR54, PIC16C56 and PIC16CR56, the register file is composed of 7 Special Function Registers and 25 General Purpose Registers (Figure 6-4).

For the PIC16C55, the register file is composed of 8 Special Function Registers and 24 General Purpose Registers.

For the PIC16C57 and PIC16CR57, the register file is composed of 8 Special Function Registers, 24 General Purpose Registers and up to 48 additional General Purpose Registers that may be addressed using a banking scheme (Figure 6-5).

For the PIC16C58 and PIC16CR58, the register file is composed of 7 Special Function Registers, 25 General Purpose Registers and up to 48 additional General Purpose Registers that may be addressed using a banking scheme (Figure 6-6).

6.2.1 GENERAL PURPOSE REGISTER FILE

The register file is accessed either directly or indirectly through the File Select Register (FSR). The FSR Register is described in Section 6.7.

FIGURE 6-4: PIC16C54, PIC16CR54, PIC16C55, PIC16C56, PIC16CR56 REGISTER









6.2.2 SPECIAL FUNCTION REGISTERS

The Special Function Registers are registers used by the CPU and peripheral functions to control the operation of the device (Table 6-1).

The Special Registers can be classified into two sets. The Special Function Registers associated with the "core" functions are described in this section. Those related to the operation of the peripheral features are described in the section for each peripheral feature.

Address	Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	Value on Power-on Reset	Details on Page
N/A	TRIS	I/O Cont	rol Regis	ters (TRIS	SA, TRIS	B, TRISC	;)			1111 1111	35
N/A	OPTION	Contains	s control b	oits to cor	figure Ti	mer0 and	Timer0/V	VDT pres	caler	11 1111	30
00h	INDF	Uses co	Jses contents of FSR to address data memory (not a physical register)					egister)	XXXX XXXX	32	
01h	TMR0	Timer0	imer0 Module Register							XXXX XXXX	38
02h ⁽¹⁾	PCL	Low ord	er 8 bits c	of PC						1111 1111	31
03h	STATUS	PA2	PA1	PA0	TO	PD	Z	DC	С	0001 1xxx	29
04h	FSR	Indirect	ndirect data memory address pointer					1xxx xxxx ⁽³⁾	32		
05h	PORTA	—	—	—	—	RA3	RA2	RA1	RA0	xxxx	35
06h	PORTB	RB7	RB6	RB5	RB4	RB3	RB2	RB1	RB0	XXXX XXXX	35
07h ⁽²⁾	PORTC	RC7	RC6	RC5	RC4	RC3	RC2	RC1	RC0	XXXX XXXX	35

Legend: x = unknown, u = unchanged, - = unimplemented, read as '0' (if applicable). Shaded cells = unimplemented or unused

Note 1: The upper byte of the Program Counter is not directly accessible. See Section 6.5 for an explanation of how to access these bits.

2: File address 07h is a General Purpose Register on the PIC16C54, PIC16CR54, PIC16C56, PIC16CR56, PIC16CR58 and PIC16CR58.

3: These values are valid for PIC16C57/CR57/C58/CR58. For the PIC16C54/CR54/C55/C56/CR56, the value on RESET is 111x xxxx and for MCLR and WDT Reset, the value is 111u uuuu.

6.3 STATUS Register

This register contains the arithmetic status of the ALU, the RESET status and the page preselect bits for program memories larger than 512 words.

The STATUS Register can be the destination for any instruction, as with any other register. If the STATUS Register is the destination for an instruction that affects the Z, DC or C bits, then the write to these three bits is disabled. These bits are set or cleared according to the device logic. Furthermore, the TO and PD bits are not

writable. Therefore, the result of an instruction with the STATUS Register as destination may be different than intended.

For example, CLRF STATUS will clear the upper three bits and set the Z bit. This leaves the STATUS Register as $000u \ u1uu$ (where u = unchanged).

It is recommended, therefore, that only BCF, BSF and MOVWF instructions be used to alter the STATUS Register because these instructions do not affect the Z, DC or C bits from the STATUS Register. For other instructions which do affect STATUS Bits, see Section 10.0, Instruction Set Summary.

REGISTER 6-1: STATUS REGISTER (ADDRESS: 03h)

	R/W-0	R/W-0	R/W-0	R-1	R-1	R/W-x	R/W-x	R/W-x			
	PA2	PA1	PA0	TO	PD	Z	DC	С			
	bit 7							bit 0			
bit 7:	PA2: This bit	unused at th	is time.								
		A2 bit as a ge with future pr		e read/write	bit is not recor	mmended, sir	nce this may a	affect upward			
bit 6-5:				-	CR56)(PIC16			58)			
					16C57/CR57, 16C57/CR57,						
		(400h - 5FFh				FIC 10C30/C	N00				
	11 = Page 3	(600h - 7FFh									
	Each page is		deperal pur	ose read/wr	ite bits in devi	ices which do	not use them	for program			
					affect upward						
bit 4:	TO: Time-ou			,	•						
		ver-up, CLRWI ime-out occur		, or sleep i	nstruction						
bit 3:	PD: Power-d	lown bit									
	•	ver-up or by tl ution of the SI									
bit 2:	Z: Zero bit										
		lt of an arithm It of an arithm									
bit 1:	DC: Digit car	ry/borrow bit	(for ADDWF a	nd SUBWF in	structions)						
	ADDWF										
	 1 = A carry from the 4th low order bit of the result occurred 0 = A carry from the 4th low order bit of the result did not occur 										
	SUBWF										
	1 = A borrow from the 4th low order bit of the result did not occur										
	0 = A borrow from the 4th low order bit of the result occurred										
bit 0:	-	row bit (for AI			F instructions		_				
	ADDWF 1 = A carry o	ocurred		orrow did n	ot occur	RRF or RLI		, respectively			
	$\pm = \pi \operatorname{carry} 0$	locurrou	/ · ·								

Legena:			
R = Readable bit	W = Writable bit	U = Unimplemented bit, re	ead as '0'
-n = Value at POR	1 = bit is set	0 = bit is cleared	x = bit is unknown

6.4 **OPTION Register**

The OPTION Register is a 6-bit wide, write-only register which contains various control bits to configure the Timer0/WDT prescaler and Timer0.

By executing the OPTION instruction, the contents of the W Register will be transferred to the OPTION Register. A RESET sets the OPTION<5:0> bits.

REGISTER 6-2: OPTION REGISTER

U-0	U-0	W-1	W-1	W-1	W-1	W-1	W-1
_	_	TOCS	TOSE	PSA	PS2	PS1	PS0
bit 7							bit 0

- bit 7-6: Unimplemented: Read as '0'
- bit 5: **TOCS**: Timer0 clock source select bit
 - 1 = Transition on T0CKI pin
 - 0 = Internal instruction cycle clock (CLKOUT)
- bit 4: **TOSE**: Timer0 source edge select bit
 - 1 = Increment on high-to-low transition on T0CKI pin
 - 0 = Increment on low-to-high transition on T0CKI pin
- bit 3: **PSA**: Prescaler assignment bit
 - 1 = Prescaler assigned to the WDT
 - 0 = Prescaler assigned to Timer0

bit 2-0: **PS<2:0>:** Prescaler rate select bits

Bit Value	Timer0 Rate	WDT Rate
000	1:2	1:1
001	1:4	1:2
010	1:8	1:4
011	1:16	1:8
100	1:32	1:16
101	1:64	1:32
110	1:128	1:64
111	1:256	1:128

Legend:			
R = Readable bit	W = Writable bit	U = Unimplemented b	it, read as '0'
-n = Value at POR	1 = bit is set	0 = bit is cleared	x = bit is unknown

6.5 Program Counter

As a program instruction is executed, the Program Counter (PC) will contain the address of the next program instruction to be executed. The PC value is increased by one, every instruction cycle, unless an instruction changes the PC.

For a GOTO instruction, bits 8:0 of the PC are provided by the GOTO instruction word. The PC Latch (PCL) is mapped to PC<7:0> (Figure 6-7, Figure 6-8 and Figure 6-9).

For the PIC16C56, PIC16CR56, PIC16C57, PIC16CR57, PIC16C58 and PIC16CR58, a page number must be supplied as well. Bit5 and bit6 of the STA-TUS Register provide page information to bit9 and bit10 of the PC (Figure 6-8 and Figure 6-9).

For a CALL instruction, or any instruction where the PCL is the destination, bits 7:0 of the PC again are provided by the instruction word. However, PC<8> does not come from the instruction word, but is always cleared (Figure 6-7 and Figure 6-8).

Instructions where the PCL is the destination, or modify PCL instructions, include MOVWF PCL, ADDWF PCL, and BSF PCL, 5.

For the PIC16C56, PIC16CR56, PIC16C57, PIC16CR57, PIC16C58 and PIC16CR58, a page number again must be supplied. Bit5 and bit6 of the STA-TUS Register provide page information to bit9 and bit10 of the PC (Figure 6-8 and Figure 6-9).

Note:	Because PC<8> is cleared in the CALL					
	instruction, or any modify PCL instruction,					
	all subroutine calls or computed jumps are					
	limited to the first 256 locations of any pro-					
	gram memory page (512 words long).					

FIGURE 6-7: LOADING OF PC BRANCH INSTRUCTIONS - PIC16C54, PIC16CR54, PIC16C55



FIGURE 6-8:

LOADING OF PC BRANCH INSTRUCTIONS - PIC16C56/PIC16CR56



FIGURE 6-9:

LOADING OF PC BRANCH INSTRUCTIONS - PIC16C57/PIC16CR57, AND PIC16C58/ PIC16CR58





6.5.1 PAGING CONSIDERATIONS – PIC16C56/CR56, PIC16C57/CR57 AND PIC16C58/CR58

If the Program Counter is pointing to the last address of a selected memory page, when it increments it will cause the program to continue in the next higher page. However, the page preselect bits in the STATUS Register will not be updated. Therefore, the next GOTO, CALL or modify PCL instruction will send the program to the page specified by the page preselect bits (PA0 or PA<1:0>).

For example, a NOP at location 1FFh (page 0) increments the PC to 200h (page 1). A GOTO xxx at 200h will return the program to address xxh on page 0 (assuming that PA<1:0> are clear).

To prevent this, the page preselect bits must be updated under program control.

6.5.2 EFFECTS OF RESET

The Program Counter is set upon a RESET, which means that the PC addresses the last location in the last page (i.e., the RESET vector).

The STATUS Register page preselect bits are cleared upon a RESET, which means that page 0 is pre-selected.

Therefore, upon a RESET, a GOTO instruction at the RESET vector location will automatically cause the program to jump to page 0.

6.6 Stack

PIC16C5X devices have a 10-bit or 11-bit wide, two-level hardware push/pop stack.

A CALL instruction will push the current value of stack 1 into stack 2 and then push the current program counter value, incremented by one, into stack level 1. If more than two sequential CALL's are executed, only the most recent two return addresses are stored.

A RETLW instruction will pop the contents of stack level 1 into the program counter and then copy stack level 2 contents into level 1. If more than two sequential RETLW's are executed, the stack will be filled with the address previously stored in level 2. Note that the W Register will be loaded with the literal value specified in the instruction. This is particularly useful for the implementation of data look-up tables within the program memory.

For the RETLW instruction, the PC is loaded with the Top of Stack (TOS) contents. All of the devices covered in this data sheet have a two-level stack. The stack has the same bit width as the device PC, therefore, paging is not an issue when returning from a subroutine.

6.7 Indirect Data Addressing; INDF and FSR Registers

The INDF Register is not a physical register. Addressing INDF actually addresses the register whose address is contained in the FSR Register (FSR is a *pointer*). This is indirect addressing.

EXAMPLE 6-1: INDIRECT ADDRESSING

- Register file 08 contains the value 10h
- Register file 09 contains the value 0Ah
- · Load the value 08 into the FSR Register
- A read of the INDF Register will return the value of 10h
- Increment the value of the FSR Register by one (FSR = 09h)
- A read of the INDF register now will return the value of 0Ah.

Reading INDF itself indirectly (FSR = 0) will produce 00h. Writing to the INDF Register indirectly results in a no-operation (although STATUS bits may be affected).

A simple program to clear RAM locations 10h-1Fh using indirect addressing is shown in Example 6-2.

EXAMPLE 6-2:

HOW TO CLEAR RAM USING INDIRECT ADDRESSING

	MOVLW	H'10'	;initialize pointer
	MOVWF	FSR	; to RAM
NEXT	CLRF	INDF	;clear INDF Register
	INCF	FSR,F	;inc pointer
	BTFSC	FSR,4	;all done?
	GOTO	NEXT	;NO, clear next
CONTINUE			
	:		;YES, continue

The FSR is either a 5-bit (PIC16C54, PIC16CR54, PIC16C55, PIC16C56, PIC16CR56) or 7-bit (PIC16C57, PIC16CR57, PIC16CR58, PIC16CR58) wide register. It is used in conjunction with the INDF Register to indirectly address the data memory area.

The FSR<4:0> bits are used to select data memory addresses 00h to 1Fh.

PIC16C54, PIC16CR54, PIC16C55, PIC16C56, PIC16CR56: These do not use banking. FSR<6:5> bits are unimplemented and read as '1's.

PIC16C57, **PIC16CR57**, **PIC16C58**, **PIC16CR58**: FSR<6:5> are the bank select bits and are used to select the bank to be addressed (00 = bank 0, 01 = bank 1, 10 = bank 2, 11 = bank 3).



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NOTES:

7.0 I/O PORTS

As with any other register, the I/O Registers can be written and read under program control. However, read instructions (e.g., MOVF PORTB, W) always read the I/O pins independent of the pin's input/output modes. On RESET, all I/O ports are defined as input (inputs are at hi-impedance) since the I/O control registers (TRISA, TRISB, TRISC) are all set.

7.1 PORTA

PORTA is a 4-bit I/O Register. Only the low order 4 bits are used (RA<3:0>). Bits 7-4 are unimplemented and read as '0's.

7.2 PORTB

PORTB is an 8-bit I/O Register (PORTB<7:0>).

7.3 PORTC

PORTC is an 8-bit I/O Register for PIC16C55, PIC16C57 and PIC16CR57.

PORTC is a General Purpose Register for PIC16C54, PIC16CR54, PIC16CR56, PIC16CR56, PIC16CS8 and PIC16CR58.

7.4 TRIS Registers

The Output Driver Control Registers are loaded with the contents of the W Register by executing the TRIS f instruction. A '1' from a TRIS Register bit puts the corresponding output driver in a hi-impedance (input) mode. A '0' puts the contents of the output data latch on the selected pins, enabling the output buffer.

Note:	A read of the ports reads the pins, not the
	output data latches. That is, if an output
	driver on a pin is enabled and driven high,
	but the external system is holding it low, a
	read of the port will indicate that the pin is
	low.

The TRIS Registers are "write-only" and are set (output drivers disabled) upon RESET.

TABLE 7-1:	SUMMARY OF PORT REGISTERS

Value on Value on Bit 4 Bit 3 Bit 1 Bit 0 MCLR and Address Name Bit 7 Bit 6 Bit 5 Bit 2 Power-On Reset WDT Reset TRIS N/A I/O Control Registers (TRISA, TRISB, TRISC) 1111 1111 1111 1111 05h PORTA RA3 RA2 RA1 RA0 _ _ _ _ xxxx _ _ _ _ uuuu PORTB 06h RB7 RB6 RB5 RB4 RB3 RB2 RB1 RB0 XXXX XXXX uuuu uuuu 07h PORTC RC7 RC6 RC5 RC4 RC3 RC2 RC1 RC0 XXXX XXXX uuuu uuuu

Legend: x = unknown, u = unchanged, - = unimplemented, read as '0', Shaded cells = unimplemented, read as '0'

7.5 I/O Interfacing

The equivalent circuit for an I/O port pin is shown in Figure 7-1. All ports may be used for both input and output operation. For input operations these ports are non-latching. Any input must be present until read by an input instruction (e.g., MOVF PORTB, W). The outputs are latched and remain unchanged until the output latch is rewritten. To use a port pin as output, the corresponding direction control bit (in TRISA, TRISB, TRISC) must be cleared (= 0). For use as an input, the corresponding TRIS bit must be set. Any I/O pin can be programmed individually as input or output.

FIGURE 7-1: EQUIVALENT CIRCUIT FOR A SINGLE I/O PIN



7.6 I/O Programming Considerations

7.6.1 BI-DIRECTIONAL I/O PORTS

Some instructions operate internally as read followed by write operations. The BCF and BSF instructions, for example, read the entire port into the CPU, execute the bit operation and re-write the result. Caution must be used when these instructions are applied to a port where one or more pins are used as input/outputs. For example, a BSF operation on bit5 of PORTB will cause all eight bits of PORTB to be read into the CPU, bit5 to be set and the PORTB value to be written to the output latches. If another bit of PORTB is used as a bi-directional I/O pin (say bit0) and it is defined as an input at this time, the input signal present on the pin itself would be read into the CPU and rewritten to the data latch of this particular pin, overwriting the previous content. As long as the pin stays in the Input mode, no problem occurs. However, if bit0 is switched into Output mode later on, the content of the data latch may now be unknown.

Example 7-1 shows the effect of two sequential read-modify-write instructions (e.g., BCF, BSF, etc.) on an I/O port.

A pin actively outputting a high or a low should not be driven from external devices at the same time in order to change the level on this pin ("wired-or", "wired-and"). The resulting high output currents may damage the chip.

EXAMPLE 7-1: READ-MODIFY-WRITE INSTRUCTIONS ON AN I/O PORT

;Initial PORT Settings
; PORTB<7:4> Inputs
; PORTB<3:0> Outputs
;PORTB<7:6> have external pull-ups and are
;not connected to other circuitry
;

;				PORT	latch	PORT	pins
;							
	BCF	PORTB,	7	;01pp	pppp	11pp	pppp
	BCF	PORTB,	6	;10pp	pppp	11pp	pppp
	MOVLW	H'3F'		;			
	TRIS	PORTB		;10pp	pppp	10pp	pppp
;							

;Note that the user may have expected the pin ;values to be 00pp pppp. The 2nd BCF caused ;RB7 to be latched as the pin value (High).

7.6.2 SUCCESSIVE OPERATIONS ON I/O PORTS

The actual write to an I/O port happens at the end of an instruction cycle, whereas for reading, the data must be valid at the beginning of the instruction cycle (Figure 7-2). Therefore, care must be exercised if a write followed by a read operation is carried out on the same I/O port. The sequence of instructions should allow the pin voltage to stabilize (load dependent) before the next instruction, which causes that file to be read into the CPU, is executed. Otherwise, the previous state of that pin may be read into the CPU rather than the new state. When in doubt, it is better to separate these instructions with a NOP or another instruction not accessing this I/O port.



FIGURE 7-2: SUCCESSIVE I/O OPERATION
8.0 TIMER0 MODULE AND TMR0 REGISTER

The Timer0 module has the following features:

- 8-bit timer/counter register, TMR0
 - Readable and writable
- 8-bit software programmable prescaler
- · Internal or external clock select
- Edge select for external clock

Figure 8-1 is a simplified block diagram of the Timer0 module, while Figure 8-2 shows the electrical structure of the Timer0 input.

Timer mode is selected by clearing the T0CS bit (OPTION<5>). In Timer mode, the Timer0 module will increment every instruction cycle (without prescaler). If TMR0 register is written, the increment is inhibited for the following two cycles (Figure 8-3 and Figure 8-4). The user can work around this by writing an adjusted value to the TMR0 register.



Counter mode is selected by setting the T0CS bit (OPTION<5>). In this mode, Timer0 will increment either on every rising or falling edge of pin T0CKI. The incrementing edge is determined by the source edge select bit T0SE (OPTION<4>). Clearing the T0SE bit selects the rising edge. Restrictions on the external clock input are discussed in detail in Section 8.1.

Note: The prescaler may be used by either the Timer0 module or the Watchdog Timer, but not both.

The prescaler assignment is controlled in software by the control bit PSA (OPTION<3>). Clearing the PSA bit will assign the prescaler to Timer0. The prescaler is not readable or writable. When the prescaler is assigned to the Timer0 module, prescale values of 1:2, 1:4,..., 1:256 are selectable. Section 8.2 details the operation of the prescaler.

A summary of registers associated with the Timer0 module is found in Table 8-1.



FIGURE 8-2: ELECTRICAL STRUCTURE OF TOCKI PIN







FIGURE 8-4: TIMER0 TIMING: INTERNAL CLOCK/PRESCALER 1:2



TABLE 8-1: REGISTERS ASSOCIATED WITH TIMER0

Address	Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	Value on Power-on Reset	<u>Value</u> on MCLR and WDT Reset
01h	TMR0	Timer0 -	8-bit real	-time cloc	k/counter					xxxx xxxx	uuuu uuuu
N/A	OPTION	_		TOCS	TOSE	PSA	PS2	PS1	PS0	11 1111	11 1111

Legend: x = unknown, u = unchanged, - = unimplemented. Shaded cells not used by Timer0.

8.1 Using Timer0 with an External Clock

When an external clock input is used for Timer0, it must meet certain requirements. The external clock requirement is due to internal phase clock (Tosc) synchronization. Also, there is a delay in the actual incrementing of Timer0 after synchronization.

8.1.1 EXTERNAL CLOCK SYNCHRONIZATION

When no prescaler is used, the external clock input is the same as the prescaler output. The synchronization of T0CKI with the internal phase clocks is accomplished by sampling the prescaler output on the Q2 and Q4 cycles of the internal phase clocks (Figure 8-5). Therefore, it is necessary for T0CKI to be high for at least 2Tosc (and a small RC delay of 20 ns) and low for at least 2Tosc (and a small RC delay of 20 ns). Refer to the electrical specification of the desired device. When a prescaler is used, the external clock input is divided by the asynchronous ripple counter-type prescaler so that the prescaler output is symmetrical. For the external clock to meet the sampling requirement, the ripple counter must be taken into account. Therefore, it is necessary for TOCKI to have a period of at least 4Tosc (and a small RC delay of 40 ns) divided by the prescaler value. The only requirement on TOCKI high and low time is that they do not violate the minimum pulse width requirement of 10 ns. Refer to parameters 40, 41 and 42 in the electrical specification of the desired device.

8.1.2 TIMER0 INCREMENT DELAY

Since the prescaler output is synchronized with the internal clocks, there is a small delay from the time the external clock edge occurs to the time the Timer0 module is actually incremented. Figure 8-5 shows the delay from the external clock edge to the timer incrementing.



Belay from clock input change to Timer0 increment is 3 lose to 7 lose (duration of Q = lose). There the error in measuring the interval between two edges on Timer0 input = ± 4 Tose max.

8.2 Prescaler

An 8-bit counter is available as a prescaler for the Timer0 module, or as a postscaler for the Watchdog Timer (WDT), respectively (Section 9.2.1). For simplicity, this counter is being referred to as "prescaler" throughout this data sheet. Note that the prescaler may be used by either the Timer0 module or the WDT, but not both. Thus, a prescaler assignment for the Timer0 module means that there is no prescaler for the WDT, and vice-versa.

The PSA and PS<2:0> bits (OPTION<3:0>) determine prescaler assignment and prescale ratio.

When assigned to the Timer0 module, all instructions writing to the TMR0 register (e.g., CLRF 1, MOVWF 1, BSF 1, x, etc.) will clear the prescaler. When assigned to WDT, a CLRWDT instruction will clear the prescaler along with the WDT. The prescaler is neither readable nor writable. On a RESET, the prescaler contains all '0's.

8.2.1 SWITCHING PRESCALER ASSIGNMENT

The prescaler assignment is fully under software control (i.e., it can be changed "on the fly" during program execution). To avoid an unintended device RESET, the following instruction sequence (Example 8-1) must be executed when changing the prescaler assignment from Timer0 to the WDT.

EXAMPLE 8-1: CHANGING PRESCALER (TIMER0→WDT)

CLRWDT	;Clear WDT
CLRF TMR0	Clear TMR0 & Prescaler
MOVLW B'00xx1111'	;Last 3 instructions in
	this example
OPTION	;are required only if
	;desired
CLRWDT	;PS<2:0> are 000 or
	;001
MOVLW B'00xx1xxx'	;Set Prescaler to
OPTION	;desired WDT rate

To change prescaler from the WDT to the Timer0 module, use the sequence shown in Example 8-2. This sequence must be used even if the WDT is disabled. A CLRWDT instruction should be executed before switching the prescaler.

EXAMPLE 8-2: CHANGING PRESCALER (WDT \rightarrow TIMER0)

CLRWDT		;Clear WDT and
		;prescaler
MOVLW	B'xxxx0xxx'	;Select TMR0, new
		;prescale value and
		;clock source

OPTION





NOTES:

9.0 SPECIAL FEATURES OF THE CPU

What sets a microcontroller apart from other processors are special circuits that deal with the needs of realtime applications. The PIC16C5X family of microcontrollers have a host of such features intended to maximize system reliability, minimize cost through elimination of external components, provide power saving operating modes and offer code protection. These features are:

- Oscillator Selection (Section 4.0)
- RESET (Section 5.0)
- Power-On Reset (Section 5.1)
- Device Reset Timer (Section 5.2)
- Watchdog Timer (WDT) (Section 9.2)
- SLEEP (Section 9.3)
- Code protection (Section 9.4)
- ID locations (Section 9.5)

The PIC16C5X Family has a Watchdog Timer which can be shut off only through configuration bit WDTE. It runs off of its own RC oscillator for added reliability. There is an 18 ms delay provided by the Device Reset Timer (DRT), intended to keep the chip in RESET until the crystal oscillator is stable. With this timer on-chip, most applications need no external RESET circuitry.

The SLEEP mode is designed to offer a very low current Power-down mode. The user can wake up from SLEEP through external RESET or through a Watchdog Timer time-out. Several oscillator options are also made available to allow the part to fit the application. The RC oscillator option saves system cost while the LP crystal option saves power. A set of configuration bits are used to select various options.

9.1 Configuration Bits

Configuration bits can be programmed to select various device configurations. Two bits are for the selection of the oscillator type and one bit is the Watchdog Timer enable bit. Nine bits are code protection bits for the PIC16C54A, PIC16CR54A, PIC16C55A, PIC16C56A, PIC16CR56A, PIC16CR57C, PIC16CR57C, PIC16CR57C,

PIC16C58B, and PIC16CR58B devices (Register 9-1). One bit is for code protection for the PIC16C54, PIC16C55, PIC16C56 and PIC16C57 devices (Register 9-2).

QTP or ROM devices have the oscillator configuration programmed at the factory and these parts are tested accordingly (see "Product Identification System" diagrams in the back of this data sheet).

REGISTER 9-1: CONFIGURATION WORD FOR PIC16C54A/CR54A/C54C/CR54C/C55A/C56A/ CR56A/C57C/CR57C/C58B/CR58B

CP	CP	CP	CP	CP	CP	CP	CP	CP	WDTE	FOSC1	FOSC0
bit 11											bit 0

bit 11-3: CP: Code Protection Bit

- 1 = Code protection off
 - 0 =Code protection on
- bit 2: WDTE: Watchdog timer enable bit
 - 1 = WDT enabled
 - 0 = WDT disabled

bit 1-0: FOSC1:FOSC0: Oscillator Selection Bit

- 00 = LP oscillator
- 01 = XT oscillator
- 10 = HS oscillator
- 11 = RC oscillator

Note 1: Refer to the PIC16C5X Programming Specification (Literature Number DS30190) to determine how to access the configuration word.

Legend:			
R = Readable bit	W = Writable bit	U = Unimplemented bit, re	ead as '0'
-n = Value at POR	1 = bit is set	0 = bit is cleared	x = bit is unknown

CONFIGURATION WORD FOR PIC16C54/C55/C56/C57 **REGISTER 9-2:**

							İ	СР	WDTE	FOSC1	FOSC0
		_	_	_				CP	WDIE	FUSCI	
bit 11											bit 0
bit 11-4:	Unimple	mented	Read as '	0'							
bit 3:	CP: Cod	e protecti	on bit.								
		e protecti									
	0 = Code	e protectio	on on								
bit 2:	WDTE: \	Vatchdog	timer ena	ble bit							
	1 = WDT	enabled									
	0 = WDT	disabled									
bit 1-0:	FOSC1:I	FOSC0: (Oscillator s	election b	oits ⁽²⁾						
	00 = LF	oscillato	or								
	01 = X	T oscillato	or								
		S oscillato									
	11 = R	C oscillate	or								
Note 1.	Refer to t	ha PIC16	C5X Prog	rammina	Specificat	ions (Liter	atura Num	her DS3	190) to d	otormino l	now to
			iration wor	0	opeemear				, 100) to u		1011 10
2:		•	orts XT, R		oscillator	onlv.					
						- 1					
Legend:											

Legend:			
R = Readable bit	W = Writable bit	U = Unimplemented bit, re	ead as '0'
-n = Value at POR	1 = bit is set	0 = bit is cleared	x = bit is unknown

9.2 Watchdog Timer (WDT)

The Watchdog Timer (WDT) is a free running on-chip RC oscillator which does not require any external components. This RC oscillator is separate from the RC oscillator of the OSC1/CLKIN pin. That means that the WDT will run even if the clock on the OSC1/CLKIN and OSC2/CLKOUT pins have been stopped, for example, by execution of a SLEEP instruction. During normal operation or SLEEP, a WDT Reset or Wake-up Reset generates a device RESET.

The $\overline{\text{TO}}$ bit (STATUS<4>) will be cleared upon a Watchdog Timer Reset (Section 6.3).

The WDT can be permanently disabled by programming the configuration bit WDTE as a '0' (Section 9.1). Refer to the PIC16C5X Programming Specifications (Literature Number DS30190) to determine how to access the configuration word.

9.2.1 WDT PERIOD

An 8-bit counter is available as a prescaler for the Timer0 module (Section 8.2), or as a postscaler for the Watchdog Timer (WDT), respectively. For simplicity, this counter is being referred to as "prescaler" throughout this data sheet. Note that the prescaler may be used by either the Timer0 module or the WDT, but not

both. Thus, a prescaler assignment for the Timer0 module means that there is no prescaler for the WDT, and vice-versa.

The PSA and PS<2:0> bits (OPTION<3:0>) determine prescaler assignment and prescale ratio (Section 6.4).

The WDT has a nominal time-out period of 18 ms (with no prescaler). If a longer time-out period is desired, a prescaler with a division ratio of up to 1:128 can be assigned to the WDT (under software control) by writing to the OPTION register. Thus, time-out a period of a nominal 2.3 seconds can be realized. These periods vary with temperature, VDD and part-to-part process variations (see Device Characterization).

Under worst case conditions (VDD = Min., Temperature = Max., WDT prescaler = 1:128), it may take several seconds before a WDT time-out occurs.

9.2.2 WDT PROGRAMMING CONSIDERATIONS

The CLRWDT instruction clears the WDT and the prescaler, if assigned to the WDT, and prevents it from timing out and generating a device RESET.

The SLEEP instruction RESETS the WDT and the prescaler, if assigned to the WDT. This gives the maximum SLEEP time before a WDT Wake-up Reset.



TABLE 9-1: SUMMARY OF REGISTERS ASSOCIATED WITH THE WATCHDOG TIMER

Address	Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	Value on Power-On Reset	<u>Value</u> on MCLR and WDT Reset
N/A	OPTION	—		Tosc	Tose	PSA	PS2	PS1	PS0	11 1111	11 1111

Legend: u = unchanged, - = unimplemented, read as '0'. Shaded cells not used by Watchdog Timer.

9.3 Power-Down Mode (SLEEP)

A device may be powered down (SLEEP) and later powered up (Wake-up from SLEEP).

9.3.1 SLEEP

The Power-down mode is entered by executing a SLEEP instruction.

If enabled, the Watchdog Timer will be cleared but keeps running, the TO bit (STATUS<4>) is set, the PD bit (STATUS<3>) is cleared and the oscillator driver is turned off. The I/O ports maintain the status they had before the SLEEP instruction was executed (driving high, driving low, or hi-impedance).

It should be noted that a RESET generated by a WDT time-out does not drive the MCLR/VPP pin low.

For lowest current consumption while powered down, the T0CKI input should be at VDD or Vss and the $\overline{\text{MCLR}}/\text{VPP}$ pin must be at a logic high level ($\overline{\text{MCLR}} = \text{VIH}$).

9.3.2 WAKE-UP FROM SLEEP

The device can wake up from SLEEP through one of the following events:

- 1. An external RESET input on MCLR/VPP pin.
- 2. A Watchdog Timer Time-out Reset (if WDT was enabled).

Both of these events cause a device RESET. The $\overline{\text{TO}}$ and $\overline{\text{PD}}$ bits can be used to determine the cause of device RESET. The $\overline{\text{TO}}$ bit is cleared if a WDT timeout occurred (and caused wake-up). The $\overline{\text{PD}}$ bit, which is set on power-up, is cleared when SLEEP is invoked.

The WDT is cleared when the device wakes from SLEEP, regardless of the wake-up source.

9.4 Program Verification/Code Protection

If the code protection bit(s) have not been programmed, the on-chip program memory can be read out for verification purposes.

Note:	Microchip does not recommend code pro-
	tecting windowed devices.

9.5 ID Locations

Four memory locations are designated as ID locations where the user can store checksum or other code-identification numbers. These locations are not accessible during normal execution but are readable and writable during program/verify.

Use only the lower 4 bits of the ID locations and always program the upper 8 bits as '1's.

Note: Microchip will assign a unique pattern number for QTP and SQTP requests and for ROM devices. This pattern number will be unique and traceable to the submitted code.

NOTES:

10.0 INSTRUCTION SET SUMMARY

Each PIC16C5X instruction is a 12-bit word divided into an OPCODE, which specifies the instruction type and one or more operands which further specify the operation of the instruction. The PIC16C5X instruction set summary in Table 10-2 groups the instructions into byte-oriented, bit-oriented, and literal and control operations. Table 10-1 shows the opcode field descriptions.

For **byte-oriented** instructions, 'f' represents a file register designator and 'd' represents a destination designator. The file register designator is used to specify which one of the 32 file registers in that bank is to be used by the instruction.

The destination designator specifies where the result of the operation is to be placed. If 'd' is '0', the result is placed in the W register. If 'd' is '1', the result is placed in the file register specified in the instruction.

For **bit-oriented** instructions, 'b' represents a bit field designator which selects the number of the bit affected by the operation, while 'f' represents the number of the file in which the bit is located.

For **literal and control** operations, 'k' represents an 8 or 9-bit constant or literal value.

TABLE 10-1:	OPCODE FIELD
	DESCRIPTIONS

	DESCRIPTIONS
Field	Description
f	Register file address (0x00 to 0x1F)
W	Working register (accumulator)
b	Bit address within an 8-bit file register
k	Literal field, constant data or label
x	Don't care location (= 0 or 1) The assembler will generate code with $x = 0$. It is the recommended form of use for com-
	patibility with all Microchip software tools.
d	Destination select; d = 0 (store result in W) d = 1 (store result in file register 'f') Default is d = 1
label	Label name
TOS	Top of Stack
PC	Program Counter
WDT	Watchdog Timer Counter
TO	Time-out bit
PD	Power-down bit
dest	Destination, either the W register or the specified register file location
[]	Options
()	Contents
\rightarrow	Assigned to
< >	Register bit field
∈	In the set of
italics	User defined term (font is courier)

All instructions are executed within one single instruction cycle, unless a conditional test is true or the program counter is changed as a result of an instruction. In this case, the execution takes two instruction cycles. One instruction cycle consists of four oscillator periods. Thus, for an oscillator frequency of 4 MHz, the normal instruction execution time would be 1 μ s. If a conditional test is true or the program counter is changed as a result of an instruction, the instruction execution time would be 2 μ s.

Figure 10-1 shows the three general formats that the instructions can have. All examples in the figure use the following format to represent a hexadecimal number:

0xhhh

where 'h' signifies a hexadecimal digit.

FIGURE 10-1: GENERAL FORMAT FOR INSTRUCTIONS

Byte-oriented file register operations									
<u>11 6</u>	5	4 0							
OPCODE	d	f (FILE #)							
d = 1 for destination	d = 0 for destination W d = 1 for destination f f = 5-bit file register address								
Bit-oriented file registe	Bit-oriented file register operations								
11 8	7	5 4 0							
OPCODE	b (Bl	IT #) f (FILE #)							
Literal and control ope	 b = 3-bit bit address f = 5-bit file register address Literal and control operations (except GOTO) 								
11	8	7 0							
OPCODE		k (literal)							
k = 8-bit immedia	k = 8-bit immediate value								
Literal and control ope	Literal and control operations - GOTO instruction								
11	9	8 0							
OPCODE		k (literal)							
k = 9-bit immedia	k = 9-bit immediate value								

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Mnemo	onic,	Description	Cualaa	12-1	Bit Opc	ode	Status	Notoo
Opera	nds	Description	Cycles	MSb		LSb	Affected	Notes
ADDWF	f,d	Add W and f	1	0001	11df	ffff	C,DC,Z	1,2,4
ANDWF	f,d	AND W with f	1	0001	01df	ffff	Z	2,4
CLRF	f	Clear f	1	0000	011f	ffff	Z	4
CLRW	-	Clear W	1	0000	0100	0000	Z	
COMF	f, d	Complement f	1	0010	01df	ffff	Z	
DECF	f, d	Decrement f	1	0000	11df	ffff	Z	2,4
DECFSZ	f, d	Decrement f, Skip if 0	1 ⁽²⁾	0010	11df	ffff	None	2,4
INCF	f, d	Increment f	1	0010	10df	ffff	Z	2,4
INCFSZ	f, d	Increment f, Skip if 0	1 ⁽²⁾	0011	11df	ffff	None	2,4
IORWF	f, d	Inclusive OR W with f	1	0001	00df	ffff	Z	2,4
MOVF	f, d	Move f	1	0010	00df	ffff	Z	2,4
MOVWF	f	Move W to f	1	0000	001f	ffff	None	1,4
NOP	-	No Operation	1	0000	0000	0000	None	
RLF	f, d	Rotate left f through Carry	1	0011	01df	ffff	С	2,4
RRF	f, d	Rotate right f through Carry	1	0011	00df	ffff	С	2,4
SUBWF	f, d	Subtract W from f	1	0000	10df	ffff	C,DC,Z	1,2,4
SWAPF	f, d	Swap f	1	0011	10df	ffff	None	2,4
XORWF	f, d	Exclusive OR W with f	1	0001	10df	ffff	Z	2,4
BIT-ORIEN	TED FIL	E REGISTER OPERATIONS	•					
BCF	f, b	Bit Clear f	1	0100	bbbf	ffff	None	2,4
BSF	f, b	Bit Set f	1	0101	bbbf	ffff	None	2,4
BTFSC	f, b	Bit Test f, Skip if Clear	1 (2)	0110	bbbf	ffff	None	
BTFSS	f, b	Bit Test f, Skip if Set	1 (2)	0111	bbbf	ffff	None	
LITERAL A	ND CON	ITROL OPERATIONS	•					
ANDLW	k	AND literal with W	1	1110	kkkk	kkkk	Z	
CALL	k	Call subroutine	2	1001	kkkk	kkkk	None	1
CLRWDT	k	Clear Watchdog Timer	1	0000	0000	0100	TO, PD	
GOTO	k	Unconditional branch	2	101k	kkkk	kkkk	None	
IORLW	k	Inclusive OR Literal with W	1	1101	kkkk	kkkk	Z	
MOVLW	k	Move Literal to W	1	1100	kkkk	kkkk	None	
OPTION	k	Load OPTION register	1	0000	0000	0010	None	
RETLW	k	Return, place Literal in W	2	1000	kkkk	kkkk	None	
SLEEP	_	Go into standby mode	1	0000	0000	0011	TO, PD	
TRIS	f	Load TRIS register	1	0000	0000	Offf	None	3
XORLW	k	Exclusive OR Literal to W	1	1111	kkkk	kkkk	Z	

TABLE 10-2: INSTRUCTION SET SUMMARY

Note 1: The 9th bit of the program counter will be forced to a '0' by any instruction that writes to the PC except for GOTO (see Section 6.5 for more on program counter).

2: When an I/O register is modified as a function of itself (e.g. MOVF PORTB, 1), the value used will be that value present on the pins themselves. For example, if the data latch is '1' for a pin configured as input and is driven low by an external device, the data will be written back with a '0'.

3: The instruction TRIS f, where f = 5, 6 or 7 causes the contents of the W register to be written to the tristate latches of PORTA, B or C respectively. A '1' forces the pin to a hi-impedance state and disables the output buffers.

4: If this instruction is executed on the TMR0 register (and, where applicable, d = 1), the prescaler will be cleared (if assigned to TMR0).

ADDWF	Add W	and f		
Syntax:	[label] A	DDWF	f,d	
Operands:	$\begin{array}{l} 0 \leq f \leq 31 \\ d \in [0,1] \end{array}$			
Operation:	(W) + (f)	\rightarrow (dest)		
Status Affected:	C, DC, Z			
Encoding:	0001	11df	ffff	
Description:	and regis	ster 'f'. If 'o in the W sult is sto	of the W r d' is 0 the register. I red back	result f 'd' is
Words:	1			
Cycles:	1			
Example:	ADDWF	TEMP_RE	CG, 0	
Before Instr W TEMP_I After Instruc W TEMP_F	= REG = ction =	0x17 0xC2 0xD9 0xC2		

ANDWF	AND W with f
Syntax:	[label] ANDWF f,d
Operands:	$\begin{array}{l} 0 \leq f \leq 31 \\ d \in [0,1] \end{array}$
Operation:	(W) .AND. (f) \rightarrow (dest)
Status Affected:	Z
Encoding:	0001 01df ffff
Description:	The contents of the W register are AND'ed with register 'f'. If 'd' is 0 the result is stored in the W regis- ter. If 'd' is '1' the result is stored back in register 'f'.
Words:	1
Cycles:	1
Example:	ANDWF TEMP_REG, 1
Before Instru W TEMP_ After Instruc W TEMP_	= 0x17 REG = 0xC2 tion = 0x17

ANDLW	AND literal with W
Syntax:	[<i>label</i>] ANDLW k
Operands:	$0 \le k \le 255$
Operation:	(W).AND. (k) \rightarrow (W)
Status Affected:	Z
Encoding:	1110 kkkk kkkk
Description:	The contents of the W register are AND'ed with the eight-bit literal 'k'. The result is placed in the W regis- ter.
Words:	1
Cycles:	1
Example:	ANDLW H'5F'
Before Instru W = After Instruc W =	0xA3

BCF	Bit Clea	r f		
Syntax:	[label]	BCF f,ł)	
Operands:	$\begin{array}{l} 0 \leq f \leq 3^{\prime} \\ 0 \leq b \leq 7 \end{array}$	-		
Operation:	$0 \rightarrow (f < b$	>)		
Status Affected:	None			
Encoding:	0100	bbbf	ffff	
Description:	Bit 'b' in	register 'f'	is cleared.	
Words:	1			
Cycles:	1			
Example:	BCF	FLAG_RE	IG, 7	
Before Instru FLAG_F After Instruct	REG =	0xC7		
FLAG_F	REG =	0x47		

BSF	Bit Set f			
Syntax:	[label]	BSF f,b		
Operands:	$\begin{array}{l} 0 \leq f \leq 31 \\ 0 \leq b \leq 7 \end{array}$			
Operation:	$1 \rightarrow (f < b$	>)		
Status Affected:	None			
Encoding:	0101	bbbf	ffff	
Description:	Bit 'b' in ı	register 'f'	is set.	
Words:	1			
Cycles:	1			
Example:	BSF	FLAG_RE	G, 7	
After Instruc	REG = 0			
FLAG_F	REG = 0	IXOA		

BTFSC	Bit Test f, Skip if Clear
Syntax:	[label] BTFSC f,b
Operands:	$\begin{array}{l} 0 \leq f \leq 31 \\ 0 \leq b \leq 7 \end{array}$
Operation:	skip if $(f < b >) = 0$
Status Affected:	None
Encoding:	0110 bbbf ffff
Description:	If bit 'b' in register 'f' is 0 then the next instruction is skipped. If bit 'b' is 0 then the next instruc- tion fetched during the current instruction execution is discarded, and a NOP is executed instead, making this a 2-cycle instruction.
Words:	1
Cycles:	1(2)
Example:	HERE BTFSC FLAG,1 FALSE GOTO PROCESS_CODE TRUE • •
Before Instru	uction
PC After Instruct if FLAG PC if FLAG PC	<pre><1> = 0, = address (TRUE);</pre>

BTFSS	Bit Test	f, Skip if	Set	
Syntax:	[label]	BTFSS f	,b	
Operands:	$0 \le f \le 31$			
	0 ≤ b < 7			
Operation:	skip if (f<	:b>) = 1		
Status Affected:	None			
Encoding:	0111	bbbf	ffff	
Description:	next instr If bit 'b' is tion fetch instructio and a NO	ruction is s '1', then led during n executi P is exec	'f' is '1' then i skipped. the next inst g the current on, is discard uted instead. ccle instructio	ruc- ded
Words:	1			
Cycles:	1(2)			
Example:	HERE FALSE TRUE	BTFSS GOTO •	FLAG,1 PROCESS_C	ODE
Before Inst	ruction			
PC After Instru	=	addres	SS (HERE)	
After Instru If FLAG PC if FLAG	<1> =	0, addres 1,	SS (FALSE);	
PC	=	addres	SS (TRUE)	

CALL	Subroutine Call
Syntax:	[<i>label</i>] CALL k
Operands:	$0 \leq k \leq 255$
Operation:	$\begin{array}{l} (PC) + 1 \rightarrow TOS; \\ k \rightarrow PC < 7:0 >; \\ (STATUS < 6:5 >) \rightarrow PC < 10:9 >; \\ 0 \rightarrow PC < 8 > \end{array}$
Status Affected:	None
Encoding:	1001 kkkk kkkk
Description:	Subroutine call. First, return address (PC+1) is pushed onto the stack. The eight bit immediate address is loaded into PC bits <7:0>. The upper bits PC<10:9> are loaded from STATUS<6:5>, PC<8> is cleared. CALL is a two- cycle instruction.
Words:	1
Cycles:	2
Example:	HERE CALL THERE
After Instruct	address (HERE) ion address (THERE)

CLRF	Clear f
	Oloui I

Syntax:	[label]	CLRF f	
Operands:	$0 \le f \le 3^{-1}$	1	
Operation:	$00h \rightarrow (f 1 \rightarrow Z$);	
Status Affected:	Z		
Encoding:	0000	011f	ffff
Description:		ents of re and the Z	gister 'f' are bit is set.
Words:	1		
Cycles:	1		
Example:	CLRF	FLAG_RE	IG
Before Instru FLAG_R After Instruct	EG =	0x5A	
FLAG_R Z	EG = =	0x00 1	

CLRW	Clear W
Syntax:	[label] CLRW
Operands:	None
Operation:	$\begin{array}{l} 00h \rightarrow (W); \\ 1 \rightarrow Z \end{array}$
Status Affected:	Z
Encoding:	0000 0100 0000
Description:	The W register is cleared. Zero bit (Z) is set.
Words:	1
Cycles:	1
Example:	CLRW
W = After Instruct	ion
W = Z =	1
Z =	Clear Watchdog Timer
Z = CLRWDT Syntax:	Clear Watchdog Timer
Z = CLRWDT Syntax: Operands:	Clear Watchdog Timer [label] CLRWDT None
Z = CLRWDT Syntax:	Clear Watchdog Timer
Z = CLRWDT Syntax: Operands:	Clear Watchdog Timer [<i>label</i>] CLRWDT None $00h \rightarrow WDT;$ $0 \rightarrow WDT$ prescaler (if assigned); $1 \rightarrow TO;$
Z = CLRWDT Syntax: Operands: Operation:	Clear Watchdog Timer [<i>label</i>] CLRWDT None $00h \rightarrow WDT;$ $0 \rightarrow WDT$ prescaler (if assigned); $1 \rightarrow \overline{TO};$ $1 \rightarrow \overline{PD}$
Z = CLRWDT Syntax: Operands: Operation: Status Affected:	Clear Watchdog Timer [<i>label</i>] CLRWDT None $00h \rightarrow WDT;$ $0 \rightarrow WDT$ prescaler (if assigned); $1 \rightarrow \overline{TO};$ $1 \rightarrow \overline{PD}$ $\overline{TO}, \overline{PD}$
Z = CLRWDT Syntax: Operands: Operation: Status Affected: Encoding:	Clear Watchdog Timer[label] CLRWDTNone $00h \rightarrow WDT;$ $0 \rightarrow WDT$ prescaler (if assigned); $1 \rightarrow \overline{TO};$ $1 \rightarrow \overline{PD}$ $\overline{TO}, \overline{PD}$ $0000 0000 0100$ The CLRWDT instruction resets theWDT. It also resets the prescaler, ifthe prescaler is assigned to theWDT and not Timer0. Status bits
Z = CLRWDT Syntax: Operands: Operation: Status Affected: Encoding: Description:	Clear Watchdog Timer[label] CLRWDTNone $00h \rightarrow WDT$; $0 \rightarrow WDT$ prescaler (if assigned); $1 \rightarrow \overline{TO}$; $1 \rightarrow \overline{PD}$ \overline{TO} , \overline{PD} 0000 0000 0100 The CLRWDT instruction resets theWDT. It also resets the prescaler, ifthe prescaler is assigned to theWDT and not Timer0. Status bitsTO and \overline{PD} are set.

After Instruction		
WDT counter	=	0x00
WDT prescaler	=	0
TO	=	1
PD	=	1

COMF	Complement f
Syntax:	[label] COMF f,d
Operands:	$\begin{array}{l} 0\leq f\leq 31\\ d\in [0,1] \end{array}$
Operation:	$(\overline{f}) \rightarrow (dest)$
Status Affected:	Z
Encoding:	0010 01df ffff
Description:	The contents of register 'f' are complemented. If 'd' is 0 the result is stored in the W register. If 'd' is 1 the result is stored back in register 'f'.
Words:	1
Cycles:	1
Example:	COMF REG1,0
Before Instru REG1 After Instruct REG1 W	= 0x13

DECF	Decreme	ent f		
Syntax:	[label]	DECF f,	d	
Operands:	$\begin{array}{l} 0 \leq f \leq 31 \\ d \in [0,1] \end{array}$			
Operation:	$(f) - 1 \rightarrow$	(dest)		
Status Affected:	Z			
Encoding:	0000	11df	ffff	
Description:	Decreme result is s 'd' is 1 th register 'f	stored in the result is		jister. If
Words:	1			
Cycles:	1			
Example:	DECF	CNT,	1	
Before Instru CNT Z After Instruct CNT Z	= 0 = 0 ion	<01		

DECFSZ	Decrement f, Skip if 0
Syntax:	[label] DECFSZ f,d
Operands:	$\begin{array}{l} 0\leq f\leq 31\\ d\in [0,1] \end{array}$
Operation:	(f) $-1 \rightarrow d$; skip if result = 0
Status Affected:	None
Encoding:	0010 11df ffff
Description:	The contents of register 'f' are dec- remented. If 'd' is 0 the result is placed in the W register. If 'd' is 1 the result is placed back in register 'f'. If the result is 0, the next instruc- tion, which is already fetched, is discarded and a NOP is executed instead making it a two-cycle instruction.
Words:	1
Cycles:	1(2)
Example:	HERE DECFSZ CNT, 1 GOTO LOOP CONTINUE • •
Before Instru PC	= address (HERE)
After Instruct CNT if CNT PC if CNT PC	tion = CNT - 1; = 0, = address (CONTINUE); ≠ 0, = address (HERE+1)

GOTO	Uncondi	tional B	anch
Syntax:	[label]	GOTO	k
Operands:	$0 \le k \le 5^{-1}$	11	
Operation:	$k \rightarrow PC < STATUS$,	PC<10:9>
Status Affected:	None		
Encoding:	101k	kkkk	kkkk
Description:	The 9-bit loaded in upper bit	immedia to PC bit s of PC a <6:5>. GC	ditional branch. te value is s <8:0>. The re loaded from pTO is a two-
Words:	1		
Cycles:	2		
Example:	GOTO TH	IERE	
After Instruct PC =	ion address	G (THER	E)

INCF	Increment f
Syntax:	[label] INCF f,d
Operands:	$\begin{array}{l} 0 \leq f \leq 31 \\ d \in [0,1] \end{array}$
Operation:	(f) + 1 \rightarrow (dest)
Status Affected:	Z
Encoding:	0010 10df ffff
Description:	The contents of register 'f' are incremented. If 'd' is 0 the result is placed in the W register. If 'd' is 1 the result is placed back in register 'f'.
Words:	1
Cycles:	1
Example:	INCF CNT, 1
Before Instru CNT Z After Instruct CNT Z	= 0xFF = 0

INCFSZ	Increment f, Skip if 0
Syntax:	[label] INCFSZ f,d
Operands:	$\begin{array}{l} 0\leq f\leq 31\\ d\in [0,1] \end{array}$
Operation:	(f) + 1 \rightarrow (dest), skip if result = 0
Status Affected:	None
Encoding:	0011 11df ffff
Description:	The contents of register 'f' are incremented. If 'd' is 0 the result is placed in the W register. If 'd' is 1 the result is placed back in register 'f'. If the result is 0, then the next instruction, which is already fetched, is discarded and a NOP is executed instead making it a two- cycle instruction.
Words:	1
Cycles:	1(2)
Example:	HERE INCFSZ CNT, 1 GOTO LOOP CONTINUE • • •
Before Instru PC After Instruc	= address (HERE)
CNT if CNT PC if CNT PC	<pre>= CNT + 1; = 0, = address (CONTINUE); ≠ 0, = address (HERE +1)</pre>

IORLW	Inclusive OR literal with W
Syntax:	[<i>label</i>] IORLW k
Operands:	$0 \leq k \leq 255$
Operation:	(W) .OR. (k) \rightarrow (W)
Status Affected:	Z
Encoding:	1101 kkkk kkkk
Description:	The contents of the W register are OR'ed with the eight bit literal 'k'. The result is placed in the W regis- ter.
Words:	1
Cycles:	1
Example:	IORLW 0x35
Before Instru W = After Instruc W = Z =	0x9A tion

IORWF	Inclusive OR W with f
Syntax:	[<i>label</i>] IORWF f,d
Operands:	$\begin{array}{l} 0\leq f\leq 31\\ d\in [0,1] \end{array}$
Operation:	(W).OR. (f) \rightarrow (dest)
Status Affected:	Z
Encoding:	0001 00df ffff
Description:	Inclusive OR the W register with register 'f'. If 'd' is 0 the result is placed in the W register. If 'd' is 1 the result is placed back in register 'f'.
Words:	1
Cycles:	1
Example:	IORWF RESULT, 0
Before Instru RESUL W After Instruct RESUL W Z	Γ = 0x13 = 0x91 tion

MOVF	Move f
Syntax:	[<i>label</i>] MOVF f,d
Operands:	$\begin{array}{l} 0\leq f\leq 31\\ d\in [0,1] \end{array}$
Operation:	$(f) \rightarrow (dest)$
Status Affected:	Z
Encoding:	0010 00df ffff
Description:	The contents of register 'f' is moved to destination 'd'. If 'd' is 0, destination is the W register. If 'd' is 1, the destination is file register 'f'. 'd' is 1 is useful to test a file register since status flag Z is affected.
Words:	1
Cycles:	1
Example:	MOVF FSR, 0
After Instruct W =	tion - value in FSR register

MOVLW	Move Lit	teral to W	I	
Syntax:	[label]	MOVLW	k	
Operands:	$0 \leq k \leq 2$	55		
Operation:	$k \rightarrow (W)$			
Status Affected:	None			
Encoding:	1100	kkkk	kkkk	
Description:	The eigh the W re		'k' is loaded	d into
Words:	1			
Cycles:	1			
Example:	MOVLW	0x5A		
After Instruct W =	ion 0x5A			

MOVWF	Move W to f
Syntax:	[<i>label</i>] MOVWF f
Operands:	$0 \leq f \leq 31$
Operation:	$(W) \rightarrow (f)$
Status Affected:	None
Encoding:	0000 001f ffff
Description:	Move data from the W register to
	register 'f'.
Words:	1
Cycles:	1
Example:	MOVWF TEMP_REG
W After Instruct	REG = 0xFF $= 0x4F$

NOP	No Oper	ation		
Syntax:	[label]	NOP		
Operands:	None			
Operation:	No opera	ation		
Status Affected:	None			
Encoding:	0000	0000	0000	
Description:	No opera	ation.		
Words:	1			
Cycles:	1			
Example:	NOP			

OPTION	Load Ol		egister	
Syntax:	[label]	OPTIO	N	
Operands:	None			
Operation:	$(W) \rightarrow C$	PTION		
Status Affected:	None			
Encoding:	0000	0000	0010	
Description:		tent of the	0	
Words:	1			
Cycles:	1			
Example	OPTION			
Before Instru	ction			
W	•	07		
After Instructi				
OPTION	= 0x	07		

RETLW	Return with Literal in W
Syntax:	[<i>label</i>] RETLW k
Operands:	$0 \leq k \leq 255$
Operation:	$k \rightarrow (W);$ TOS \rightarrow PC
Status Affected:	None
Encoding:	1000 kkkk kkkk
Description:	The W register is loaded with the eight bit literal 'k'. The program counter is loaded from the top of the stack (the return address). This is a two-cycle instruction.
Words:	1
Cycles:	2
Example:	CALL TABLE ;W contains ;table offset ;value. • ;W now has table • ;value.
TABLE	<pre>ADDWF PC ;W = offset RETLW k1 ;Begin table RETLW k2 ;</pre>
Before Instru	
W After Instruct	= 0x07
After Instruct W	ion = value of k8

RLF	Rotate Left f through Carry			
Syntax:	[<i>label</i>] RLF f,d			
Operands:	$\begin{array}{l} 0 \leq f \leq 31 \\ d \in [0,1] \end{array}$			
Operation:	See description below			
Status Affected:	С			
Encoding:	0011 01df ffff			
Description:	The contents of register 'f' are rotated one bit to the left through the Carry Flag (STATUS<0>). If 'd' is 0 the result is placed in the W register. If 'd' is 1 the result is stored back in register 'f'.			
Words:	1			
Cycles:	1			
Example:	RLF REG1,0			
Before Instru REG1 C After Instruct	= 1110 0110 = 0 tion			
REG1 W C	= 1110 0110 = 1100 1100 = 1			

RRF	Rotate Right f through Carry		
Syntax:	[<i>label</i>] RRF f,d		
Operands:	$\begin{array}{l} 0\leq f\leq 31\\ d\in [0,1] \end{array}$		
Operation:	See description below		
Status Affected:	С		
Encoding:	0011 00df ffff		
Description:	The contents of register 'f' are rotated one bit to the right through the Carry Flag (STATUS<0>). If 'd' is 0 the result is placed in the W register. If 'd' is 1 the result is placed back in register 'f'.		
Words:	1		
Cycles:	1		
Example:	RRF REG1,0		
Before Instru REG1 C After Instruct	$= 1110 0110 \\ = 0$		
REG1 W C	= 1110 0110 = 0111 0011 = 0		

SLEEP	Enter SLEEP Mode
Syntax:	[<i>label</i>] SLEEP
Operands:	None
Operation:	$\begin{array}{l} 00h \rightarrow WDT; \\ 0 \rightarrow WDT \text{ prescaler; if assigned} \\ 1 \rightarrow \overline{TO}; \\ 0 \rightarrow \overline{PD} \end{array}$
Status Affected:	TO, PD
Encoding:	0000 0000 0011
Description:	Time-out status bit (\overline{TO}) is set. The power-down status bit (\overline{PD}) is cleared. The WDT and its pres- caler are cleared. The processor is put into SLEEP mode with the oscillator stopped. See section on SLEEP for more details.
Words:	1
Cycles:	1
Example:	SLEEP

SUBWF	Subt	ract W	from f
Syntax:	[label	JSL	JBWF f,d
Operands:	$0 \le f$	≤ 31	
•	d ∈ [0	D,1]	
Operation:	(f) – (W) \rightarrow	(dest)
Status Affected:	C, DO	C, Z	
Encoding:	000	- 1	Odf ffff
Description:			s complement method) ter from register 'f'. If 'd'
	is 0 tł regist	ne resu er. If 'o	It is stored in the W I' is 1 the result is in register 'f'.
Words:	1		
Cycles:	1		
Example 1:	SUBW	FF	REG1, 1
Before Instru	ction		
REG1	=	3	
W	=	2	
С	=	?	
After Instruct	ion		
REG1	=	1	
W C	=	2 1	, recult is positive
Example 2:	=	I	; result is positive
Before Instru	ction		
REG1	=	2	
W	=	2	
C	=	?	
After Instruct	ion		
REG1	=	0	
W	=	2	
С	=	1	; result is zero
Example 3:			
Before Ins	tructio		
REG1	=	1	
W	=	2	
C	=	?	
After Instruct		0.VEE	
REG1 W	=	0xFF 2	
C	_	2	; result is negative
Ũ	-	U	, isourio nogativo

SWAPF	Swap Nibbles in f
Syntax:	[label] SWAPF f,d
Operands:	$\begin{array}{l} 0 \leq f \leq 31 \\ d \in [0,1] \end{array}$
Operation:	$(f<3:0>) \rightarrow (dest<7:4>);$ $(f<7:4>) \rightarrow (dest<3:0>)$
Status Affected:	None
Encoding:	0011 10df ffff
Description:	The upper and lower nibbles of register 'f' are exchanged. If 'd' is 0 the result is placed in W register. If 'd' is 1 the result is placed in register 'f'.
Words:	1
Cycles:	1
Example	SWAPF REG1, 0
REG1 After Instruct REG1 W	= 0xA5 ion = 0xA5 = 0x5A
TRIS	Load TRIS Register
Syntax:	[<i>label</i>] TRIS f
Operands:	f = 5, 6 or 7
Operation:	(W) \rightarrow TRIS register f
Status Affected:	None
Encoding:	0000 0000 0fff
Description:	TRIS register 'f' ($f = 5, 6, or 7$) is loaded with the contents of the W register.
Words:	1
Cycles:	1
Example	TRIS PORTB
Before Instru W After Instructi TRISB	= 0xA5 on

XORLW	Exclusiv	e OR lite	eral with	w
Syntax:	[label]	XORLW	k	
Operands:	$0 \le k \le 2$	55		
Operation:	(W) .XOF	$R. k \to (W$	/)	
Status Affected:	Z			
Encoding:	1111	kkkk	kkkk	
Description:	XOR'ed	with the e	e W regis eight bit lit ed in the V	eral 'k'.
Words:	1			
Cycles:	1			
Example:	XORLW	0xAF		
Before Instru W = After Instruct W =	0xB5			

Exclusive OR W with f				
[label] XORWF f,d	-			
$\begin{array}{l} 0 \leq f \leq 31 \\ d \in [0,1] \end{array}$				
(W) .XOR. (f) \rightarrow (dest)	(W) .XOR. (f) \rightarrow (dest)			
ted: Z				
0001 10df ffff				
W register with register 'f'. If 'd' is 0 the result is stored in the W regis- ter. If 'd' is 1 the result is stored back in register 'f'.				
1				
1				
XORWF REG,1				
Instruction G = 0xAF = 0xB5 struction G = 0x1A = 0xB5				
the result is stored in t ter. If 'd' is 1 the result back in register 'f'. 1 1 XORWF REG, 1 nstruction G = 0xAF = 0xB5 struction	er 'f'. If 'd' is 0 the W regis-			

11.0 DEVELOPMENT SUPPORT

The PIC[®] microcontrollers are supported with a full range of hardware and software development tools:

- Integrated Development Environment
 - MPLAB[®] IDE Software
- Assemblers/Compilers/Linkers
 - MPASM[™] Assembler
 - MPLAB C17 and MPLAB C18 C Compilers
 - MPLINK™ Object Linker/
 - MPLIB[™] Object Librarian
- Simulators
 - MPLAB SIM Software Simulator
- Emulators
 - MPLAB ICE 2000 In-Circuit Emulator
 - ICEPIC[™] In-Circuit Emulator
- In-Circuit Debugger
- MPLAB ICD
- Device Programmers
 - PRO MATE[®] II Universal Device Programmer
- PICSTART[®] Plus Entry-Level Development Programmer
- Low Cost Demonstration Boards
 - PICDEM[™]1 Demonstration Board
 - PICDEM 2 Demonstration Board
 - PICDEM 3 Demonstration Board
 - PICDEM 17 Demonstration Board
 - KEELOQ[®] Demonstration Board

11.1 MPLAB Integrated Development Environment Software

The MPLAB IDE software brings an ease of software development previously unseen in the 8-bit microcontroller market. The MPLAB IDE is a Windows[®]-based application that contains:

- An interface to debugging tools
 - simulator
 - programmer (sold separately)
 - emulator (sold separately)
 - in-circuit debugger (sold separately)
- A full-featured editor
- A project manager
- Customizable toolbar and key mapping
- A status bar
- On-line help

The MPLAB IDE allows you to:

- Edit your source files (either assembly or 'C')
- One touch assemble (or compile) and download to PIC MCU emulator and simulator tools (automatically updates all project information)
- Debug using:
 - source files
 - absolute listing file
 - machine code

The ability to use MPLAB IDE with multiple debugging tools allows users to easily switch from the cost-effective simulator to a full-featured emulator with minimal retraining.

11.2 MPASM Assembler

The MPASM assembler is a full-featured universal macro assembler for all PIC MCUs.

The MPASM assembler has a command line interface and a Windows shell. It can be used as a stand-alone application on a Windows 3.x or greater system, or it can be used through MPLAB IDE. The MPASM assembler generates relocatable object files for the MPLINK object linker, Intel[®] standard HEX files, MAP files to detail memory usage and symbol reference, an absolute LST file that contains source lines and generated machine code, and a COD file for debugging.

The MPASM assembler features include:

- Integration into MPLAB IDE projects.
- User-defined macros to streamline assembly code.
- Conditional assembly for multi-purpose source files.
- Directives that allow complete control over the assembly process.

11.3 MPLAB C17 and MPLAB C18 C Compilers

The MPLAB C17 and MPLAB C18 Code Development Systems are complete ANSI 'C' compilers for Microchip's PIC17CXXX and PIC18CXXX family of microcontrollers, respectively. These compilers provide powerful integration capabilities and ease of use not found with other compilers.

For easier source level debugging, the compilers provide symbol information that is compatible with the MPLAB IDE memory display.

11.4 MPLINK Object Linker/ MPLIB Object Librarian

The MPLINK object linker combines relocatable objects created by the MPASM assembler and the MPLAB C17 and MPLAB C18 C compilers. It can also link relocatable objects from pre-compiled libraries, using directives from a linker script.

The MPLIB object librarian is a librarian for precompiled code to be used with the MPLINK object linker. When a routine from a library is called from another source file, only the modules that contain that routine will be linked in with the application. This allows large libraries to be used efficiently in many different applications. The MPLIB object librarian manages the creation and modification of library files.

The MPLINK object linker features include:

- Integration with MPASM assembler and MPLAB C17 and MPLAB C18 C compilers.
- Allows all memory areas to be defined as sections to provide link-time flexibility.

The MPLIB object librarian features include:

- Easier linking because single libraries can be included instead of many smaller files.
- Helps keep code maintainable by grouping related modules together.
- Allows libraries to be created and modules to be added, listed, replaced, deleted or extracted.

11.5 MPLAB SIM Software Simulator

The MPLAB SIM software simulator allows code development in a PC-hosted environment by simulating the PIC series microcontrollers on an instruction level. On any given instruction, the data areas can be examined or modified and stimuli can be applied from a file, or user-defined key press, to any of the pins. The execution can be performed in single step, execute until break, or trace mode.

The MPLAB SIM simulator fully supports symbolic debugging using the MPLAB C17 and the MPLAB C18 C compilers and the MPASM assembler. The software simulator offers the flexibility to develop and debug code outside of the laboratory environment, making it an excellent multiproject software development tool.

11.6 MPLAB ICE High Performance Universal In-Circuit Emulator with MPLAB IDE

The MPLAB ICE universal in-circuit emulator is intended to provide the product development engineer with a complete microcontroller design tool set for PIC microcontrollers (MCUs). Software control of the MPLAB ICE in-circuit emulator is provided by the MPLAB Integrated Development Environment (IDE), which allows editing, building, downloading and source debugging from a single environment.

The MPLAB ICE 2000 is a full-featured emulator system with enhanced trace, trigger and data monitoring features. Interchangeable processor modules allow the system to be easily reconfigured for emulation of different processors. The universal architecture of the MPLAB ICE in-circuit emulator allows expansion to support new PIC microcontrollers.

The MPLAB ICE in-circuit emulator system has been designed as a real-time emulation system, with advanced features that are generally found on more expensive development tools. The PC platform and Microsoft[®] Windows environment were chosen to best make these features available to you, the end user.

11.7 ICEPIC In-Circuit Emulator

The ICEPIC low cost, in-circuit emulator is a solution for the Microchip Technology PIC16C5X, PIC16C6X, PIC16C7X and PIC16CXXX families of 8-bit One-Time-Programmable (OTP) microcontrollers. The modular system can support different subsets of PIC16C5X or PIC16CXXX products through the use of interchangeable personality modules, or daughter boards. The emulator is capable of emulating without target application circuitry being present.

11.8 MPLAB ICD In-Circuit Debugger

Microchip's In-Circuit Debugger, MPLAB ICD, is a powerful, low cost, run-time development tool. This tool is based on the FLASH PIC MCUs and can be used to develop for this and other PIC microcontrollers. The MPLAB ICD utilizes the in-circuit debugging capability built into the FLASH devices. This feature, along with Microchip's In-Circuit Serial ProgrammingTM protocol, offers cost-effective in-circuit FLASH debugging from the graphical user interface of the MPLAB Integrated Development Environment. This enables a designer to develop and debug source code by watching variables, single-stepping and setting break points. Running at full speed enables testing hardware in real-time.

11.9 PRO MATE II Universal Device Programmer

The PRO MATE II universal device programmer is a full-featured programmer, capable of operating in Stand-alone mode, as well as PC-hosted mode. The PRO MATE II device programmer is CE compliant.

The PRO MATE II device programmer has programmable VDD and VPP supplies, which allow it to verify programmed memory at VDD min and VDD max for maximum reliability. It has an LCD display for instructions and error messages, keys to enter commands and a modular detachable socket assembly to support various package types. In Stand-alone mode, the PRO MATE II device programmer can read, verify, or program PIC devices. It can also set code protection in this mode.

11.10 PICSTART Plus Entry Level Development Programmer

The PICSTART Plus development programmer is an easy-to-use, low cost, prototype programmer. It connects to the PC via a COM (RS-232) port. MPLAB Integrated Development Environment software makes using the programmer simple and efficient.

The PICSTART Plus development programmer supports all PIC devices with up to 40 pins. Larger pin count devices, such as the PIC16C92X and PIC17C76X, may be supported with an adapter socket. The PICSTART Plus development programmer is CE compliant.

11.11 PICDEM 1 Low Cost PIC MCU Demonstration Board

The PICDEM 1 demonstration board is a simple board which demonstrates the capabilities of several of Microchip's microcontrollers. The microcontrollers supported are: PIC16C5X (PIC16C54 to PIC16C58A). PIC16C61, PIC16C62X, PIC16C71, PIC16C8X, PIC17C42, PIC17C43 and PIC17C44. All necessary hardware and software is included to run basic demo programs. The user can program the sample microcontrollers provided with the PICDEM 1 demonstration board on a PRO MATE II device programmer, or a PICSTART Plus development programmer, and easily test firmware. The user can also connect the PICDEM 1 demonstration board to the MPLAB ICE incircuit emulator and download the firmware to the emulator for testing. A prototype area is available for the user to build some additional hardware and connect it to the microcontroller socket(s). Some of the features include an RS-232 interface, a potentiometer for simulated analog input, push button switches and eight LEDs connected to PORTB.

11.12 PICDEM 2 Low Cost PIC16CXX Demonstration Board

The PICDEM 2 demonstration board is a simple demonstration board that supports the PIC16C62, PIC16C64, PIC16C65, PIC16C73 and PIC16C74 microcontrollers. All the necessary hardware and software is included to run the basic demonstration programs. The user can program the sample microcontrollers provided with the PICDEM 2 demonstration board on a PRO MATE II device programmer, or a PICSTART Plus development programmer, and easily test firmware. The MPLAB ICE in-circuit emulator may also be used with the PICDEM 2 demonstration board to test firmware. A prototype area has been provided to the user for adding additional hardware and connecting it to the microcontroller socket(s). Some of the features include a RS-232 interface, push button switches, a potentiometer for simulated analog input, a serial EEPROM to demonstrate usage of the I^2C^{TM} bus and separate headers for connection to an LCD module and a keypad.

11.13 PICDEM 3 Low Cost PIC16CXXX Demonstration Board

The PICDEM 3 demonstration board is a simple demonstration board that supports the PIC16C923 and PIC16C924 in the PLCC package. It will also support future 44-pin PLCC microcontrollers with an LCD Module. All the necessary hardware and software is included to run the basic demonstration programs. The user can program the sample microcontrollers provided with the PICDEM 3 demonstration board on a PRO MATE II device programmer, or a PICSTART Plus development programmer with an adapter socket, and easily test firmware. The MPLAB ICE in-circuit emulator may also be used with the PICDEM 3 demonstration board to test firmware. A prototype area has been provided to the user for adding hardware and connecting it to the microcontroller socket(s). Some of the features include a RS-232 interface, push button switches, a potentiometer for simulated analog input, a thermistor and separate headers for connection to an external LCD module and a keypad. Also provided on the PICDEM 3 demonstration board is a LCD panel, with 4 commons and 12 segments, that is capable of displaying time, temperature and day of the week. The PICDEM 3 demonstration board provides an additional RS-232 interface and Windows software for showing the demultiplexed LCD signals on a PC. A simple serial interface allows the user to construct a hardware demultiplexer for the LCD signals.

11.14 PICDEM 17 Demonstration Board

The PICDEM 17 demonstration board is an evaluation board that demonstrates the capabilities of several Microchip microcontrollers, including PIC17C752, PIC17C756A, PIC17C762 and PIC17C766. All necessary hardware is included to run basic demo programs, which are supplied on a 3.5-inch disk. A programmed sample is included and the user may erase it and program it with the other sample programs using the PRO MATE II device programmer, or the PICSTART Plus development programmer, and easily debug and test the sample code. In addition, the PICDEM 17 demonstration board supports downloading of programs to and executing out of external FLASH memory on board. The PICDEM 17 demonstration board is also usable with the MPLAB ICE in-circuit emulator, or the PICMASTER emulator and all of the sample programs can be run and modified using either emulator. Additionally, a generous prototype area is available for user hardware.

11.15 KEELOQ Evaluation and Programming Tools

KEELOQ evaluation and programming tools support Microchip's HCS Secure Data Products. The HCS evaluation kit includes a LCD display to show changing codes, a decoder to decode transmissions and a programming interface to program test transmitters.

TABLE 11-1: DEVELOPMENT TOOLS FROM MICROCHIP

	- - - -	6 33 520 540 540 540 540 540 540 540 540 540 54	мсь мс <i>в</i>
MPLAB [®] C17 C complex I	> > > >	>	
MPLAB [®] C18 C compiler I		· · ·	
MPASN™ Assembler/ MPLNW™ Object Linker ×		× ×	
MPLAB® (CE In-Circuit Emulator	> > > >	> > > >	×
ICEPIC ^M In-Circuit Emulator ✓ <t< th=""><th>× × ×</th><th></th><th></th></t<>	× × ×		
MPLAB® ICD In-Circuit ·· </th <th>></th> <th></th> <th></th>	>		
PICSTART® Plus Entry Level <th< th=""><th></th><th>></th><th></th></th<>		>	
PRO MATE® II · · · · · · · · · · · · · · · · · · ·	> > >	> >	
PICDEMTW 1 Demonstration <	> > >	> > > >	`
PICDEMTW 2 Demonstration	>		
PICDEMTW 3 Demonstration PICDEMTW 3 Demonstration PICDEMTW 14A Demonstration PIC	×+	>	
PICDEM TM 14A Demonstration Board PICDEM TM 17 Demonstration Board KEELoa [®] Evaluation Kit KEELoa [®] Transponder Kit microlD TM Programmer's Kit 125 KHz microlD TM	*		
		>	
			
			>
			>
Developer's Kit			>
125 kHz Anticollision microlD TM Developer's Kit			>
13.56 MHz Anticollision microlD TM Developer's Kit			>
MCP2510 CAN Developer's Kit			×

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NOTES:

12.0 ELECTRICAL CHARACTERISTICS - PIC16C54A

Absolute Maximum Ratings^(†)

Ambient Temperature under bias	–55°C to +125°C
Storage Temperature	65°C to +150°C
Voltage on VDD with respect to VSS	0V to +7.5V
Voltage on MCLR with respect to Vss ⁽¹⁾	0V to +14V
Voltage on all other pins with respect to Vss	0.6V to (VDD + 0.6V)
Total power dissipation ⁽²⁾	800 mW
Max. current out of Vss pin	150 mA
Max. current into Vod pin	100 mA
Max. current into an input pin (T0CKI only)	±500 μA
Input clamp current, Iк (Vi < 0 or Vi > VDD)	±20 mA
Output clamp current, IOK (VO < 0 or VO > VDD)	±20 mA
Max. output current sunk by any I/O pin	25 mA
Max. output current sourced by any I/O pin	20 mA
Max. output current sourced by a single I/O port (PORTA, B or C)	40 mA
Max. output current sunk by a single I/O port (PORTA, B or C)	50 mA

- **Note 1:** Voltage spikes below Vss at the $\overline{\text{MCLR}}$ pin, inducing currents greater than 80 mA, may cause latch-up. Thus, a series resistor of 50 to 100 Ω should be used when applying a "low" level to the $\overline{\text{MCLR}}$ pin rather than pulling this pin directly to Vss.
 - 2: Power Dissipation is calculated as follows: Pdis = VDD x {IDD Σ IOH} + Σ {(VDD VOH) x IOH} + Σ (VOL x IOL)

† NOTICE: Stresses above those listed under "Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operation listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

12.1 DC Characteristics: PIC16C54/55/56/57-RC, XT, 10, HS, LP (Commercial)

PIC16C54/55/56/57-RC, XT, 10, HS, LP (Commercial)			Standard Operating Conditions (unless otherwise specified) Operating Temperature $0^{\circ}C \le TA \le +70^{\circ}C$ for commercial					
Param No.	Symbol	Characteristic/Device	Min	Тур†	Max	Units	Conditions	
D001	Vdd	Supply Voltage PIC16C5X-RC PIC16C5X-XT PIC16C5X-10 PIC16C5X-HS PIC16C5X-LP	3.0 3.0 4.5 4.5 2.5		6.25 6.25 5.5 5.5 6.25	V V V V		
D002	Vdr	RAM Data Retention Voltage ⁽¹⁾	_	1.5*	_	V	Device in SLEEP Mode	
D003	VPOR	VDD Start Voltage to ensure Power-on Reset		Vss	—	V	See Section 5.1 for details on Power-on Reset	
D004	SVDD	VDD Rise Rate to ensure Power-on Reset	0.05*		—	V/ms	See Section 5.1 for details on Power-on Reset	
D010	IDD	Supply Current ⁽²⁾ PIC16C5X-RC ⁽³⁾ PIC16C5X-XT PIC16C5X-10 PIC16C5X-HS PIC16C5X-HS PIC16C5X-LP	 	1.8 1.8 4.8 4.8 9.0 15	3.3 3.3 10 10 20 32	mA mA mA mA μA	Fosc = 4 MHz, VDD = $5.5V$ Fosc = 4 MHz, VDD = $5.5V$ Fosc = 10 MHz, VDD = $5.5V$ Fosc = 10 MHz, VDD = $5.5V$ Fosc = 20 MHz, VDD = $5.5V$ Fosc = 32 kHz, VDD = $3.0V$, WDT disabled	
D020	Ipd	Power-down Current ⁽²⁾	—	4.0 0.6	12 9	μΑ μΑ	VDD = 3.0V, WDT enabled VDD = 3.0V, WDT disabled	

* These parameters are characterized but not tested.

† Data in "Typ" column is based on characterization results at 25°C. This data is for design guidance only and is not tested.

Note 1: This is the limit to which VDD can be lowered in SLEEP mode without losing RAM data.

2: The supply current is mainly a function of the operating voltage and frequency. Other factors such as bus loading, oscillator type, bus rate, internal code execution pattern and temperature also have an impact on the current consumption.

- a) The test conditions for all IDD measurements in active Operation mode are: OSC1 = external square wave, from rail-to-rail; all I/O pins tristated, pulled to Vss, T0CKI = VDD, MCLR = VDD; WDT enabled/disabled as specified.
- b) For standby current measurements, the conditions are the same, except that the device is in SLEEP mode. The power-down current in SLEEP mode does not depend on the oscillator type.
- **3:** Does not include current through REXT. The current through the resistor can be estimated by the formula: IR = VDD/2REXT (mA) with REXT in k Ω .

12.2 DC Characteristics: PIC16C54/55/56/57-RCI, XTI, 10I, HSI, LPI (Industrial)

PIC16C54/55/56/57-RCI, XTI, 10I, HSI, LPI (Industrial)			Standard Operating Conditions (unless otherwise specified) Operating Temperature $-40^{\circ}C \le TA \le +85^{\circ}C$ for industrial					
Param No.	Symbol	Characteristic/Device	Min	Тур†	Max	Units	Conditions	
D001	Vdd	Supply Voltage PIC16C5X-RCI PIC16C5X-XTI PIC16C5X-10I PIC16C5X-HSI PIC16C5X-LPI	3.0 3.0 4.5 4.5 2.5		6.25 6.25 5.5 5.5 6.25	V V V V		
D002	Vdr	RAM Data Retention Voltage ⁽¹⁾		1.5*		V	Device in SLEEP mode	
D003	VPOR	VDD Start Voltage to ensure Power-on Reset	—	Vss	—	V	See Section 5.1 for details on Power-on Reset	
D004	SVDD	VDD Rise Rate to ensure Power-on Reset	0.05*		—	V/ms	See Section 5.1 for details on Power-on Reset	
D010	IDD	Supply Current ⁽²⁾ PIC16C5X-RCI ⁽³⁾ PIC16C5X-XTI PIC16C5X-10I PIC16C5X-HSI PIC16C5X-HSI PIC16C5X-LPI		1.8 1.8 4.8 4.8 9.0 15	3.3 3.3 10 10 20 40	mA mA mA mA μA	Fosc = 4 MHz, VDD = $5.5V$ Fosc = 4 MHz, VDD = $5.5V$ Fosc = 10 MHz, VDD = $5.5V$ Fosc = 10 MHz, VDD = $5.5V$ Fosc = 20 MHz, VDD = $5.5V$ Fosc = 32 kHz, VDD = $3.0V$, WDT disabled	
D020	Ipd	Power-down Current ⁽²⁾	_	4.0 0.6	14 12	μΑ μΑ	VDD = 3.0V, WDT enabled VDD = 3.0V, WDT disabled	

* These parameters are characterized but not tested.

- † Data in "Typ" column is based on characterization results at 25°C. This data is for design guidance only and is not tested.
- Note 1: This is the limit to which VDD can be lowered in SLEEP mode without losing RAM data.
 - 2: The supply current is mainly a function of the operating voltage and frequency. Other factors such as bus loading, oscillator type, bus rate, internal code execution pattern and temperature also have an impact on the current consumption.
 - a) The test conditions for all IDD measurements in active Operation mode are: OSC1 = external square wave, from rail-to-rail; all I/O pins tristated, pulled to Vss, T0CKI = VDD, MCLR = VDD; WDT enabled/disabled as specified.
 - b) For standby current measurements, the conditions are the same, except that the device is in SLEEP mode. The power-down current in SLEEP mode does not depend on the oscillator type.
 - **3:** Does not include current through REXT. The current through the resistor can be estimated by the formula: IR = VDD/2REXT (mA) with REXT in kΩ.

12.3 DC Characteristics: PIC16C54/55/56/57-RCE, XTE, 10E, HSE, LPE (Extended)

PIC16C54/55/56/57-RCE, XTE, 10E, HSE, LPE (Extended)			Standard Operating Conditions (unless otherwise specified) Operating Temperature $-40^{\circ}C \le TA \le +125^{\circ}C$ for extended					
Param No.	Symbol	Characteristic/Device	Min	Тур†	Max	Units	Conditions	
D001	Vdd	Supply Voltage PIC16C5X-RCE PIC16C5X-XTE PIC16C5X-10E PIC16C5X-HSE PIC16C5X-LPE	3.25 3.25 4.5 4.5 2.5		6.0 6.0 5.5 5.5 6.0	V V V V		
D002	Vdr	RAM Data Retention Voltage ⁽¹⁾	—	1.5*	—	V	Device in SLEEP mode	
D003	VPOR	VDD Start Voltage to ensure Power-on Reset	—	Vss	—	V	See Section 5.1 for details on Power-on Reset	
D004	SVDD	VDD Rise Rate to ensure Power-on Reset	0.05*		_	V/ms	See Section 5.1 for details on Power-on Reset	
D010	IDD	Supply Current ⁽²⁾ PIC16C5X-RCE ⁽³⁾ PIC16C5X-XTE PIC16C5X-10E PIC16C5X-HSE PIC16C5X-HSE PIC16C5X-LPE		1.8 1.8 4.8 4.8 9.0 19	3.3 3.3 10 10 20 55	mA mA mA mA μA	Fosc = 4 MHz, VDD = $5.5V$ Fosc = 4 MHz, VDD = $5.5V$ Fosc = 10 MHz, VDD = $5.5V$ Fosc = 10 MHz, VDD = $5.5V$ Fosc = 16 MHz, VDD = $5.5V$ Fosc = 32 kHz, VDD = $3.25V$, WDT disabled	
D020	Ipd	Power-down Current ⁽²⁾	—	5.0 0.8	22 18	μΑ μΑ	VDD = 3.25V, WDT enabled VDD = 3.25V, WDT disabled	

* These parameters are characterized but not tested.

† Data in "Typ" column is based on characterization results at 25°C. This data is for design guidance only and is not tested.

Note 1: This is the limit to which VDD can be lowered in SLEEP mode without losing RAM data.

2: The supply current is mainly a function of the operating voltage and frequency. Other factors such as bus loading, oscillator type, bus rate, internal code execution pattern and temperature also have an impact on the current consumption.

- a) The test conditions for all IDD measurements in active Operation mode are: OSC1 = external square wave, from rail-to-rail; all I/O pins tristated, pulled to Vss, T0CKI = VDD, MCLR = VDD; WDT enabled/disabled as specified.
- b) For standby current measurements, the conditions are the same, except that the device is in SLEEP mode. The power-down current in SLEEP mode does not depend on the oscillator type.
- **3:** Does not include current through REXT. The current through the resistor can be estimated by the formula: IR = VDD/2REXT (mA) with REXT in k Ω .

12.4 DC Characteristics: PIC16C54/55/56/57-RC, XT, 10, HS, LP (Commercial) PIC16C54/55/56/57-RCI, XTI, 10I, HSI, LPI (Industrial)

DC CHARACTERISTICS			$\begin{array}{ll} \mbox{Standard Operating Conditions (unless otherwise specified)} \\ \mbox{Operating Temperature} & 0^{\circ}C \leq TA \leq +70^{\circ}C \mbox{ for commercial} \\ -40^{\circ}C \leq TA \leq +85^{\circ}C \mbox{ for industrial} \end{array}$						
Param No.	Symbol	Characteristic/Device	Min	Тур†	Max	Units	Conditions		
D030	VIL	Input Low Voltage I/O ports MCLR (Schmitt Trigger) TOCKI (Schmitt Trigger) OSC1 (Schmitt Trigger) OSC1 (Schmitt Trigger)	Vss Vss Vss Vss Vss		0.2 VDD 0.15 VDD 0.15 VDD 0.15 VDD 0.3 VDD	V V V V	Pin at hi-impedance PIC16C5X-RC only ⁽³⁾ PIC16C5X-XT, 10, HS, LP		
D040	Vih	Input High Voltage I/O ports I/O ports I/O ports MCLR (Schmitt Trigger) TOCKI (Schmitt Trigger) OSC1 (Schmitt Trigger) OSC1 (Schmitt Trigger)	0.45 VDD 2.0 0.36 VDD 0.85 VDD 0.85 VDD 0.85 VDD 0.7 VDD		VDD VDD VDD VDD VDD VDD VDD VDD	V V V V V V	For all VDD ⁽⁴⁾ 4.0V < VDD ≤ 5.5V ⁽⁴⁾ VDD > 5.5V PIC16C5X-RC only ⁽³⁾ PIC16C5X-XT, 10, HS, LP		
D050	VHYS	Hysteresis of Schmitt Trigger inputs	0.15 VDD*	_	—	V			
D060	Ιι∟	Input Leakage Current ^(1,2) I/O ports MCLR MCLR T0CKI OSC1	-1 -5 -3 -3	0.5 — 0.5 0.5 0.5	+1 +5 +3 +3	μΑ μΑ μΑ μΑ	For VDD \leq 5.5V: VSS \leq VPIN \leq VDD, pin at hi-impedance VPIN = VSS + 0.25V VPIN = VDD VSS \leq VPIN \leq VDD VSS \leq VPIN \leq VDD, PIC16C5X-XT, 10, HS, LP		
D080	Vol	Output Low Voltage I/O ports OSC2/CLKOUT		—	0.6 0.6	V V	IOL = 8.7 mA, VDD = 4.5V IOL = 1.6 mA, VDD = 4.5V, PIC16C5X-RC		
D090	Vон	Output High Voltage ⁽²⁾ I/O ports OSC2/CLKOUT	Vdd – 0.7 Vdd – 0.7			V V	IOH = -5.4 mA, VDD = 4.5V IOH = -1.0 mA, VDD = 4.5V, PIC16C5X-RC		

* These parameters are characterized but not tested.

† Data in the Typical ("Typ") column is based on characterization results at 25°C. This data is for design guidance only and is not tested.

- **Note 1:** The leakage current on the MCLR/VPP pin is strongly dependent on the applied voltage level. The specified levels represent normal operating conditions. Higher leakage current may be measured at different input voltage.
 - 2: Negative current is defined as coming out of the pin.
 - **3:** For PIC16C5X-RC devices, the OSC1/CLKIN pin is a Schmitt Trigger input. It is not recommended that the PIC16C5X be driven with external clock in RC mode.
 - 4: The user may use the better of the two specifications.

12.5 DC Characteristics: PIC16C54/55/56/57-RCE, XTE, 10E, HSE, LPE (Extended)

DC CHARACTERISTICS			Standard Operating Conditions (unless otherwise specified)Operating Temperature $-40^{\circ}C \le TA \le +125^{\circ}C$ for extended						
Param No.	Symbol	Characteristic	Min	Тур†	Max	Units	Conditions		
D030	VIL	Input Low Voltage							
		I/O ports	Vss		0.15 VDD	V	Pin at hi-impedance		
		MCLR (Schmitt Trigger)	Vss		0.15 VDD	V			
		T0CKI (Schmitt Trigger)	Vss	—	0.15 VDD	V			
		OSC1 (Schmitt Trigger)	Vss		0.15 VDD	V	PIC16C5X-RC only ⁽³⁾		
		OSC1 (Schmitt Trigger)	Vss	—	0.3 Vdd	V	PIC16C5X-XT, 10, HS, LP		
D040	Vih	Input High Voltage							
		I/O ports	0.45 VDD		Vdd	V	For all VDD ⁽⁴⁾		
		I/O ports	2.0	—	Vdd	V	$4.0V < VDD \le 5.5V^{(4)}$		
		I/O ports	0.36 VDD		Vdd	V	VDD > 5.5 V		
		MCLR (Schmitt Trigger)	0.85 VDD		Vdd	V			
		T0CKI (Schmitt Trigger)	0.85 VDD		Vdd	V			
		OSC1 (Schmitt Trigger)	0.85 VDD		Vdd	V	PIC16C5X-RC only ⁽³⁾		
		OSC1 (Schmitt Trigger)	0.7 Vdd	—	Vdd	V	PIC16C5X-XT, 10, HS, LP		
D050	VHYS	Hysteresis of Schmitt Trigger inputs	0.15 Vdd*		—	V			
D060	lı∟	Input Leakage Current (1,2)					For V DD ≤ 5.5 V :		
		I/O ports	-1	0.5	+1	μΑ	VSS \leq VPIN \leq VDD, pin at hi-impedance		
		MCLR	-5		_	μA	VPIN = VSS + $0.25V$		
		MCLR	_	0.5	+5	μA	VPIN = VDD		
		тоскі	-3	0.5	+3	μA	$VSS \leq VPIN \leq VDD$		
		OSC1	-3	0.5	+3	μA	$\label{eq:VSS} \begin{split} & VSS \leq VPIN \leq VDD, \\ & PIC16C5X-XT, \ 10, \ HS, \ LP \end{split}$		
D080	Vol	Output Low Voltage							
		I/O ports OSC2/CLKOUT		 _	0.6 0.6	V V	IOL = 8.7 mA, VDD = 4.5V IOL = 1.6 mA, VDD = 4.5V, PIC16C5X-RC		
D090	Мон	Output High Voltage ⁽²⁾							
D090	Vон	I/O ports OSC2/CLKOUT	Vdd – 0.7 Vdd – 0.7	—	_ _	V V	IOH = -5.4 mA, VDD = 4.5V IOH = -1.0 mA, VDD = 4.5V, PIC16C5X-RC		

† Data in the Typical ("Typ") column is based on characterization results at 25°C. This data is for design guidance only and is not tested.

Note 1: The leakage current on the MCLR/VPP pin is strongly dependent on the applied voltage level. The specified levels represent normal operating conditions. Higher leakage current may be measured at different input voltage.

2: Negative current is defined as coming out of the pin.

3: For PIC16C5X-RC devices, the OSC1/CLKIN pin is a Schmitt Trigger input. It is not recommended that the PIC16C5X be driven with external clock in RC mode.

4: The user may use the better of the two specifications.
12.6 Timing Parameter Symbology and Load Conditions

The timing parameter symbols have been created with one of the following formats:

1. TppS2ppS

2 Tn	2. TppS									
	PO									
Т										
F	Frequency	T Time								
Lowe	owercase letters (pp) and their meanings:									
рр										
2	to	mc MCLR								
ck	CLKOUT	osc oscillator								
су	cycle time	os OSC1								
drt	device reset timer	t0 T0CKI								
io	I/O port	wdt watchdog timer								
Uppe	ercase letters and their meanings:									
S										
F	Fall	P Period								
Н	High	R Rise								
I	Invalid (Hi-impedance)	V Valid								
L	Low	Z Hi-impedance								

FIGURE 12-1: LOAD CONDITIONS FOR DEVICE TIMING SPECIFICATIONS - PIC16C54/55/56/57



12.7 Timing Diagrams and Specifications



FIGURE 12-2: EXTERNAL CLOCK TIMING - PIC16C54/55/56/57

TABLE 12-1: EXTERNAL CLOCK TIMING REQUIREMENTS - PIC16C54/55/56/57

AC Characteristics		$ \begin{array}{ll} \mbox{Standard Operating Conditions (unless otherwise specified)} \\ \mbox{Operating Temperature} & 0^{\circ}C \leq TA \leq +70^{\circ}C \mbox{ for commercial} \\ -40^{\circ}C \leq TA \leq +85^{\circ}C \mbox{ for industrial} \\ -40^{\circ}C \leq TA \leq +125^{\circ}C \mbox{ for extended} \\ \end{array} $								
Param No. Symbol		Characteristic	Min	Тур†	Max	Units	Conditions			
1A	Fosc	External CLKIN Frequency ⁽¹⁾	DC		4.0	MHz	XT OSC mode			
			DC	—	10	MHz	10 MHz mode			
			DC	_	20	MHz	HS osc mode (Comm/Ind)			
			DC	_	16	MHz	HS osc mode (Ext)			
			DC	—	40	kHz	LP osc mode			
		Oscillator Frequency ⁽¹⁾	DC	_	4.0	MHz	RC osc mode			
			0.1	_	4.0	MHz	XT OSC mode			
			4.0	_	10	MHz	10 MHz mode			
			4.0	—	20	MHz	HS OSC mode (Comm/Ind)			
			4.0	_	16	MHz	HS osc mode (Ext)			
			DC	—	40	kHz	LP osc mode			

* These parameters are characterized but not tested.

† Data in the Typical ("Typ") column is at 5.0V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

Note 1: All specified values are based on characterization data for that particular oscillator type under standard operating conditions with the device executing code. Exceeding these specified limits may result in an unstable oscillator operation and/or higher than expected current consumption. When an external clock input is used, the "max" cycle time limit is "DC" (no clock) for all devices.

2: Instruction cycle period (TCY) equals four times the input oscillator time base period.

		Standard Operating Conditions (unless otherwise specified)									
AC Chara	cteristics	Operating Temperature $0^{\circ}C \leq TA \leq +70^{\circ}C$ for commercial $-40^{\circ}C \leq TA \leq +85^{\circ}C$ for industrial									
				TA ≤ +125							
Param No.	Symbol	Characteristic	Min	Тур†	Max	Units	Conditions				
1	Tosc	External CLKIN Period ⁽¹⁾	250	—	_	ns	XT OSC mode				
			100	—	—	ns	10 MHz mode				
			50	—	—	ns	HS osc mode (Comm/Ind)				
			62.5	—	—	ns	HS osc mode (Ext)				
			25	—	_	μS	LP OSC mode				
		Oscillator Period ⁽¹⁾	250	—	—	ns	RC OSC mode				
			250	—	10,000	ns	XT OSC mode				
			100	—	250	ns	10 MHz mode				
			50	—	250	ns	HS OSC mode (Comm/Ind)				
			62.5	—	250	ns	HS osc mode (Ext)				
			25	—	_	μS	LP OSC mode				
2	Тсу	Instruction Cycle Time ⁽²⁾	—	4/Fosc		—					
3	TosL,	Clock in (OSC1) Low or High	85*	—	—	ns	XT oscillator				
	TosH	Time	20*	—	—	ns	HS oscillator				
			2.0*	—		μS	LP oscillator				
4	TosR,	Clock in (OSC1) Rise or Fall	—	—	25*	ns	XT oscillator				
	TosF	Time	—	—	25*	ns	HS oscillator				
			—	—	50*	ns	LP oscillator				

TABLE 12-1: EXTERNAL CLOCK TIMING REQUIREMENTS - PIC16C54/55/56/57

* These parameters are characterized but not tested.

† Data in the Typical ("Typ") column is at 5.0V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

Note 1: All specified values are based on characterization data for that particular oscillator type under standard operating conditions with the device executing code. Exceeding these specified limits may result in an unstable oscillator operation and/or higher than expected current consumption. When an external clock input is used, the "max" cycle time limit is "DC" (no clock) for all devices.

2: Instruction cycle period (TCY) equals four times the input oscillator time base period.

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TABLE 12-2: CLKOUT AND I/O TIMING REQUIREMENTS - PIC16C54/55/56/57

AC Char	acteristics	Standard Operating Conditions (unless otherwise specified)Operating Temperature $0^{\circ}C \leq TA \leq +70^{\circ}C$ for commercial $-40^{\circ}C \leq TA \leq +85^{\circ}C$ for industrial $-40^{\circ}C \leq TA \leq +125^{\circ}C$ for extended								
Param No.	Symbol	Characteristic	Min	Тур†	Max	Units				
10	TosH2ckL	OSC1↑ to CLKOUT↓ ⁽¹⁾	_	15	30**	ns				
11	TosH2ckH	OSC1↑ to CLKOUT↑ ⁽¹⁾	_	15	30**	ns				
12	TckR	CLKOUT rise time ⁽¹⁾		5.0	15**	ns				
13	TckF	CLKOUT fall time ⁽¹⁾	—	5.0	15**	ns				
14	TckL2ioV	CLKOUT↓ to Port out valid ⁽¹⁾			40**	ns				
15	TioV2ckH	Port in valid before CLKOUT ⁽¹⁾	0.25 TCY+30*	_	_	ns				
16	TckH2iol	Port in hold after CLKOUT ⁽¹⁾	0*	_	_	ns				
17	TosH2ioV	OSC1↑ (Q1 cycle) to Port out valid ⁽²⁾	_		100*	ns				
18	TosH2iol	OSC1 [↑] (Q2 cycle) to Port input invalid (I/O in hold time)	TBD	—		ns				
19	TioV2osH	Port input valid to OSC1↑ (I/O in setup time)	TBD	—	—	ns				
20	TioR	Port output rise time ⁽²⁾	—	10	25**	ns				
21	TioF	Port output fall time ⁽²⁾	—	10	25**	ns				

* These parameters are characterized but not tested.

** These parameters are design targets and are not tested. No characterization data available at this time.

† Data in the Typical ("Typ") column is at 5.0V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

Note 1: Measurements are taken in RC Mode where CLKOUT output is 4 x Tosc.

2: Please refer to Figure 12-1 for load conditions.



FIGURE 12-4: RESET, WATCHDOG TIMER, AND DEVICE RESET TIMER TIMING -PIC16C54/55/56/57

TABLE 12-3: RESET, WATCHDOG TIMER, AND DEVICE RESET TIMER - PIC16C54/55/56/57

AC Chara	cteristics	$\begin{array}{l} \mbox{Standard Operating Conditions (unless otherwise specified)} \\ \mbox{Operating Temperature} & 0^{\circ}C \leq TA \leq +70^{\circ}C \mbox{ for commercial} \\ -40^{\circ}C \leq TA \leq +85^{\circ}C \mbox{ for industrial} \\ -40^{\circ}C \leq TA \leq +125^{\circ}C \mbox{ for extended} \end{array}$							
Param No. Symbol		Characteristic	Min	Тур†	Max	Units	Conditions		
30	TmcL	MCLR Pulse Width (low)	100*	—	—	ns	VDD = 5.0V		
31	Twdt	Watchdog Timer Time-out Period (No Prescaler)	9.0*	18*	30*	ms	VDD = 5.0V (Comm)		
32	Tdrt	Device Reset Timer Period	9.0*	18*	30*	ms	VDD = 5.0V (Comm)		
34	Tioz	I/O Hi-impedance from MCLR Low	_	_	100*	ns			

* These parameters are characterized but not tested.

† Data in the Typical ("Typ") column is at 5.0V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

FIGURE 12-5: TIMER0 CLOCK TIMINGS - PIC16C54/55/56/57



TABLE 12-4: TIMER0 CLOCK REQUIREMENTS - PIC16C54/55/56/57

AC Ch	aracterist	Operating Temperature	$\begin{array}{llllllllllllllllllllllllllllllllllll$					
Param No.	Symbol	Characteristic	Min	Тур†	Max	Units	Conditions	
40	Tt0H	T0CKI High Pulse Width - No Prescaler - With Prescaler	0.5 Tcy + 20* 10*		_	ns ns		
41	Tt0L	T0CKI Low Pulse Width - No Prescaler - With Prescaler	0.5 Tcy + 20* 10*		_	ns ns		
42	Tt0P	T0CKI Period	20 or <u>Tcy + 40</u> * N			ns	Whichever is greater. N = Prescale Value (1, 2, 4,, 256)	

* These parameters are characterized but not tested.

† Data in the Typical ("Typ") column is at 5.0V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

13.0 ELECTRICAL CHARACTERISTICS - PIC16CR54A

Absolute Maximum Ratings(†)

Ambient Temperature under bias	–55°C to +125°C
Storage Temperature	–65°C to +150°C
Voltage on VDD with respect to Vss	0 to +7.5V
Voltage on MCLR with respect to Vss ⁽¹⁾	0 to +14V
Voltage on all other pins with respect to Vss0	0.6V to (VDD + 0.6V)
Total power dissipation ⁽²⁾	800 mW
Max. current out of Vss pin	150 mA
Max. current into Vod pin	50 mA
Max. current into an input pin (T0CKI only)	±500 μA
Input clamp current, Iк (VI < 0 or VI > VDD)	±20 mA
Output clamp current, IOK (V0 < 0 or V0 > VDD)	±20 mA
Max. output current sunk by any I/O pin	
Max. output current sourced by any I/O pin	20 mA
Max. output current sourced by a single I/O port (PORTA or B)	40 mA
Max. output current sunk by a single I/O port (PORTA or B)	50 mA

- **Note 1:** Voltage spikes below Vss at the $\overline{\text{MCLR}}$ pin, inducing currents greater than 80 mA may cause latch-up. Thus, a series resistor of 50 to 100 Ω should be used when applying a low level to the $\overline{\text{MCLR}}$ pin rather than pulling this pin directly to Vss.
 - **2:** Power Dissipation is calculated as follows: PDIS = VDD x {IDD \sum IOH} + \sum {(VDD-VOH) x IOH} + \sum (VOL x IOL)

† NOTICE: Stresses above those listed under "Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operation listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

13.1 DC Characteristics: PIC16CR54A-04, 10, 20, PIC16LCR54A-04 (Commercial) PIC16CR54A-04I, 10I, 20I, PIC16LCR54A-04I (Industrial)

PIC16LC	PIC16LCR54A-04 PIC16LCR54A-04I (Commercial, Industrial)				$\begin{tabular}{lllllllllllllllllllllllllllllllllll$						
PIC16CR54A-04, 10, 20 PIC16CR54A-04I, 10I, 20I (Commercial, Industrial)				$\begin{array}{llllllllllllllllllllllllllllllllllll$							
Param No. Symbol Characteristic/Device				Тур†	Max	Units	Conditions				
	Vdd	Supply Voltage									
D001		PIC16LCR54A	2.0		6.25	V					
D001 D001A		PIC16CR54A	2.5 4.5	_	6.25 5.5	V V	RC and XT modes HS mode				
D002	Vdr	RAM Data Retention Voltage ⁽¹⁾	_	1.5*	_	V	Device in SLEEP mode				
D003	VPOR	VDD Start Voltage to ensure Power-on Reset	—	Vss	—	V	See Section 5.1 for details on Power-on Reset				
D004	SVDD	VDD Rise Rate to ensure Power-on Reset	0.05*	_	—	V/ms	See Section 5.1 for details on Power-on Reset				
	Idd	Supply Current ⁽²⁾									
D005		PICLCR54A	_	10	20 70	μΑ μΑ	Fosc = 32 kHz, VDD = 2.0V Fosc = 32 kHz, VDD = 6.0V				
D005A		PIC16CR54A		2.0 0.8 90	3.6 1.8 350	mA mA μA	RC⁽³⁾ and XT modes: Fosc = 4.0 MHz, VDD = 6.0V Fosc = 4.0 MHz, VDD = 3.0V Fosc = 200 kHz, VDD = 2.5V HS mode:				
				4.8 9.0	10 20	mA mA	Fosc = 10 MHz, VDD = 5.5V Fosc = 20 MHz, VDD = 5.5V				

Legend: Rows with standard voltage device data only are shaded for improved readability.

- * These parameters are characterized but not tested.
- † Data in "Typ" column is at 5V, 25°C, unless otherwise stated. These parameters are for design guidance only, and are not tested.

Note 1: This is the limit to which VDD can be lowered in SLEEP mode without losing RAM data.

- 2: The supply current is mainly a function of the operating voltage and frequency. Other factors such as bus loading, oscillator type, bus rate, internal code execution pattern and temperature also have an impact on the current consumption.
 - a) The test conditions for all IDD measurements in active Operation mode are: OSC1 = external square wave, from rail-to-rail; all I/O pins tristated, pulled to Vss, T0CKI = VDD, MCLR = VDD; WDT enabled/ disabled as specified.
 - b) For standby current measurements, the conditions are the same, except that the device is in SLEEP mode. The power-down current in SLEEP mode does not depend on the oscillator type.
- **3:** Does not include current through REXT. The current through the resistor can be estimated by the formula: IR = VDD/2REXT (mA) with REXT in k Ω .

13.1 DC Characteristics: PIC16CR54A-04, 10, 20, PIC16LCR54A-04 (Commercial) PIC16CR54A-04I, 10I, 20I, PIC16LCR54A-04I (Industrial)

PIC16LC	PIC16LCR54A-04 PIC16LCR54A-04I (Commercial, Industrial)				$\begin{array}{l} \mbox{Standard Operating Conditions (unless otherwise specified)} \\ \mbox{Operating Temperature} & 0^{\circ}C \leq TA \leq +70^{\circ}C \mbox{ for commercial} \\ -40^{\circ}C \leq TA \leq +85^{\circ}C \mbox{ for industrial} \end{array}$						
PIC16CR	254A-04, 10 254A-04I, 10 ercial, Indus) i , 20i	$\begin{array}{llllllllllllllllllllllllllllllllllll$								
Param No.	Symbol	Characteristic/Device	Min Typ† Max Units				Conditions				
	IPD	Power-down Current ⁽²⁾									
D006		PIC16LCR54A-Commercial		1.0 2.0 3.0 5.0	6.0 8.0* 15 25	μΑ μΑ μΑ μΑ	VDD = 2.5V, WDT disabled VDD = 4.0V, WDT disabled VDD = 6.0V, WDT disabled VDD = 6.0V, WDT enabled				
D006A		PIC16CR54A-Commercial		1.0 2.0 3.0 5.0	6.0 8.0* 15 25	μΑ μΑ μΑ μΑ	VDD = 2.5V, WDT disabled VDD = 4.0V, WDT disabled VDD = 6.0V, WDT disabled VDD = 6.0V, WDT enabled				
D007		PIC16LCR54A-Industrial		1.0 2.0 3.0 3.0 5.0	8.0 10* 20* 18 45	μΑ μΑ μΑ μΑ	VDD = 2.5V, WDT disabled VDD = 4.0V, WDT disabled VDD = 4.0V, WDT enabled VDD = 6.0V, WDT disabled VDD = 6.0V, WDT enabled				
D007A		PIC16CR54A-Industrial		1.0 2.0 3.0 3.0 5.0	8.0 10* 20* 18 45	μΑ μΑ μΑ μΑ	VDD = 2.5V, WDT disabled VDD = 4.0V, WDT disabled VDD = 4.0V, WDT enabled VDD = 6.0V, WDT disabled VDD = 6.0V, WDT enabled				

Legend: Rows with standard voltage device data only are shaded for improved readability.

- * These parameters are characterized but not tested.
- † Data in "Typ" column is at 5V, 25°C, unless otherwise stated. These parameters are for design guidance only, and are not tested.
- **Note 1:** This is the limit to which VDD can be lowered in SLEEP mode without losing RAM data.
 - 2: The supply current is mainly a function of the operating voltage and frequency. Other factors such as bus loading, oscillator type, bus rate, internal code execution pattern and temperature also have an impact on the current consumption.
 - a) The test conditions for all IDD measurements in active Operation mode are: OSC1 = external square wave, from rail-to-rail; all I/O pins tristated, pulled to Vss, TOCKI = VDD, MCLR = VDD; WDT enabled/ disabled as specified.
 - b) For standby current measurements, the conditions are the same, except that the device is in SLEEP mode. The power-down current in SLEEP mode does not depend on the oscillator type.
 - 3: Does not include current through REXT. The current through the resistor can be estimated by the formula: IR = VDD/2REXT (mA) with REXT in k Ω .

13.2 DC Characteristics: PIC16CR54A-04E, 10E, 20E (Extended)

	PIC16CR54A-04E, 10E, 20E (Extended)				Standard Operating Conditions (unless otherwise specified)Operating Temperature $-40^{\circ}C \le TA \le +125^{\circ}C$ for extended					
Param No.	Symbol	Characteristic	Min	Тур†	Max	Units	Conditions			
D001	Vdd	Supply Voltage RC, XT and LP modes HS mode	3.25 4.5		6.0 5.5	V V				
D002	Vdr	RAM Data Retention Voltage ⁽¹⁾	—	1.5*	—	V	Device in SLEEP mode			
D003	VPOR	VDD Start Voltage to ensure Power-on Reset	—	Vss	—	V	See Section 5.1 for details on Power-on Reset			
D004	Svdd	VDD Rise Rate to ensure Power- on Reset	0.05*	_		V/ms	See Section 5.1 for details on Power-on Reset			
D010	IDD	Supply Current ⁽²⁾ RC ⁽³⁾ and XT modes HS mode HS mode		1.8 4.8 9.0	3.3 10 20	mA mA mA	Fosc = 4.0 MHz, Vdd = 5.5V Fosc = 10 MHz, Vdd = 5.5V Fosc = 16 MHz, Vdd = 5.5V			
D020	IPD	Power-down Current ⁽²⁾		5.0 0.8	22 18	μΑ μΑ	VDD = 3.25V, WDT enabled VDD = 3.25V, WDT disabled			

These parameters are characterized but not tested.

† Data in the Typical ("Typ") column is based on characterization results at 25°C. This data is for design guidance only and is not tested.

Note 1: This is the limit to which VDD can be lowered in SLEEP mode without losing RAM data.

- 2: The supply current is mainly a function of the operating voltage and frequency. Other factors such as bus loading, oscillator type, bus rate, internal code execution pattern and temperature also have an impact on the current consumption.
 - a) The test conditions for all IDD measurements in active Operation mode are: OSC1 = external square wave, from rail-to-rail; all I/O pins tristated, pulled to Vss, TOCKI = VDD, MCLR = VDD; WDT enabled/ disabled as specified.
 - b) For standby current measurements, the conditions are the same, except that the device is in SLEEP mode. The power-down current in SLEEP mode does not depend on the oscillator type.
- 3: Does not include current through REXT. The current through the resistor can be estimated by the formula: IR = VDD/2REXT (mA) with REXT in kΩ.

13.3 DC Characteristics: PIC16CR54A-04, 10, 20, PIC16LCR54A-04 (Commercial) PIC16CR54A-04I, 10I, 20I, PIC16LCR54A-04I (Industrial)

DC CH	ARACTEI	RISTICS	$\begin{array}{l} \mbox{Standard Operating Conditions (unless otherwise specified)}\\ \mbox{Operating Temperature} & 0^{\circ}C \leq TA \leq +70^{\circ}C \mbox{ for commercial}\\ -40^{\circ}C \leq TA \leq +85^{\circ}C \mbox{ for industrial} \end{array}$					
Param No.	Symbol	Characteristic	Min	Тур†	Max	Units	Conditions	
D030	VIL	Input Low Voltage I/O ports MCLR (Schmitt Trigger) T0CKI (Schmitt Trigger) OSC1 (Schmitt Trigger) OSC1	Vss Vss Vss Vss Vss		0.2 VDD 0.15 VDD 0.15 VDD 0.15 VDD 0.15 VDD 0.15 VDD	V V V V	Pin at hi-impedance RC mode only ⁽³⁾ XT, HS and LP modes	
D040	VIн	Input High Voltage I/O ports I/O ports MCLR (Schmitt Trigger) T0CKI (Schmitt Trigger) OSC1 (Schmitt Trigger) OSC1	2.0 0.6 VDD 0.85 VDD 0.85 VDD 0.85 VDD 0.85 VDD		VDD VDD VDD VDD VDD VDD VDD	V V V V V	VDD = 3.0V to 5.5V ⁽⁴⁾ Full VDD range ⁽⁴⁾ RC mode only ⁽³⁾ XT, HS and LP modes	
D050	VHYS	Hysteresis of Schmitt Trigger inputs	0.15 VDD*	—	—	V		
D060	lι∟	Input Leakage Current ^(1,2) I/O ports	-1.0	_	+1.0	μA	For VDD \leq 5.5V: VSS \leq VPIN \leq VDD, pin at hi-impedance	
		MCLR MCLR TOCKI OSC1	-5.0 -3.0 -3.0	— 0.5 0.5 0.5	 +5.0 +3.0 +3.0	μΑ μΑ μΑ	$\label{eq:VPIN} \begin{array}{l} VPIN = VSS + 0.25V \\ VPIN = VDD \\ VSS \leq VPIN \leq VDD \\ VSS \leq VPIN \leq VDD, \\ XT, HS \text{and} LP \text{modes} \end{array}$	
D080	Vol	Output Low Voltage I/O ports OSC2/CLKOUT		_	0.5 0.5	V V	IOL = 10 mA, VDD = 6.0 V IOL = 1.9 mA, VDD = 6.0 V, RC mode only	
D090	Vон	Output High Voltage ⁽²⁾ I/O ports OSC2/CLKOUT	Vdd - 0.5 Vdd - 0.5	_		V V	IOH = -4.0 mA, VDD = 6.0 V IOH = -0.8 mA, VDD = 6.0 V, RC mode only	

* These parameters are characterized but not tested.

- † Data in the Typical ("Typ") column is based on characterization results at 25°C. This data is for design guidance only and is not tested.
- **Note 1:** The leakage current on the MCLR/VPP pin is strongly dependent on the applied voltage level. The specified levels represent normal operating conditions. Higher leakage current may be measured at different input voltage.
 - 2: Negative current is defined as coming out of the pin.
 - **3:** For the RC mode, the OSC1/CLKIN pin is a Schmitt Trigger input. It is not recommended that the PIC16C5X be driven with external clock in RC mode.
 - 4: The user may use the better of the two specifications.

13.4 DC Characteristics: PIC16CR54A-04E, 10E, 20E (Extended)

DC CH	ARACTER	RISTICS	Standard Operating Conditions (unless otherwise specified)Operating Temperature $-40^{\circ}C \le TA \le +125^{\circ}C$ for extended						
Param No.	Symbol	Characteristic	Min	Тур†	Мах	Units	Conditions		
D030	VIL	Input Low Voltage							
		I/O ports	Vss		0.15 Vdd	V	Pin at hi-impedance		
		MCLR (Schmitt Trigger)	Vss		0.15 VDD	V			
		T0CKI (Schmitt Trigger)	Vss		0.15 VDD	V			
		OSC1 (Schmitt Trigger)	Vss		0.15 VDD	V	RC mode only ⁽³⁾		
		OSC1	Vss	—	0.3 Vdd	V	XT, HS and LP modes		
D040	Vін	Input High Voltage							
		I/O ports	0.45 Vdd		Vdd	V	For all VDD ⁽⁴⁾		
		I/O ports	2.0		Vdd	V	$4.0V < VDD \le 5.5V^{(4)}$		
		I/O ports	0.36 Vdd		Vdd	V	VDD > 5.5V		
		MCLR (Schmitt Trigger)	0.85 VDD		Vdd	V			
		T0CKI (Schmitt Trigger)	0.85 VDD		Vdd	V			
		OSC1 (Schmitt Trigger)	0.85 VDD		Vdd	V	RC mode only ⁽³⁾		
		OSC1	0.7 Vdd	—	Vdd	V	XT, HS and LP modes		
D050	VHYS	Hysteresis of Schmitt Trigger inputs	0.15 Vdd*	—	_	V			
D060	lı∟	Input Leakage Current ^(1,2)					For VDD ≤ 5.5 V:		
		I/O ports	-1.0	0.5	+1.0	μA	$VSS \leq VPIN \leq VDD$,		
							pin at hi-impedance		
		MCLR	-5.0		_	μA	VPIN = VSS + 0.25V		
		MCLR	_	0.5	+5.0	μΑ	VPIN = VDD		
		TOCKI	-3.0	0.5	+3.0	μΑ	$VSS \leq VPIN \leq VDD$		
		OSC1	-3.0	0.5	+3.0	μA	$VSS \leq VPIN \leq VDD$,		
							XT, HS and LP modes		
D080	Vol	Output Low Voltage							
		I/O ports	I —	—	0.6	V	IOL = 8.7 mA, VDD = 4.5V		
		OSC2/CLKOUT			0.6	V	IOL = 1.6 mA, VDD = 4.5 V,		
							RC mode only		
D090	Voh	Output High Voltage ⁽²⁾							
		I/O ports	Vdd - 0.7	—	—	V	IOH = −5.4 mA, VDD = 4.5\		
		OSC2/CLKOUT	Vdd - 0.7	—	-	V	IOH = -1.0 mA, VDD = 4.5 V RC mode only		

† Data in the Typical ("Typ") column is based on characterization results at 25°C. This data is for design guidance only and is not tested.

Note 1: The leakage current on the MCLR/VPP pin is strongly dependent on the applied voltage level. The specified levels represent normal operating conditions. Higher leakage current may be measured at different input voltage.

2: Negative current is defined as coming out of the pin.

3: For the RC mode, the OSC1/CLKIN pin is a Schmitt Trigger input. It is not recommended that the PIC16C5X be driven with external clock in RC mode.

4: The user may use the better of the two specifications.

13.5 Timing Parameter Symbology and Load Conditions

The timing parameter symbols have been created with one of the following formats:

1. TppS2ppS

2. Tp	ρS	
Т		
F	Frequency	T Time
Lowe	ercase letters (pp) and their meanings:	
рр		
2	to	mc MCLR
ck	CLKOUT	osc oscillator
су	cycle time	os OSC1
drt	device reset timer	t0 T0CKI
io	I/O port	wdt watchdog timer
Uppe	ercase letters and their meanings:	
S		
F	Fall	P Period
н	High	R Rise
T	Invalid (Hi-impedance)	V Valid
L	Low	Z Hi-impedance

FIGURE 13-1: LOAD CONDITIONS FOR DEVICE TIMING SPECIFICATIONS - PIC16CR54A



13.6 Timing Diagrams and Specifications



FIGURE 13-2: EXTERNAL CLOCK TIMING - PIC16CR54A

TABLE 13-1: EXTERNAL CLOCK TIMING REQUIREMENTS - PIC16CR54A

AC Characteristics		$\begin{array}{ll} \mbox{Standard Operating Conditions (unless otherwise specified)} \\ \mbox{Operating Temperature} & 0^{\circ}C \leq TA \leq +70^{\circ}C \ \ for \ commercial \\ -40^{\circ}C \leq TA \leq +85^{\circ}C \ \ for \ industrial \\ -40^{\circ}C \leq TA \leq +125^{\circ}C \ \ for \ extended \end{array}$					
Param No.	Symbol	Characteristic	Min	Тур†	Max	Units	Conditions
	Fosc	External CLKIN Frequency ⁽¹⁾	DC	_	4.0	MHz	XT OSC mode
			DC	—	4.0	MHz	HS osc mode (04)
			DC	_	10	MHz	HS osc mode (10)
			DC	—	20	MHz	HS osc mode (20)
			DC	_	200	kHz	LP osc mode
		Oscillator Frequency ⁽¹⁾	DC		4.0	MHz	RC OSC mode
			0.1	_	4.0	MHz	XT osc mode
			4.0	_	4.0	MHz	HS osc mode (04)
			4.0	_	10	MHz	HS osc mode (10)
			4.0	_	20	MHz	HS osc mode (20)
			5.0	—	200	kHz	LP osc mode

* These parameters are characterized but not tested.

† Data in the Typical ("Typ") column is based on characterization results at 25°C. This data is for design guidance only and is not tested.

Note 1: All specified values are based on characterization data for that particular oscillator type under standard operating conditions with the device executing code. Exceeding these specified limits may result in an unstable oscillator operation and/or higher than expected current consumption. When an external clock input is used, the "max" cycle time limit is "DC" (no clock) for all devices.

2: Instruction cycle period (TCY) equals four times the input oscillator time base period.

AC Characteristics		Standard Operating Conditions (unless otherwise specified)Operating Temperature $0^{\circ}C \le TA \le +70^{\circ}C$ for commercial $-40^{\circ}C \le TA \le +85^{\circ}C$ for industrial $-40^{\circ}C \le TA \le +125^{\circ}C$ for extended					
Param No.	Symbol	Characteristic	Min	Тур†	Max	Units	Conditions
1	Tosc	External CLKIN Period ⁽¹⁾	250	_	_	ns	XT osc mode
			250	—	—	ns	HS osc mode (04)
			100	—		ns	HS osc mode (10)
			50	—		ns	HS osc mode (20)
			5.0	_	_	μS	LP OSC mode
		Oscillator Period ⁽¹⁾	250		_	ns	RC OSC mode
			250	—	10,000	ns	XT OSC mode
			250	—	250	ns	HS OSC mode (04)
			100	—	250	ns	HS osc mode (10)
			50	—	250	ns	HS osc mode (20)
			5.0	_	200	μS	LP OSC mode
2	Тсу	Instruction Cycle Time ⁽²⁾	—	4/Fosc		_	
3	TosL, TosH	Clock in (OSC1) Low or High	50*		_	ns	XT oscillator
		Time	20*	—	—	ns	HS oscillator
			2.0*	_	—	μS	LP oscillator
4	TosR, TosF	Clock in (OSC1) Rise or Fall	_	—	25*	ns	XT oscillator
		Time	—	—	25*	ns	HS oscillator
			_	—	50*	ns	LP oscillator

TABLE 13-1:	EXTERNAL CLOCK TIMING REQUIREMENTS - PIC16CR54A
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These parameters are characterized but not tested.

† Data in the Typical ("Typ") column is based on characterization results at 25°C. This data is for design guidance only and is not tested.

Note 1: All specified values are based on characterization data for that particular oscillator type under standard operating conditions with the device executing code. Exceeding these specified limits may result in an unstable oscillator operation and/or higher than expected current consumption. When an external clock input is used, the "max" cycle time limit is "DC" (no clock) for all devices.

when an external clock input is used, the "max" cycle time limit is "Du" (no clock) for all device

2: Instruction cycle period (TcY) equals four times the input oscillator time base period.



TABLE 13-2: CLKOUT AND I/O TIMING REQUIREMENTS - PIC16CR54A

AC Chara	acteristics	$\begin{array}{ll} \mbox{Standard Operating Conditions (unless otherwise specified)} \\ \mbox{Operating Temperature} & 0^{\circ}C \leq TA \leq +70^{\circ}C \mbox{ for commercial} \\ -40^{\circ}C \leq TA \leq +85^{\circ}C \mbox{ for industrial} \\ -40^{\circ}C \leq TA \leq +125^{\circ}C \mbox{ for extended} \end{array}$						
Param No.	Symbol	Characteristic	Min	Тур†	Max	Units		
10	TosH2ckL	OSC1↑ to CLKOUT↓ ⁽¹⁾	—	15	30**	ns		
11	TosH2ckH	OSC1↑ to CLKOUT↑ ⁽¹⁾	—	15	30**	ns		
12	TckR	CLKOUT rise time ⁽¹⁾	—	5.0	15**	ns		
13	TckF	CLKOUT fall time ⁽¹⁾	—	5.0	15**	ns		
14	TckL2ioV	CLKOUT↓ to Port out valid ⁽¹⁾	—	—	40**	ns		
15	TioV2ckH	Port in valid before CLKOUT ⁽¹⁾	0.25 TCY+30*	—		ns		
16	TckH2iol	Port in hold after CLKOUT ⁽¹⁾	0*	—		ns		
17	TosH2ioV	OSC1↑ (Q1 cycle) to Port out valid ⁽²⁾	—	—	100*	ns		
18	TosH2iol	OSC1 [↑] (Q2 cycle) to Port input invalid (I/O in hold time)	TBD	—	—	ns		
19	TioV2osH	Port input valid to OSC1↑ (I/O in setup time)	TBD	—	—	ns		
20	TioR	Port output rise time ⁽²⁾	_	10	25**	ns		
21	TioF	Port output fall time ⁽²⁾	_	10	25**	ns		

* These parameters are characterized but not tested.

- ** These parameters are design targets and are not tested. No characterization data available at this time.
- † Data in the Typical ("Typ") column is based on characterization results at 25°C. This data is for design guidance only and is not tested.

Note 1: Measurements are taken in RC Mode where CLKOUT output is 4 x Tosc.

2: Please refer to Figure 13.1 for load conditions.



FIGURE 13-4: RESET, WATCHDOG TIMER, AND DEVICE RESET TIMER TIMING - PIC16CR54A

TABLE 13-3: RESET, WATCHDOG TIMER, AND DEVICE RESET TIMER - PIC16CR54A

AC Chara	cteristics	$ \begin{array}{ll} \mbox{Standard Operating Conditions (unless otherwise specified)} \\ \mbox{Operating Temperature} & 0^{\circ}C \leq TA \leq +70^{\circ}C \mbox{ for commercial} \\ -40^{\circ}C \leq TA \leq +85^{\circ}C \mbox{ for industrial} \\ -40^{\circ}C \leq TA \leq +125^{\circ}C \mbox{ for extended} \\ \end{array} $						
Param No.	Symbol	Characteristic	Min	Тур†	Max	Units	Conditions	
30	TmcL	MCLR Pulse Width (low)	1.0*			μS	VDD = 5.0V	
31	Twdt	Watchdog Timer Time-out Period (No Prescaler)	7.0*	18*	40*	ms	VDD = 5.0V (Comm)	
32	Tdrt	Device Reset Timer Period	7.0*	18*	30*	ms	VDD = 5.0V (Comm)	
34	Tioz	I/O Hi-impedance from MCLR Low	_	_	1.0*	μS		

These parameters are characterized but not tested.

† Data in the Typical ("Typ") column is at 5.0V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

FIGURE 13-5: TIMER0 CLOCK TIMINGS - PIC16CR54A



TABLE 13-4: TIMER0 CLOCK REQUIREMENTS - PIC16CR54A

AC Characteristics Standard Operating Operating Temperat				•	$TA \le +7$ $TA \le +8$	70°C fo 35°C fo	or comr or indus	nercial strial
Param No.	Symbol		Characteristic	Min	Тур†	Max	Units	Conditions
40	Tt0H	T0CKI High	Pulse Width - No Prescaler - With Prescaler	0.5 Tcy + 20* 10*		_	ns ns	
41	TtOL	T0CKI Low	Pulse Width - No Prescaler - With Prescaler	0.5 Tcy + 20* 10*			ns ns	-
42	Tt0P	T0CKI Perio	od	20 or <u>Tcy + 40</u> * N		—	ns	Whichever is greater. N = Prescale Value (1, 2, 4,, 256)

These parameters are characterized but not tested.

† Data in the Typical ("Typ") column is at 5.0V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

14.0 DEVICE CHARACTERIZATION - PIC16C54A

The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only. The performance characteristics listed herein are not tested or guaranteed. In some graphs or tables, the data presented may be outside the specified operating range (e.g., outside specified power supply range) and therefore outside the warranted range.

"Typical" represents the mean of the distribution at 25°C. "Maximum" or "minimum" represents (mean + 3σ) or (mean - 3σ) respectively, where σ is a standard deviation, over the whole temperature range.





TABLE 14-1: RC OSCILLATOR FREQUENCIES

Сехт	Rext	Average Fosc @ 5 V, 25°C		
20 pF	3.3K	5 MHz	± 27%	
	5K	3.8 MHz	± 21%	
	10K	2.2 MHz	± 21%	
	100K	262 kHz	± 31%	
100 pF	3.3K	1.6 MHz	± 13%	
	5K	1.2 MHz	± 13%	
	10K	684 kHz	± 18%	
	100K	71 kHz	± 25%	
300 pF	3.3K	660 kHz	± 10%	
	5.0K	484 kHz	± 14%	
	10K	267 kHz	± 15%	
	100K	29 kHz	± 19%	

The frequencies are measured on DIP packages.

The percentage variation indicated here is part-to-part variation due to normal process distribution. The variation indicated is ± 3 standard deviations from the average value for VDD = 5V.

PIC16C5X

FIGURE 14-2: TYPICAL RC OSC FREQUENCY vs. VDD, CEXT = 20 PF Typical: statistical mean @ 25°C Maximum: mean + 3s (-40°C to 125°C) Minimum: mean – 3s (-40°C to 125°C) 5.5 R = 3.3K5.0 4.5 R = 5K 4.0 3.5 Fosc (MHz) 3.0 R = 10K 2.5 2.0 Measured on DIP Packages, $T = 25^{\circ}C$ 1.5 1.0 R = 100K 0.5 0.0 3.0 3.5 4.0 4.5 5.0 5.5 6.0 VDD (Volts)

FIGURE 14-3:

TYPICAL RC OSC FREQUENCY vs. VDD, CEXT = 100 PF





FIGURE 14-5: TYPICAL IPD vs. VDD, WATCHDOG DISABLED



FIGURE 14-6: MAXIMUM IPD vs. VDD, WATCHDOG DISABLED



FIGURE 14-7: T

TYPICAL IPD vs. VDD, WATCHDOG ENABLED



FIGURE 14-8: MAXIMUM IPD vs. VDD, WATCHDOG ENABLED



IPD, with WDT enabled, has two components: The leakage current, which increases with higher temperature, and the operating current of the WDT logic, which increases with lower temperature. At -40° C, the latter dominates explaining the apparently anomalous behavior.

FIGURE 14-9: VTH (INPUT THRESHOLD VOLTAGE) OF I/O PINS vs. VDD







PIC16C5X



















FIGURE 14-16: TRANSCONDUCTANCE (gm) OF HS OSCILLATOR vs. VDD







FIGURE 14-18:

TRANSCONDUCTANCE (gm) OF XT OSCILLATOR vs. VDD









FIGURE 14-22: PORTA, B AND C IOL vs. VoL, VDD = 5 V



TABLE 14-2: INPUT CAPACITANCE FOR PIC16C54/56

Pin	Typical Capa	acitance (pF)
Pin	18L PDIP	18L SOIC
RA port	5.0	4.3
RB port	5.0	4.3
MCLR	17.0	17.0
OSC1	4.0	3.5
OSC2/CLKOUT	4.3	3.5
TOCKI	3.2	2.8

All capacitance values are typical at 25° C. A part-to-part variation of ±25% (three standard deviations) should be taken into account.

TABLE 14-3:	INPUT CAPACITANCE FOR
	PIC16C55/57

Typical Capacitance (pF				
Pin	28L PDIP (600 mil)	28L SOIC		
RA port	5.2	4.8		
RB port	5.6	4.7		
RC port	5.0	4.1		
MCLR	17.0	17.0		
OSC1	6.6	3.5		
OSC2/CLKOUT	4.6	3.5		
T0CKI	4.5	3.5		

All capacitance values are typical at 25° C. A part-to-part variation of ±25% (three standard deviations) should be taken into account.

15.0 ELECTRICAL CHARACTERISTICS - PIC16C54A

Absolute Maximum Ratings ^(†)	
Ambient temperature under bias	–55°C to +125°C
Storage temperature	–65°C to +150°C
Voltage on VDD with respect to Vss	0 to +7.5V
Voltage on MCLR with respect to Vss	0 to +14V
Voltage on all other pins with respect to Vss	–0.6V to (VDD + 0.6V)
Total power dissipation ⁽¹⁾	800 mW
Max. current out of Vss pin	150 mA
Max. current into Vod pin	100 mA
Max. current into an input pin (T0CKI only)	±500 μA
Input clamp current, Iik (VI < 0 or VI > VDD)	±20 mA
Output clamp current, IOK (VO < 0 or VO > VDD)	
Max. output current sunk by any I/O pin	25 mA
Max. output current sourced by any I/O pin	20 mA
Max. output current sourced by a single I/O port (PORTA or B)	50 mA
Max. output current sunk by a single I/O port (PORTA or B)	50 mA
Note 1: Power dissipation is calculated as follows: Pdis = VDD x {IDD - \sum IOH} + \sum {(VD	D-VOH) X IOH} + Σ (VOL X IOL)

† NOTICE: Stresses above those listed under "Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operation listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

15.1 DC Characteristics: PIC16C54A-04, 10, 20 (Commercial) PIC16C54A-04I, 10I, 20I (Industrial) PIC16LC54A-04 (Commercial) PIC16LC54A-04I (Industrial)

PIC16LC54A-04 PIC16LC54A-04I (Commercial, Industrial)				Standard Operating Conditions (unless otherwise specified)Operating Temperature $0^{\circ}C \le TA \le +70^{\circ}C$ for commercial $-40^{\circ}C \le TA \le +85^{\circ}C$ for industrial					
PIC16C54A-04, 10, 20			Standard Operating Conditions (unless otherwise specified)Operating Temperature $0^{\circ}C \le TA \le +70^{\circ}C$ for commercial $-40^{\circ}C \le TA \le +85^{\circ}C$ for industrial						
Param No. Symbol Characteristic/Device				Тур†	Max	Units	Conditions		
	Vdd	Supply Voltage			•				
D001		PIC16LC54A	3.0 2.5	_	6.25 6.25	V V	XT and RC modes LP mode		
D001A		PIC16C54A	3.0 4.5	_	6.25 5.5	V V	RC, XT and LP modes HS mode		
D002	Vdr	RAM Data Retention Voltage ⁽¹⁾	—	1.5*	—	V	Device in SLEEP mode		
D003	VPOR	VDD Start Voltage to ensure Power-on Reset	—	Vss	—	V	See Section 5.1 for details on Power-on Reset		
D004	SVDD	VDD Rise Rate to ensure Power-on Reset	0.05*	—	—	V/ms	See Section 5.1 for details on Power-on Reset		
	IDD	Supply Current ⁽²⁾							
D005		PIC16LC5X	—	0.5	2.5	mA	Fosc = 4.0 MHz, VDD = 5.5V, RC ⁽³⁾ and XT modes		
			—	11	27	μA	Fosc = 32 kHz, VDD = 2.5V, WDT disabled, LP mode, Commercial		
			—	11	35	μA	Fosc = 32 kHz, VDD = 2.5V, WDT disabled, LP mode, Industrial		
D005A		PIC16C5X	—	1.8	2.4	mA	Fosc = 4.0 MHz, VDD = 5.5V, RC ⁽³⁾ and XT modes		
			—	2.4	8.0	mA	Fosc = 10 MHz, VDD = 5.5V, HS mode		
			_	4.5 14	16 29	mA μA	Fosc = 20 MHz, VDD = 5.5V, HS mode Fosc = 32 kHz, VDD = 3.0V, WDT disabled, LP mode, Commercial		
			—	17	37	μA	Fosc = 32 kHz , VDD = 3.0V , WDT disabled, LP mode, Industrial		

Legend: Rows with standard voltage device data only are shaded for improved readability.

These parameters are characterized but not tested.

- † Data in "Typ" column is based on characterization results at 25°C. This data is for design guidance only and is not tested.
- **Note 1:** This is the limit to which VDD can be lowered in SLEEP mode without losing RAM data.
 - 2: The supply current is mainly a function of the operating voltage and frequency. Other factors such as bus loading, oscillator type, bus rate, internal code execution pattern and temperature also have an impact on the current consumption.
 - a) The test conditions for all IDD measurements in active Operation mode are: OSC1 = external square wave, from rail-to-rail; all I/O pins tristated, pulled to Vss, T0CKI = VDD, MCLR = VDD; WDT enabled/ disabled as specified.
 - b) For standby current measurements, the conditions are the same, except that the device is in SLEEP mode. The power-down current in SLEEP mode does not depend on the oscillator type.
 - 3: Does not include current through REXT. The current through the resistor can be estimated by the formula: IR = VDD/2REXT (mA) with REXT in k Ω .

15.1 DC Characteristics: PIC16C54A-04, 10, 20 (Commercial) PIC16C54A-04I, 10I, 20I (Industrial) PIC16LC54A-04 (Commercial) PIC16LC54A-04I (Industrial)

PIC16LC54A-04 PIC16LC54A-04I (Commercial, Industrial)				$\begin{array}{ll} \mbox{Standard Operating Conditions (unless otherwise specified)} \\ \mbox{Operating Temperature} & 0^{\circ}C \leq TA \leq +70^{\circ}C \mbox{ for commercial} \\ -40^{\circ}C \leq TA \leq +85^{\circ}C \mbox{ for industrial} \end{array}$						
PIC16C54A-04, 10, 20 PIC16C54A-04I, 10I, 20I (Commercial, Industrial)			$\begin{array}{ll} \mbox{Standard Operating Conditions (unless otherwise specified)} \\ \mbox{Operating Temperature} & 0^{\circ}C \leq TA \leq +70^{\circ}C \mbox{ for commercial} \\ -40^{\circ}C \leq TA \leq +85^{\circ}C \mbox{ for industrial} \end{array}$							
Param No.	Symbol	Characteristic/Device	Min Typ† Max Units Conditions							
	IPD	Power-down Current ⁽²⁾								
D006		PIC16LC5X		2.5 0.25 2.5 0.25	12 4.0 14 5.0	μΑ μΑ μΑ μΑ	VDD = 2.5V, WDT enabled, Commercial VDD = 2.5V, WDT disabled, Commercial VDD = 2.5V, WDT enabled, Industrial VDD = 2.5V, WDT disabled, Industrial			
D006A		PIC16C5X		4.0 0.25 5.0 0.3	12 4.0 14 5.0	μΑ μΑ μΑ μΑ	VDD = 3.0V, WDT enabled, Commercial VDD = 3.0V, WDT disabled, Commercial VDD = 3.0V, WDT enabled, Industrial VDD = 3.0V, WDT disabled, Industrial			

Legend: Rows with standard voltage device data only are shaded for improved readability.

* These parameters are characterized but not tested.

† Data in "Typ" column is based on characterization results at 25°C. This data is for design guidance only and is not tested.

Note 1: This is the limit to which VDD can be lowered in SLEEP mode without losing RAM data.

2: The supply current is mainly a function of the operating voltage and frequency. Other factors such as bus loading, oscillator type, bus rate, internal code execution pattern and temperature also have an impact on the current consumption.

- a) The test conditions for all IDD measurements in active Operation mode are: OSC1 = external square wave, from rail-to-rail; all I/O pins tristated, pulled to Vss, T0CKI = VDD, MCLR = VDD; WDT enabled/ disabled as specified.
- b) For standby current measurements, the conditions are the same, except that the device is in SLEEP mode. The power-down current in SLEEP mode does not depend on the oscillator type.
- 3: Does not include current through REXT. The current through the resistor can be estimated by the formula: IR = VDD/2REXT (mA) with REXT in k Ω .

15.2 DC Characteristics: PIC16C54A-04E, 10E, 20E (Extended) PIC16LC54A-04E (Extended)

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				$\begin{array}{llllllllllllllllllllllllllllllllllll$						
				$\begin{array}{llllllllllllllllllllllllllllllllllll$						
Param No.	Symbol	Characteristic	Min	Тур†	Max	Units	Conditions			
	Vdd	Supply Voltage								
D001		PIC16LC54A	3.0 2.5	_	6.25 6.25	V V	XT and RC modes LP mode			
D001A		PIC16C54A	3.5 4.5		5.5 5.5	V V	RC and XT modes HS mode			
D002	Vdr	RAM Data Retention Voltage ⁽¹⁾	—	1.5*	-	V	Device in SLEEP mode			
D003	VPOR	VDD Start Voltage to ensure Power-on Reset	—	Vss	-	V	See Section 5.1 for details on Power-on Reset			
D004	SVDD	VDD Rise Rate to ensure Power-on Reset	0.05*	_	_	V/ms	See Section 5.1 for details on Power-on Reset			
	IDD	Supply Current ⁽²⁾								
D010		PIC16LC54A	—	0.5	25	mA	Fosc = 4.0 MHz, VDD = 5.5V, RC ⁽³⁾ and XT modes			
			—	11	27	μA	Fosc = 32 kHz, VDD = 2.5V, LP mode, Commercial			
			—	11	35	μA	Fosc = 32 kHz, VDD = 2.5V, LP mode, Industrial			
			_	11	37	μA	Fosc = 32 kHz, VDD = 2.5V, LP mode, Extended			
D010A		PIC16C54A	—	1.8	3.3	mA	Fosc = 4.0 MHz, VDD = 5.5V, $RC^{(3)}$ and XT modes			
			—	4.8	10	mA	Fosc = 10 MHz, VDD = 5.5V, HS mode			
			—	9.0	20	mA	Fosc = 20 MHz, VDD = 5.5V, HS mode			

Legend: Rows with standard voltage device data only are shaded for improved readability.

- * These parameters are characterized but not tested.
- † Data in the Typical ("Typ") column is based on characterization results at 25°C. This data is for design guidance only and is not tested.
- Note 1: This is the limit to which VDD can be lowered in SLEEP mode without losing RAM data.
 - 2: The supply current is mainly a function of the operating voltage and frequency. Other factors such as bus loading, oscillator type, bus rate, internal code execution pattern and temperature also have an impact on the current consumption.
 - a) The test conditions for all IDD measurements in active Operation mode are: OSC1 = external square wave, from rail-to-rail; all I/O pins tristated, pulled to Vss, TOCKI = VDD, MCLR = VDD; WDT enabled/ disabled as specified.
 - b) For standby current measurements, the conditions are the same, except that the device is in SLEEP mode. The power-down current in SLEEP mode does not depend on the oscillator type.
 - **3:** Does not include current through REXT. The current through the resistor can be estimated by the formula: IR = VDD/2REXT (mA) with REXT in kΩ.

15.2 DC Characteristics: PIC16

PIC16C54A-04E, 10E, 20E (Extended) PIC16LC54A-04E (Extended)

							tions (unless otherwise specified) $-40^{\circ}C \le TA \le +125^{\circ}C$ for extended		
PIC16C54A-04E, 10E, 20E (Extended)				Standard Operating Conditions (unless otherwise specified)Operating Temperature $-40^{\circ}C \le TA \le +125^{\circ}C$ for extended					
Param No.	Symbol	Characteristic	Min	Тур†	Max	Units	Conditions		
	IPD	Power-down Current ⁽²⁾							
D020		PIC16LC54A	_	2.5 0.25	15 7.0	μΑ μΑ	VDD = 2.5V, WDT enabled, Extended VDD = 2.5V, WDT disabled, Extended		
D020A		PIC16C54A		5.0 0.8	22 18*	μΑ μΑ	VDD = 3.5V, WDT enabled VDD = 3.5V, WDT disabled		

Legend: Rows with standard voltage device data only are shaded for improved readability.

* These parameters are characterized but not tested.

- † Data in the Typical ("Typ") column is based on characterization results at 25°C. This data is for design guidance only and is not tested.
- **Note 1:** This is the limit to which VDD can be lowered in SLEEP mode without losing RAM data.
 - 2: The supply current is mainly a function of the operating voltage and frequency. Other factors such as bus loading, oscillator type, bus rate, internal code execution pattern and temperature also have an impact on the current consumption.
 - a) The test conditions for all IDD measurements in active Operation mode are: OSC1 = external square wave, from rail-to-rail; all I/O pins tristated, pulled to Vss, T0CKI = VDD, MCLR = VDD; WDT enabled/ disabled as specified.
 - b) For standby current measurements, the conditions are the same, except that the device is in SLEEP mode. The power-down current in SLEEP mode does not depend on the oscillator type.
 - **3:** Does not include current through REXT. The current through the resistor can be estimated by the formula: IR = VDD/2REXT (mA) with REXT in k Ω .

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15.3 DC Characteristics: PIC16LV54A-02 (Commercial) PIC16LV54A-02I (Industrial)

PIC16LV54A-02 PIC16LV54A-02I (Commercial, Industrial)			$\begin{array}{ll} \mbox{Standard Operating Conditions (unless otherwise specified)} \\ \mbox{Operating Temperature} & 0^{\circ}C \leq TA \leq +70^{\circ}C \mbox{ for commercial} \\ -20^{\circ}C \leq TA \leq +85^{\circ}C \mbox{ for industrial} \end{array}$					
Param No.	Symbol	Characteristic	Min	Тур†	Max	Units	Conditions	
D001	Vdd	Supply Voltage RC and XT modes	2.0	_	3.8	V		
D002	Vdr	RAM Data Retention Voltage ⁽¹⁾	_	1.5*	—	V	Device in SLEEP mode	
D003	VPOR	VDD Start Voltage to ensure Power-on Reset	—	Vss	—	V	See Section 5.1 for details on Power-on Reset	
D004	Svdd	VDD Rise Rate to ensure Power-on Reset	0.05*	_	—	V/ms	See Section 5.1 for details on Power-on Reset	
D010	IDD	Supply Current⁽²⁾ RC ⁽³⁾ and XT modes LP mode, Commercial LP mode, Industrial		0.5 11 14	 27 35	mA μA μA	Fosc = 2.0 MHz, VDD = 3.0V Fosc = 32 kHz, VDD = 2.5V WDT disabled Fosc = 32 kHz, VDD = 2.5V WDT disabled	
D020	IPD	Power-down Current^(2,4) Commercial Commercial Industrial Industrial		2.5 0.25 3.5 0.3	12 4.0 14 5.0	μΑ μΑ μΑ μΑ	VDD = 2.5V, WDT enabled VDD = 2.5V, WDT disabled VDD = 2.5V, WDT enabled VDD = 2.5V, WDT disabled	

These parameters are characterized but not tested.

- † Data in the Typical ("Typ") column is based on characterization results at 25°C. This data is for design guidance only and is not tested.
- **Note 1:** This is the limit to which VDD can be lowered in SLEEP mode without losing RAM data.
 - 2: The supply current is mainly a function of the operating voltage and frequency. Other factors such as bus loading, oscillator type, bus rate, internal code execution pattern and temperature also have an impact on the current consumption.
 - a) The test conditions for all IDD measurements in active Operation mode are: OSC1 = external square wave, from rail-to-rail; all I/O pins tristated, pulled to VSS, T0CKI = VDD, MCLR = VDD; WDT enabled/ disabled as specified.
 - b) For standby current measurements, the conditions are the same, except that the device is in SLEEP mode. The power-down current in SLEEP mode does not depend on the oscillator type.
 - **3:** Does not include current through REXT. The current through the resistor can be estimated by the formula: IR = VDD/2REXT (mA) with REXT in kΩ.
 - 4: The oscillator start-up time can be as much as 8 seconds for XT and LP oscillator selection on wake-up from SLEEP mode or during initial power-up.
15.4 DC Characteristics: PIC16C54A-04, 10, 20, PIC16LC54A-04, PIC16LV54A-02 (Commercial) PIC16C54A-04I, 10I, 20I, PIC16LC54A-04I, PIC16LV54A-02I (Industrial) PIC16C54A-04I, 10I, 20I, PIC16LC54A-04I, PIC16LV54A-02I (Industrial) PIC16C54A-04E, 10E, 20E, PIC16LC54A-04E (Extended)

DC CHARACTERISTICS			$ \begin{array}{l} \mbox{Standard Operating Conditions (unless otherwise specified)} \\ \mbox{Operating Temperature} & 0^\circ C \leq TA \leq +70^\circ C \mbox{ for commercial} \\ & -40^\circ C \leq TA \leq +85^\circ C \mbox{ for industrial} \\ & -20^\circ C \leq TA \leq +85^\circ C \mbox{ for industrial-PIC16LV54A-02I} \\ & -40^\circ C \leq TA \leq +125^\circ C \mbox{ for extended} \end{array} $						
Param No.	Symbol	Characteristic	Units	Conditions					
D030	VIL	Input Low Voltage I/O ports MCLR (Schmitt Trigger) T0CKI (Schmitt Trigger) OSC1 (Schmitt Trigger) OSC1	Vss Vss Vss Vss Vss Vss		0.2 VDD 0.15 VDD 0.15 VDD 0.15 VDD 0.3 VDD	V V V V	Pin at hi-impedance RC mode only ⁽³⁾ XT, HS and LP modes		
D040	VIH	Input High Voltage I/O ports I/O ports MCLR (Schmitt Trigger) T0CKI (Schmitt Trigger) OSC1 (Schmitt Trigger) OSC1	0.2 VDD + 1 2.0 0.85 VDD 0.85 VDD 0.85 VDD 0.85 VDD 0.7 VDD		VDD VDD VDD VDD VDD VDD VDD	V V V V V V	For all V _{DD} ⁽⁴⁾ 4.0V < V _{DD} ≤ 5.5V ⁽⁴⁾ RC mode only ⁽³⁾ XT, HS and LP modes		
D050	VHYS	Hysteresis of Schmitt Trigger inputs	0.15 Vdd*	_	—	V			
D060	IIL	Input Leakage Current ^(1,2) I/O ports MCLR MCLR TOCKI OSC1	-1.0 -5.0 -3.0 -3.0	0.5 0.5 0.5 0.5	+1.0 +5.0 +3.0 +3.0 —	μΑ μΑ μΑ μΑ μΑ	For VDD \leq 5.5V: VSS \leq VPIN \leq VDD, pin at hi-impedance VPIN = VSS +0.25V VPIN = VDD VSS \leq VPIN \leq VDD VSS \leq VPIN \leq VDD, XT, HS and LP modes		
D080	VOL	Output Low Voltage I/O ports OSC2/CLKOUT	_	_	0.6 0.6	V V	IOL = 8.7 mA, VDD = 4.5V IOL = 1.6 mA, VDD = 4.5V, RC mode only		
	VOH	Output High Voltage ⁽²⁾ I/O ports OSC2/CLKOUT	Vdd - 0.7 Vdd - 0.7			V V	IOH = -5.4 mA, VDD = 4.5V IOH = -1.0 mA, VDD = 4.5V, RC mode only		

These parameters are characterized but not tested.

† Data in the Typical ("Typ") column is based on characterization results at 25°C. This data is for design guidance only and is not tested.

Note 1: The leakage current on the MCLR/VPP pin is strongly dependent on the applied voltage level. The specified levels represent normal operating conditions. Higher leakage current may be measured at different input voltage.

2: Negative current is defined as coming out of the pin.

3: For the RC mode, the OSC1/CLKIN pin is a Schmitt Trigger input. It is not recommended that the PIC16C5X be driven with external clock in RC mode.

*

15.5 Timing Parameter Symbology and Load Conditions

The timing parameter symbols have been created with one of the following formats:

1. TppS2ppS

oS	
Frequency	T Time
case letters (pp) and their meanings:	
to	mc MCLR
CLKOUT	osc oscillator
cycle time	os OSC1
device reset timer	t0 T0CKI
I/O port	wdt watchdog timer
case letters and their meanings:	
Fall	P Period
High	R Rise
Invalid (Hi-impedance)	V Valid
Low	Z Hi-impedance
	case letters (pp) and their meanings: o CLKOUT cycle time device reset timer I/O port case letters and their meanings: Fall High Invalid (Hi-impedance)

FIGURE 15-1: LOAD CONDITIONS FOR DEVICE TIMING SPECIFICATIONS - PIC16C54A



15.6 Timing Diagrams and Specifications

FIGURE 15-2: EXTERNAL CLOCK TIMING - PIC16C54A



TABLE 15-1: EXTERNAL CLOCK TIMING REQUIREMENTS - PIC16C54A
--

AC Characteristics		$\begin{array}{llllllllllllllllllllllllllllllllllll$						
Param No.	Symbol	Characteristic	Min	Тур†	Max	Max Units Conditions		
	Fosc	External CLKIN Fre-	DC	_	4.0	MHz	XT OSC mode	
		quency ⁽¹⁾	DC	—	2.0	MHz	XT osc mode (PIC16LV54A)	
			DC	—	4.0	MHz	HS osc mode (04)	
			DC	—	10	MHz	HS osc mode (10)	
			DC	—	20	MHz	HS osc mode (20)	
			DC	—	200	kHz	LP OSC mode	
		Oscillator Frequency ⁽¹⁾	DC		4.0	MHz	RC osc mode	
			DC	—	2.0	MHz	RC osc mode (PIC16LV54A)	
			0.1	—	4.0	MHz	XT OSC mode	
			0.1	—	2.0	MHz	XT osc mode (PIC16LV54A)	
			4.0	—	4.0	MHz	HS osc mode (04)	
			4.0	—	10	MHz	HS osc mode (10)	
			4.0	—	20	MHz	HS osc mode (20)	
			5.0	—	200	kHz	LP osc mode	

* These parameters are characterized but not tested.

† Data in the Typical ("Typ") column is based on characterization results at 25°C. This data is for design guidance only and is not tested.

- Note 1: All specified values are based on characterization data for that particular oscillator type under standard operating conditions with the device executing code. Exceeding these specified limits may result in an unstable oscillator operation and/or higher than expected current consumption. When an external clock input is used, the "max" cycle time limit is "DC" (no clock) for all devices.
 - Instruction cycle period (TcY) equals four times the input oscillator time base period.

TABLE 15-1:	EXTERNAL CLOCK TIMING REQUIREMENTS - PIC16C54A
-------------	--

AC Characteristics		$\begin{array}{llllllllllllllllllllllllllllllllllll$						
Param No.	Symbol	Characteristic Min Typ† Max Units Conditions						
1	Tosc	External CLKIN Period ⁽¹⁾	250	_		ns	XT OSC mode	
			500	—	—	ns	XT osc mode (PIC16LV54A)	
			250	—	—	ns	HS osc mode (04)	
			100	—	—	ns	HS osc mode (10)	
			50	—	—	ns	HS osc mode (20)	
			5.0	_		μs	LP OSC mode	
		Oscillator Period ⁽¹⁾	250	_	_	ns	RC osc mode	
			500	—	—	ns	RC osc mode (PIC16LV54A)	
			250	—	10,000	ns	XT OSC mode	
			500	—	—	ns	XT osc mode (PIC16LV54A)	
			250	—	250	ns	HS osc mode (04)	
			100	—	250	ns	HS osc mode (10)	
			50	—	250	ns	HS osc mode (20)	
			5.0	_	200	μs	LP OSC mode	
2	Тсу	Instruction Cycle Time ⁽²⁾	—	4/Fosc	—	—		
3	TosL, TosH	Clock in (OSC1) Low or	85*	_	—	ns	XT oscillator	
		High Time	20*	—	—	ns	HS oscillator	
			2.0*	—	—	μS	LP oscillator	
4	TosR, TosF	Clock in (OSC1) Rise or	—	_	25*	ns	XT oscillator	
		Fall Time	—	—	25*	ns	HS oscillator	
			—	—	50*	ns	LP oscillator	

* These parameters are characterized but not tested.

† Data in the Typical ("Typ") column is based on characterization results at 25°C. This data is for design guidance only and is not tested.

Note 1: All specified values are based on characterization data for that particular oscillator type under standard operating conditions with the device executing code. Exceeding these specified limits may result in an unstable oscillator operation and/or higher than expected current consumption. When an external clock input is used, the "max" cycle time limit is "DC" (no clock) for all devices.

2: Instruction cycle period (TcY) equals four times the input oscillator time base period.



TABLE 15-2: CLKOUT AND I/O TIMING REQUIREMENTS - PIC16C54A

AC Chara	octeristics	$ \begin{array}{ll} \mbox{Standard Operating Conditions (unless otherwise specified)} \\ \mbox{Operating Temperature} & 0^{\circ}C \leq TA \leq +70^{\circ}C \ \ for \ commercial \\ -40^{\circ}C \leq TA \leq +85^{\circ}C \ for \ industrial \\ -20^{\circ}C \leq TA \leq +85^{\circ}C \ for \ industrial - \ PIC16LV54A-02I \\ -40^{\circ}C \leq TA \leq +125^{\circ}C \ for \ extended \\ \end{array} $						
Param No.	Symbol	Characteristic	Min	Тур†	Мах	Units		
10	TosH2ckL	OSC1↑ to CLKOUT↓ ⁽¹⁾	—	15	30**	ns		
11	TosH2ckH	OSC1↑ to CLKOUT↑ ⁽¹⁾	—	15	30**	ns		
12	TckR	CLKOUT rise time ⁽¹⁾	—	5.0	15**	ns		
13	TckF	CLKOUT fall time ⁽¹⁾	—	5.0	15**	ns		
14	TckL2ioV	CLKOUT↓ to Port out valid ⁽¹⁾	—	—	40**	ns		
15	TioV2ckH	Port in valid before CLKOUT ⁽¹⁾	0.25 TCY+30*	—	—	ns		
16	TckH2iol	Port in hold after CLKOUT ⁽¹⁾	0*	—	—	ns		
17	TosH2ioV	OSC1↑ (Q1 cycle) to Port out valid ⁽²⁾	—	—	100*	ns		
18	TosH2iol	OSC1 [↑] (Q2 cycle) to Port input invalid (I/O in hold time)	TBD	—	—	ns		
19	TioV2osH	Port input valid to OSC1↑ (I/O in setup time)	TBD	—	—	ns		
20	TioR	Port output rise time ⁽²⁾	—	10	25**	ns		
21	TioF	Port output fall time ⁽²⁾	—	10	25**	ns		

* These parameters are characterized but not tested.

** These parameters are design targets and are not tested. No characterization data available at this time.

† Data in the Typical ("Typ") column is based on characterization results at 25°C. This data is for design guidance only and is not tested.

Note 1: Measurements are taken in RC Mode where CLKOUT output is 4 x Tosc.

2: Please refer to Figure 15-1 for load conditions.



FIGURE 15-4: RESET, WATCHDOG TIMER, AND DEVICE RESET TIMER TIMING - PIC16C54A

TABLE 15-3: RESET, WATCHDOG TIMER, AND DEVICE RESET TIMER - PIC16C54A

		Standard Operating Condition	ns (unle	ess othe	erwise	specifie	ed)	
		Operating Temperature $0^{\circ}C \le TA \le +70^{\circ}C$ for commercial						
AC Chara	cteristics	-40	$0^{\circ}C \leq TA$	√≤ + 85°	C for ind	dustrial		
		-20	$0^{\circ}C \leq TA$	∖ ≤ + 85°	C for ind	dustrial -	- PIC16LV54A-02I	
		-40	$0^{\circ}C \leq TA$	∖ ≤ + 125	°C for e	xtended	ł	
Param								
No.	Symbol	Characteristic	Min	Тур†	Мах	Units	Conditions	
30	TmcL	MCLR Pulse Width (low)	100*	_	_	ns	VDD = 5.0V	
			1	—	—	μS	VDD = 5.0V (PIC16LV54A only)	
31	Twdt	Watchdog Timer Time-out	9.0*	18*	30*	ms	VDD = 5.0V (Comm)	
		Period (No Prescaler)						
32	Tdrt	Device Reset Timer Period	9.0*	18*	30*	ms	VDD = 5.0V (Comm)	
34	Tioz	I/O Hi-impedance from MCLR	_	_	100*	ns		
		Low	—		1μs	—	(PIC16LV54A only)	

These parameters are characterized but not tested.

† Data in the Typical ("Typ") column is at 5V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.



TABLE 15-4: TIMER0 CLOCK REQUIREMENTS - PIC16C54A

		Standard Operating	g Conditions (ur	nless o	therw	ise spe	ecified)	
		Operating Temperat	ature $0^{\circ}C \le TA \le +70^{\circ}C$ for commercial					
1	AC Chara	octeristics	$-40^{\circ}C \le$	$TA \le +8$	85°C fo	or indus	trial	
			$-20^{\circ}C \le$	TA ≤ +8	85°C fc	or indus	trial - PIC16LV54A-02I	
			$-40^{\circ}C \le$	Ta ≤ +1	25°C	for exte	ended	
Param No.	Symbol	Characteristic	Min	Тур†	Max	Units	Conditions	
40	Tt0H	T0CKI High Pulse Width						
		- No Prescaler	0.5 TCY + 20*	—	—	ns		
		- With Prescaler	10*	—	_	ns		
41	Tt0L	T0CKI Low Pulse Width						
		- No Prescaler	0.5 TCY + 20*	—	—	ns		
		- With Prescaler	10*	—	_	ns		
42	Tt0P	T0CKI Period	20 or <u>TCY + 40</u> *	—	_	ns	Whichever is greater.	
			N				N = Prescale Value	
							(1, 2, 4,, 256)	

* These parameters are characterized but not tested.

† Data in the Typical ("Typ") column is at 5V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested. NOTES:

16.0 DEVICE CHARACTERIZATION - PIC16C54A

The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only. The performance characteristics listed herein are not tested or guaranteed. In some graphs or tables, the data presented may be outside the specified operating range (e.g., outside specified power supply range) and therefore outside the warranted range.

"Typical" represents the mean of the distribution at 25°C. "Maximum" or "minimum" represents (mean + 3σ) or (mean - 3σ) respectively, where σ is a standard deviation, over the whole temperature range.



FIGURE 16-1: TYPICAL RC OSCILLATOR FREQUENCY vs. TEMPERATURE

TABLE 16-1:	RC OSCILLATOR FREQUENCIES
-------------	---------------------------

Сехт	Rext	Average Fosc @ 5 V, 25°C		
20 pF	3.3K	5 MHz	± 27%	
	5K	3.8 MHz	± 21%	
	10K	2.2 MHz	± 21%	
	100K	262 kHz	± 31%	
100 pF	3.3K	1.6 MHz	± 13%	
	5K	1.2 MHz	± 13%	
	10K	684 kHz	± 18%	
	100K	71 kHz	± 25%	
300 pF	3.3K	660 kHz	± 10%	
	5.0K	484 kHz	± 14%	
	10K	267 kHz	± 15%	
	100K	29 kHz	± 19%	

The frequencies are measured on DIP packages.

The percentage variation indicated here is part-to-part variation due to normal process distribution. The variation indicated is ± 3 standard deviation from average value for VDD = 5V.









FIGURE 16-4: TYPICAL RC OSCILLATOR FREQUENCY vs. VDD, CEXT = 300 PF, 25°C

PIC16C5X

FIGURE 16-5: TYPICAL IPD vs. VDD, WATCHDOG DISABLED (25°C)







FIGURE 16-7: VTH (INPUT THRESHOLD VOLTAGE) OF I/O PINS - VDD







PIC16C5X



FIGURE 16-9: VIH, VIL OF MCLR, TOCKI AND OSC1 (IN RC MODE) vs. VDD



FIGURE 16-10: TYPICAL IDD vs. FREQUENCY (WDT DISABLED, RC MODE @ 20 PF, 25°C)

FIGURE 16-11: MAXIMUM IDD vs. FREQUENCY (WDT DISABLED, RC MODE @ 20 PF, -40°C to +85°C)





FIGURE 16-12: TYPICAL IDD vs. FREQUENCY (WDT DISABLED, RC MODE @ 100 PF, 25°C)

FIGURE 16-13: MAXIMUM IDD vs. FREQUENCY (WDT DISABLED, RC MODE @ 100 PF, -40°C to +85°C)



 Typical: statistical mean @ 25°C.

 Maximum: mean + 3s (-40°C to 125°C)

 Minimum: mean - 3s (-40°C to 125°C)
 </tr

FIGURE 16-14: TYPICAL IDD vs. FREQUENCY (WDT DISABLED, RC MODE @ 300 PF, 25°C)

FIGURE 16-15: MAXIMUM IDD vs. FREQUENCY (WDT DISABLED, RC MODE @ 300 PF, -40°C to +85°C)





FIGURE 16-17: TRANSCONDUCTANCE (gm) OF HS OSCILLATOR vs. VDD



FIGURE 16-18: TRANSCONDUCTANCE (gm) OF LP OSCILLATOR vs. VDD



FIGURE 16-19:

TRANSCONDUCTANCE (gm) OF XT OSCILLATOR vs. VDD





FIGURE 16-21: PORTA, B AND C IOH vs. VOH, VDD = 5V





TABLE 16-2:INPUT CAPACITANCE FOR
PIC16C54A/C58A

Pin	Typical Capacitance (pF)				
FIII	18L PDIP	18L SOIC			
RA port	5.0	4.3			
RB port	5.0	4.3			
MCLR	17.0	17.0			
OSC1	4.0	3.5			
OSC2/CLKOUT	4.3	3.5			
TOCKI	3.2	2.8			

All capacitance values are typical at 25°C. A part-to-part variation of $\pm 25\%$ (three standard deviations) should be taken into account.

FIGURE 16-23: PORTA, B AND C IOL vs. VoL, VDD = 5V



NOTES:

17.0 ELECTRICAL CHARACTERISTICS - PIC16LC54A

Absolute Maximum Ratings^(†)

Ambient temperature under bias	–55°C to +125°C
Storage temperature	
Voltage on VDD with respect to Vss	0 to +7.5V
Voltage on MCLR with respect to Vss	0 to +14V
Voltage on all other pins with respect to Vss0.0	6V to (VDD + 0.6V)
Total power dissipation ⁽¹⁾	800 mW
Max. current out of Vss pin	150 mA
Max. current into Vod pin	
Max. current into an input pin (T0CKI only)	±500 μA
Input clamp current, liк (Vi < 0 or Vi > VDD)	±20 mA
Output clamp current, IOK (VO < 0 or VO > VDD)	±20 mA
Max. output current sunk by any I/O pin	25 mA
Max. output current sourced by any I/O pin	20 mA
Max. output current sourced by a single I/O (Port A, B or C)	50 mA
Max. output current sunk by a single I/O (Port A, B or C)	50 mA
Note 1: Power dissipation is calculated as follows: Pdis = VDD x {IDD - \sum IOH} + \sum {(VDD-VOH) x let $x \in X$ }	OH} + $∑$ (VOL x IOL)

† NOTICE: Stresses above those listed under "Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operation listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

PIC16C5X







2: The maximum rated speed of the part limits the permissible combinations of voltage and frequency. Please reference the Product Identification System section for the maximum rated speed of the parts.





2: The maximum rated speed of the part limits the permissible combinations of voltage and frequency.

Please reference the Product Identification System section for the maximum rated speed of the parts.







17.1 DC Characteristics:PIC16C54C/C55A/C56A/C57C/C58B-04, 20 (Commercial, Industrial) PIC16LC54C/LC55A/LC56A/LC57C/LC58B-04 (Commercial, Industrial) PIC16CR54C/CR56A/CR57C/CR58B-04, 20 (Commercial, Industrial) PIC16LCR54C/LCR56A/LCR57C/LCR58B-04 (Commercial, Industrial)

PIC16LC5X PIC16LCR5X (Commercial, Industrial)				ting Terr	peratu	ire	ions (unless otherwise specified) $0^{\circ}C \le TA \le +70^{\circ}C$ for commercial $-40^{\circ}C \le TA \le +85^{\circ}C$ for industrial	
PIC16C5X PIC16CR5X (Commercial, Industrial)				ting Terr	-		ions (unless otherwise specified) 0°C ≤ TA ≤ +70°C for commercial −40°C ≤ TA ≤ +85°C for industrial	
Param No.	Symbol	Characteristic/Device	Min	Тур†	Max	Units Conditions		
	Vdd	Supply Voltage						
D001		PIC16LC5X	2.5 2.7 2.5		5.5 5.5 5.5	V V V	$\begin{array}{l} -40^{\circ}C \leq TA \leq +\ 85^{\circ}C,\ 16LCR5X \\ -40^{\circ}C \leq TA \leq 0^{\circ}C,\ 16LC5X \\ 0^{\circ}C \leq TA \leq +\ 85^{\circ}C\ 16LC5X \end{array}$	
D001A		PIC16C5X	3.0 4.5	_	5.5 5.5	V V	RC, XT, LP and HS mode from 0 - 10 MHz from 10 - 20 MHz	
D002	Vdr	RAM Data Retention Volt- age ⁽¹⁾	—	1.5*	_	V	Device in SLEEP mode	
D003	VPOR	VDD Start Voltage to ensure Power-on Reset	—	Vss	—	V	See Section 5.1 for details on Power-on Reset	
D004	SVDD	VDD Rise Rate to ensure Power-on Reset	0.05*	—	—	V/ms	See Section 5.1 for details on Power-on Reset	

Legend: Rows with standard voltage device data only are shaded for improved readability.

* These parameters are characterized but not tested.

- † Data in "Typ" column is at 5V, 25°C, unless otherwise stated. These parameters are for design guidance only, and are not tested.
- Note 1: This is the limit to which VDD can be lowered in SLEEP mode without losing RAM data.
 - 2: The supply current is mainly a function of the operating voltage and frequency. Other factors such as bus loading, oscillator type, bus rate, internal code execution pattern and temperature also have an impact on the current consumption.
 - a) The test conditions for all IDD measurements in active Operation mode are: OSC1 = external square wave, from rail-to-rail; all I/O pins tristated, pulled to Vss, T0CKI = VDD, MCLR = VDD; WDT enabled/disabled as specified.
 - b) For standby current measurements, the conditions are the same, except that the device is in SLEEP mode. The power-down current in SLEEP mode does not depend on the oscillator type.
 - **3:** Does not include current through REXT. The current through the resistor can be estimated by the formula: IR = VDD/2REXT (mA) with REXT in k Ω .

17.1 DC Characteristics:PIC16C54C/C55A/C56A/C57C/C58B-04, 20 (Commercial, Industrial) PIC16LC54C/LC55A/LC56A/LC57C/LC58B-04 (Commercial, Industrial) PIC16CR54C/CR56A/CR57C/CR58B-04, 20 (Commercial, Industrial) PIC16LCR54C/LCR56A/LCR57C/LCR58B-04 (Commercial, Industrial)

PIC16LC5X PIC16LCR5X (Commercial, Industrial)				ard Ope ting Terr	•		ions (unless otherwise specified) $0^{\circ}C \le TA \le +70^{\circ}C$ for commercial $-40^{\circ}C \le TA \le +85^{\circ}C$ for industrial	
PIC16C5X PIC16CR5X (Commercial, Industrial)				ard Ope ting Terr	•		ions (unless otherwise specified) $0^{\circ}C \le TA \le +70^{\circ}C$ for commercial $-40^{\circ}C \le TA \le +85^{\circ}C$ for industrial	
Param No.	Symbol	Characteristic/Device	Min	Min Typ† Max Units Conditions				
	IDD	Supply Current ^(2,3)						
D010		PIC16LC5X	_	0.5	2.4	mA	Fosc = 4.0 MHz, VDD = 5.5V, XT and	
			—	11	27	μA	RC modes	
							FOSC = 32 kHz, VDD = 2.5 V, LP mode,	
			—	14	35	μA	Commercial	
							Fosc = 32 kHz, VDD = 2.5V, LP mode, Industrial	
D010A		PIC16C5X	_	1.8	2.4	mA	Fosc = 4 MHz, VDD = 5.5V, XT and RC	
			—	2.6	3.6*	mA	modes	
			—	4.5	16	mA	Fosc = 10 MHz, VDD = 3.0V, HS mode	
			—	14	32	μA	Fosc = 20 MHz, VDD = 5.5V, HS mode Fosc = 32 kHz, VDD = 3.0V, LP mode,	
			—	17	40	μA	Commercial	
							Fosc = 32 kHz, VDD = 3.0V, LP mode, Industrial	

Legend: Rows with standard voltage device data only are shaded for improved readability.

* These parameters are characterized but not tested.

- † Data in "Typ" column is at 5V, 25°C, unless otherwise stated. These parameters are for design guidance only, and are not tested.
- Note 1: This is the limit to which VDD can be lowered in SLEEP mode without losing RAM data.
 - 2: The supply current is mainly a function of the operating voltage and frequency. Other factors such as bus loading, oscillator type, bus rate, internal code execution pattern and temperature also have an impact on the current consumption.
 - a) The test conditions for all IDD measurements in active Operation mode are: OSC1 = external square wave, from rail-to-rail; all I/O pins tristated, pulled to VSS, T0CKI = VDD, MCLR = VDD; WDT enabled/disabled as specified.
 - b) For standby current measurements, the conditions are the same, except that the device is in SLEEP mode. The power-down current in SLEEP mode does not depend on the oscillator type.
 - 3: Does not include current through REXT. The current through the resistor can be estimated by the formula: IR = VDD/2REXT (mA) with REXT in k Ω .

17.1 DC Characteristics:PIC16C54C/C55A/C56A/C57C/C58B-04, 20 (Commercial, Industrial) PIC16LC54C/LC55A/LC56A/LC57C/LC58B-04 (Commercial, Industrial) PIC16CR54C/CR56A/CR57C/CR58B-04, 20 (Commercial, Industrial) PIC16LCR54C/LCR56A/LCR57C/LCR58B-04 (Commercial, Industrial)

PIC16LC5X PIC16LCR5X (Commercial, Industrial)				ard Ope ting Terr	•		ions (unless otherwise specified) $0^{\circ}C \le TA \le +70^{\circ}C$ for commercial $-40^{\circ}C \le TA \le +85^{\circ}C$ for industrial
PIC16C5X PIC16CR5X (Commercial, Industrial)				ard Ope ting Terr			ions (unless otherwise specified) $0^{\circ}C \le TA \le +70^{\circ}C$ for commercial $-40^{\circ}C \le TA \le +85^{\circ}C$ for industrial
Param No. Symbol Characteristic/Device				Тур†	Max	Units	Conditions
	IPD	Power-down Current ⁽²⁾					
D020		PIC16LC5X		0.25 0.25 1	2 3 5	μΑ μΑ μΑ	VDD = 2.5V, WDT disabled, Commercial $VDD = 2.5V$, WDT disabled, Industrial $VDD = 2.5V$, WDT enabled, Commercial
			_	1.25	8	μA	$V_{DD} = 2.5V, WDT$ enabled, Industrial
D020A		PIC16C5X		0.25 0.25 1.8 2.0 4	4.0 5.0 7.0* 8.0* 12*	μΑ μΑ μΑ μΑ	VDD = 3.0V, WDT disabled, Commercial VDD = 3.0V, WDT disabled, Industrial VDD = 5.5V, WDT disabled, Commercial VDD = 5.5V, WDT disabled, Industrial VDD = 3.0V, WDT enabled, Commercial
			—	4	14*	μA	VDD = 3.0V, WDT enabled, Industrial
			_	9.8 12	27* 30*	μΑ μΑ	VDD = 5.5V, WDT enabled, Commercial VDD = 5.5V, WDT enabled, Industrial

Legend: Rows with standard voltage device data only are shaded for improved readability.

* These parameters are characterized but not tested.

† Data in "Typ" column is at 5V, 25°C, unless otherwise stated. These parameters are for design guidance only, and are not tested.

Note 1: This is the limit to which VDD can be lowered in SLEEP mode without losing RAM data.

2: The supply current is mainly a function of the operating voltage and frequency. Other factors such as bus loading, oscillator type, bus rate, internal code execution pattern and temperature also have an impact on the current consumption.

a) The test conditions for all IDD measurements in active Operation mode are: OSC1 = external square wave, from rail-to-rail; all I/O pins tristated, pulled to VSS, T0CKI = VDD, MCLR = VDD; WDT enabled/disabled as specified.

- b) For standby current measurements, the conditions are the same, except that the device is in SLEEP mode. The power-down current in SLEEP mode does not depend on the oscillator type.
- **3:** Does not include current through REXT. The current through the resistor can be estimated by the formula: IR = VDD/2REXT (mA) with REXT in k Ω .

17.2 DC Characteristics: PIC16C54C/C55A/C56A/C57C/C58B-04E, 20E (Extended) PIC16CR54C/CR56A/CR57C/CR58B-04E, 20E (Extended)

PIC16C54C/C55A/C56A/C57C/C58B-04E, 20E PIC16CR54C/CR56A/CR57C/CR58B-04E, 20E (Extended)				Standard Operating Conditions (unless otherwise specific Operating Temperature $-40^{\circ}C \le TA \le +125^{\circ}C$ for extended						
Param No. Symbol Characteristic				Тур†	Max	Units	Conditions			
D001	Vdd	3.0 4.5		5.5 5.5		RC, XT, LP, and HS mode from 0 - 10 MHz from 10 - 20 MHz				
D002	Vdr	RAM Data Retention Voltage ⁽¹⁾	—	1.5*	—	V	Device in SLEEP mode			
D003	VPOR	VDD start voltage to ensure Power-on Reset	—	Vss	—	V	See Section 5.1 for details on Power-on Reset			
D004	SVDD	VDD rise rate to ensure Power-on Reset	0.05*	—	—	V/ms	See Section 5.1 for details on Power-on Reset			
D010	IDD	Supply Current ⁽²⁾ XT and RC ⁽³⁾ modes HS mode	_	1.8 9.0	3.3 20	mA mA	Fosc = 4.0 MHz, Vdd = 5.5V Fosc = 20 MHz, Vdd = 5.5V			
D020	IPD	Power-down Current ⁽²⁾		0.3 10 12 4.8 18 26	17 50* 60* 31* 68* 90*	μΑ μΑ μΑ μΑ μΑ μΑ	VDD = 3.0V, WDT disabled VDD = 4.5V, WDT disabled VDD = 5.5V, WDT disabled VDD = 3.0V, WDT enabled VDD = 4.5V, WDT enabled VDD = 5.5V, WDT enabled			

These parameters are characterized but not tested.

† Data in "Typ" column is at 5V, 25°C, unless otherwise stated. These parameters are for design guidance only, and are not tested.

- Note 1: This is the limit to which VDD can be lowered in SLEEP mode without losing RAM data.
 - 2: The supply current is mainly a function of the operating voltage and frequency. Other factors such as bus loading, oscillator type, bus rate, internal code execution pattern, and temperature also have an impact on the current consumption.
 - a) The test conditions for all IDD measurements in active Operation mode are: OSC1 = external square wave, from rail-to-rail; all I/O pins tristated, pulled to Vss, TOCKI = VDD, MCLR = VDD; WDT enabled/ disabled as specified.
 - b) For standby current measurements, the conditions are the same, except that the device is in SLEEP mode. The power-down current in SLEEP mode does not depend on the oscillator type.
 - **3:** Does not include current through REXT. The current through the resistor can be estimated by the formula: IR = VDD/2REXT (mA) with REXT in kΩ.

17.3 DC Characteristics: PIC16C54C/C55A/C56A/C57C/C58B-04, 20 (Commercial, Industrial, Extended) PIC16LC54C/LC55A/LC56A/LC57C/LC58B-04 (Commercial, Industrial) PIC16CR54C/CR56A/CR57C/CR58B-04, 20 (Commercial, Industrial, Extended) PIC16LCR54C/LCR56A/LCR57C/LCR58B-04 (Commercial, Industrial)

DC CH	ARACTE	RISTICS	Standard Operat Operating Tempe		$\begin{array}{l} \mbox{ditions (unless otherwise specified)} \\ 0^{\circ}C \leq TA \leq +70^{\circ}C \mbox{ for commercial} \\ -40^{\circ}C \leq TA \leq +85^{\circ}C \mbox{ for industrial} \\ -40^{\circ}C \leq TA \leq +125^{\circ}C \mbox{ for extended} \end{array}$			
Param No.	Symbol	Characteristic	Min	Тур†	Max	Units	Conditions	
D030	VIL	Input Low Voltage I/O Ports I/O Ports MCLR (Schmitt Trigger) TOCKI (Schmitt Trigger) OSC1 (Schmitt Trigger) OSC1	Vss Vss Vss Vss Vss Vss Vss	 	0.8 V 0.15 VDD 0.15 VDD 0.15 VDD 0.15 VDD 0.3 VDD	V V V V V	4.5V <v<sub>DD ≤ 5.5V Otherwise RC mode only⁽³⁾ XT, HS and LP modes</v<sub>	
D040	Viн	Input High Voltage I/O ports I/O ports MCLR (Schmitt Trigger) TOCKI (Schmitt Trigger) OSC1 (Schmitt Trigger) OSC1	2.0 0.25 Vdd+0.8 0.85 Vdd 0.85 Vdd 0.85 Vdd 0.85 Vdd 0.7 Vdd	 	Vdd Vdd Vdd Vdd Vdd Vdd Vdd	V V V V V	4.5V < VDD ≤ 5.5V Otherwise RC mode only ⁽³⁾ XT, HS and LP modes	
D050	VHYS	Hysteresis of Schmitt Trigger inputs	0.15 Vdd*	—	_	V		
D060	Ιι∟	Input Leakage Current ^(1,2) I/O ports MCLR MCLR T0CKI OSC1	-1.0 -5.0 -3.0 -3.0	0.5 — 0.5 0.5 0.5	+1.0 +5.0 +3.0 +3.0 —	μΑ μΑ μΑ μΑ μΑ	For VDD \leq 5.5V: VSS \leq VPIN \leq VDD, pin at hi-impedance VPIN = VSS +0.25V VPIN = VDD VSS \leq VPIN \leq VDD VSS \leq VPIN \leq VDD, XT, HS and LP modes	
D080	Vol	Output Low Voltage I/O ports OSC2/CLKOUT		_	0.6 0.6	V V	IOL = 8.7 mA, VDD = 4.5V IOL = 1.6 mA, VDD = 4.5V, RC mode only	
D090	Vон	Output High Voltage ⁽²⁾ I/O ports OSC2/CLKOUT	Vdd - 0.7 Vdd - 0.7	_	_	V V	IOH = -5.4 mA, VDD = 4.5V IOH = -1.0 mA, VDD = 4.5V, RC mode only	

† Data in the Typical ("Typ") column is based on characterization results at 25°C. This data is for design guidance only and is not tested.

- Note 1: The leakage current on the MCLR/VPP pin is strongly dependent on the applied voltage level. The specified levels represent normal operating conditions. Higher leakage current may be measured at different input voltage.
 - **2:** Negative current is defined as coming out of the pin.
 - 3: For the RC mode, the OSC1/CLKIN pin is a Schmitt Trigger input. It is not recommended that the PIC16C5X be driven with external clock in RC mode.

17.4 Timing Parameter Symbology and Load Conditions

The timing parameter symbols have been created with one of the following formats:

1. TppS2ppS

2. Tp	pS	
Т		
F	Frequency	T Time
Lowe	rcase letters (pp) and their meanings:	
рр		
2	to	mc MCLR
ck	CLKOUT	osc oscillator
су	cycle time	os OSC1
drt	device reset timer	t0 T0CKI
io	I/O port	wdt watchdog timer
Uppe	rcase letters and their meanings:	
S		
F	Fall	P Period
н	High	R Rise
I	Invalid (Hi-impedance)	V Valid
L	Low	Z Hi-impedance

FIGURE 17-5: LOAD CONDITIONS FOR DEVICE TIMING SPECIFICATIONS -PIC16C54C/CR54C/C55A/C56A/CR56A/C57C/CR57C/C58B/CR58B-04, 20



17.5 Timing Diagrams and Specifications



FIGURE 17-6: EXTERNAL CLOCK TIMING - PIC16C5X, PIC16CR5X

TABLE 17-1: EXTERNAL CLOCK TIMING REQUIREMENTS - PIC16C5X, PIC16CR5X

AC Charac	cteristics	$\begin{array}{llllllllllllllllllllllllllllllllllll$							
Param No.	Symbol	Characteristic	Min	Тур†	Max	Units	Conditions		
	Fosc	External CLKIN Frequency ⁽¹⁾	DC	_	4.0	MHz	XT osc mode		
			DC	—	4.0	MHz	HS osc mode (04)		
			DC	—	20	MHz	HS osc mode (20)		
			DC	—	200	kHz	LP osc mode		
		Oscillator Frequency ⁽¹⁾	DC	—	4.0	MHz	RC osc mode		
			0.45	—	4.0	MHz	XT osc mode		
			4.0	—	4.0	MHz	HS osc mode (04)		
			4.0	—	20	MHz	HS osc mode (20)		
			5.0		200	kHz	LP OSC mode		
1	Tosc	External CLKIN Period ⁽¹⁾	250	—	—	ns	XT osc mode		
			250	—	—	ns	HS osc mode (04)		
			50	—	—	ns	HS osc mode (20)		
	Oscillator Period ⁽¹⁾		5.0		—	μS	LP OSC mode		
			250	—	—	ns	RC osc mode		
			250	—	2,200	ns	XT osc mode		
				—	250	ns	HS osc mode (04)		
			50	—	250	ns	HS osc mode (20)		
			5.0	—	200	μS	LP OSC mode		

* These parameters are characterized but not tested.

† Data in the Typical ("Typ") column is at 5V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

Note 1: All specified values are based on characterization data for that particular oscillator type under standard operating conditions with the device executing code. Exceeding these specified limits may result in an unstable oscillator operation and/or higher than expected current consumption.

When an external clock input is used, the "max" cycle time limit is "DC" (no clock) for all devices.

2: Instruction cycle period (TCY) equals four times the input oscillator time base period.

TABLE 17-1: EXTERNAL CLOCK TIMING REQUIREMENTS - PIC16C5X, PIC16CR5X

AC Characteristics		-40°C	$C \le TA :$ $C \le TA :$	ss other∖ ≤ +70°C f ≤ +85°C f ≤ +125°C	or com or indu	mercial strial	-
Param No.	Symbol	Characteristic	Min	Тур†	Max	Units	Conditions
2	Тсу	Instruction Cycle Time ⁽²⁾		4/Fosc		—	
3	TosL, TosH	Clock in (OSC1) Low or High Time	50* 20*			ns ns	XT oscillator HS oscillator
4	TosR, TosF	Clock in (OSC1) Rise or Fall Time	2.0*	_	 25*	μS ns	LP oscillator XT oscillator
			_		25* 50*	ns ns	HS oscillator LP oscillator

- * These parameters are characterized but not tested.
- † Data in the Typical ("Typ") column is at 5V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.
- **Note 1:** All specified values are based on characterization data for that particular oscillator type under standard operating conditions with the device executing code. Exceeding these specified limits may result in an unstable oscillator operation and/or higher than expected current consumption.

When an external clock input is used, the "max" cycle time limit is "DC" (no clock) for all devices.

2: Instruction cycle period (TCY) equals four times the input oscillator time base period.



AC Chara	acteristics	$-40^{\circ}C \le TA \le -40^{\circ}C \le -4$	• otherwise spec +70°C for comme +85°C for industr +125°C for exten	ercial ial		
Param No.	Symbol	Characteristic	Min	Тур†	Max	Units
10	TosH2ckL	OSC1↑ to CLKOUT↓ ⁽¹⁾	_	15	30**	ns
11	TosH2ckH	OSC1↑ to CLKOUT↑ ⁽¹⁾	_	15	30**	ns
12	TckR	CLKOUT rise time ⁽¹⁾	—	5.0	15**	ns
13	TckF	CLKOUT fall time ⁽¹⁾	—	5.0	15**	ns
14	TckL2ioV	CLKOUT↓ to Port out valid ⁽¹⁾	—		40**	ns
15	TioV2ckH	Port in valid before CLKOUT ⁽¹⁾	0.25 TCY+30*		_	ns
16	TckH2iol	Port in hold after CLKOUT ⁽¹⁾	0*		_	ns
17	TosH2ioV	OSC1↑ (Q1 cycle) to Port out valid ⁽²⁾	—		100*	ns
18	TosH2iol	OSC1↑ (Q2 cycle) to Port input invalid (I/O in hold time)	TBD	_	_	ns
19	TioV2osH	Port input valid to OSC1↑ (I/O in setup time)	TBD		_	ns
20	TioR	Port output rise time ⁽²⁾	_	10	25**	ns
21	TioF	Port output fall time ⁽²⁾	—	10	25**	ns

* These parameters are characterized but not tested.

** These parameters are design targets and are not tested. No characterization data available at this time.

† Data in the Typical ("Typ") column is at 5V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

Note 1: Measurements are taken in RC Mode where CLKOUT output is 4 x Tosc.

2: Refer to Figure 17-5 for load conditions.



FIGURE 17-8: RESET, WATCHDOG TIMER, AND DEVICE RESET TIMER TIMING - PIC16C5X, PIC16CR5X

TABLE 17-3: RESET, WATCHDOG TIMER, AND DEVICE RESET TIMER - PIC16C5X, PIC16CR5X

AC Characteristics		$ \begin{array}{l} \mbox{Standard Operating Conditions (unless otherwise specified)} \\ \mbox{Operating Temperature} & 0^{\circ}C \leq TA \leq +70^{\circ}C \mbox{ for commercial} \\ -40^{\circ}C \leq TA \leq +85^{\circ}C \mbox{ for industrial} \\ -40^{\circ}C \leq TA \leq +125^{\circ}C \mbox{ for extended} \end{array} $								
Param No.	Symbol	Characteristic	Min	Тур†	Мах	Units	Conditions			
30	TmcL	MCLR Pulse Width (low)	1000*		_	ns	VDD = 5.0V			
31	Twdt	Watchdog Timer Time-out Period (No Prescaler)	9.0*	18*	30*	ms	VDD = 5.0V (Comm)			
32	Tdrt	Device Reset Timer Period	9.0*	18*	30*	ms	VDD = 5.0V (Comm)			
34	Tioz	I/O Hi-impedance from MCLR Low	100*	300*	1000*	ns				

* These parameters are characterized but not tested.

† Data in the Typical ("Typ") column is at 5V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

FIGURE 17-9: TIMER0 CLOCK TIMINGS - PIC16C5X, PIC16CR5X



TABLE 17-4: TIMER0 CLOCK REQUIREMENTS - PIC16C5X, PIC16CR5X

ļ	AC Chara	cteristics Standard Operatin Operating Temperat	$\begin{array}{ll} \mbox{dard Operating Conditions (unless otherwise specified)} \\ \mbox{ating Temperature} & 0^\circ C \leq TA \leq +70^\circ C \mbox{ for commercial} \\ -40^\circ C \leq TA \leq +85^\circ C \mbox{ for industrial} \\ -40^\circ C \leq TA \leq +125^\circ C \mbox{ for extended} \end{array}$							
Param No.	Symbol	Characteristic	Min	Тур†	Max	Units	Conditions			
40	Tt0H	T0CKI High Pulse Width - No Prescaler	0.5 Tcy + 20*		_	ns				
		- With Prescaler	10*	_	—	ns				
41	TtOL	T0CKI Low Pulse Width - No Prescaler	0.5 Tcy + 20*	_	_	ns				
		- With Prescaler	10*	_	_	ns				
42	Tt0P	T0CKI Period	20 or <u>Tcy + 40</u> * N	_		ns	Whichever is greater. N = Prescale Value (1, 2, 4,, 256)			

These parameters are characterized but not tested.

† Data in the Typical ("Typ") column is at 5V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.
18.0 DEVICE CHARACTERIZATION - PIC16LC54A

The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only. The performance characteristics listed herein are not tested or guaranteed. In some graphs or tables, the data presented may be outside the specified operating range (e.g., outside specified power supply range) and therefore outside the warranted range.

"Typical" represents the mean of the distribution at 25°C. "Maximum" or "minimum" represents (mean + 3σ) or (mean - 3σ) respectively, where σ is a standard deviation, over the whole temperature range.



FIGURE 18-1: TYPICAL RC OSCILLATOR FREQUENCY vs. TEMPERATURE

TABLE 18-1: RC OSCILLATOR FREQUENCIES

Сехт	Rext	Average Fosc @ 5V, 25°C		
20 pF	3.3K	5 MHz	± 27%	
	5K	3.8 MHz	± 21%	
	10K	2.2 MHz	± 21%	
	100K	262 kHz	± 31%	
100 pF	3.3K	1.63 MHz	± 13%	
	5K	1.2 MHz	± 13%	
	10K	684 kHz	± 18%	
	100K	71 kHz	± 25%	
300 pF	3.3K	660 kHz	± 10%	
	5.0K	484 kHz	± 14%	
	10K	267 kHz	± 15%	
	100K	29 kHz	± 19%	

The frequencies are measured on DIP packages.

The percentage variation indicated here is part-to-part variation due to normal process distribution. The variation indicated is ± 3 standard deviation from average value for VDD = 5V.



FIGURE 18-2: TYPICAL RC OSCILLATOR FREQUENCY vs. VDD, CEXT = 20 PF, 25°C







FIGURE 18-4: TYPICAL RC OSCILLATOR FREQUENCY vs. VDD, CEXT = 300 PF, 25°C





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PIC16C5X

FIGURE 18-10: VTH (INPUT THRESHOLD TRIP POINT VOLTAGE) OF OSC1 INPUT (IN XT, HS AND LP MODES) vs. VDD









FIGURE 18-12: TYPICAL IDD vs. FREQUENCY (WDT DISABLED, RC MODE @ 100 PF, 25°C)











FIGURE 18-17: PORTA, B AND C IOL vs. Vol, VDD = 3 V





TABLE 18-2:INPUT CAPACITANCE

Pin	Typical Capacitance (pF)				
Pin	18L PDIP	18L SOIC			
RA port	5.0	4.3			
RB port	5.0	4.3			
MCLR	17.0	17.0			
OSC1	4.0	3.5			
OSC2/CLKOUT	4.3	3.5			
тоскі	3.2	2.8			

All capacitance values are typical at 25° C. A part-to-part variation of ±25% (three standard deviations) should be taken into account.

19.0 ELECTRICAL CHARACTERISTICS - PIC16LC54C 40MHz

Absolute Maximum Ratings^(†)

Ambient temperature under bias55°C to +125°	°C
Storage temperature	
Voltage on VDD with respect to Vss0 to +7.5	5V
Voltage on MCLR with respect to Vss0 to +14	1V
Voltage on all other pins with respect to Vss0.6V to (VDD + 0.6	
Total power dissipation ⁽¹⁾	
Max. current out of Vss pin	۱A
Max. current into Vod pin	
Max. current into an input pin (T0CKI only)±500 μ	ιA
Input clamp current, Iiк (Vi <0 or Vi > VDD)±20 m	۱A
Output clamp current, IOK (VO < 0 or VO > VDD)	۱A
Max. output current sunk by any I/O pin25 m	۱A
Max. output current sourced by any I/O pin20 m	۱A
Max. output current sourced by a single I/O (Port A, B or C)50 m	۱A
Max. output current sunk by a single I/O (Port A, B or C)	۱A
Note 1: Power dissipation is calculated as follows: Pdis = VDD x {IDD - Σ IOH} + Σ {(VDD-VOH) x IOH} + Σ (VOL x IO	L)

† NOTICE: Stresses above those listed under "Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operation listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

PIC16C5X

FIGURE 19-1: PIC16C54C/C55A/C56A/C57C/C58B-40 VOLTAGE-FREQUENCY GRAPH, $0^{\circ}C \le T_A \le +70^{\circ}C$





- **2:** The maximum rated speed of the part limits the permissible combinations of voltage and frequency. Please reference the Product Identification System section for the maximum rated speed of the parts.
- **3:** Operation between 20 to 40 MHz requires the following:
 - VDD between 4.5V. and 5.5V
 - OSC1 externally driven
 - OSC2 not connected
 - HS mode
 - Commercial temperatures

Devices qualified for 40 MHz operation have -40 designation (ex: PIC16C54C-40/P).

4: For operation between DC and 20 MHz, see Section 17.1.

19.1 DC Characteristics:PIC16C54C/C55A/C56A/C57C/C58B-40 (Commercial)⁽¹⁾

PIC16C54C/C55A/C56A/C57C/C58B-40 (Commercial)				ard Ope ing Tem	-		itions (unless otherwise specified) $0^{\circ}C \le TA \le +70^{\circ}C$ for commercial	
Param No.	Symbol	Characteristic	Min	Тур†	Max	Units	Conditions	
D001	Vdd	Supply Voltage	4.5	-	5.5	V	HS mode from 20 - 40 MHz	
D002	Vdr	RAM Data Retention Voltage ⁽²⁾		1.5*	—	V	Device in SLEEP mode	
D003	VPOR	VDD Start Voltage to ensure Power-on Reset	—	Vss	—	V	See Section 5.1 for details on Power-on Reset	
D004	SVDD	VDD Rise Rate to ensure Power- on Reset	0.05*	_	—	V/ms	See Section 5.1 for details on Power-on Reset	
D010	Idd	Supply Current ⁽³⁾	_	5.2 6.8	12.3 16	mA mA	Fosc = 40 MHz, VDD = 4.5V, HS mode Fosc = 40 MHz, VDD = 5.5V, HS mode	
D020	IPD	Power-down Current ⁽³⁾	_	1.8 9.8	7.0 27*	μΑ μΑ	VDD = 5.5V, WDT disabled, Commercial VDD = 5.5V, WDT enabled, Commercial	

* These parameters are characterized but not tested.

† Data in the Typical ("Typ") column is based on characterization results at 25°C. This data is for design guidance only and is not tested.

- **Note 1:** Device operation between 20 MHz to 40 MHz requires the following: VDD between 4.5V to 5.5V, OSC1 pin externally driven, OSC2 pin not connected, HS oscillator mode and commercial temperatures. For operation between DC and 20 MHz, See Section 19.1.
 - **2:** This is the limit to which VDD can be lowered in SLEEP mode without losing RAM data.
 - **3:** The supply current is mainly a function of the operating voltage and frequency. Other factors such as bus loading, oscillator type, bus rate, internal code execution pattern and temperature also have an impact on the current consumption.
 - a) The test conditions for all IDD measurements in active Operation mode are: OSC1 = external square wave, from rail-to-rail; all I/O pins tristated, pulled to Vss, T0CKI = VDD, MCLR = VDD; WDT enabled/disabled as specified.
 - b) For standby current measurements, the conditions are the same, except that the device is in SLEEP mode. The power-down current in SLEEP mode does not depend on the oscillator type.

19.2 DC Characteristics: PIC16C54C/C55A/C56A/C57C/C58B-40 (Commercial)⁽¹⁾

DC CH	ARACTER	RISTICS	Standard Operating Conditions (unless otherwise specified)Operating Temperature $0^{\circ}C \le TA \le +70^{\circ}C$ for commercial				
Param No.	Symbol	Characteristic	Min	Тур†	Max	Units	Conditions
D030	VIL	Input Low Voltage I/O Ports MCLR (Schmitt Trigger) T0CKI (Schmitt Trigger) OSC1	Vss Vss Vss Vss		0.8 0.15 VDD 0.15 VDD 0.2 VDD	> > > >	4.5V <vdd <math="">\leq 5.5V HS, 20 MHz \leq Fosc \leq 40 MHz</vdd>
D040	Viн	Input High Voltage I/O ports MCLR (Schmitt Trigger) T0CKI (Schmitt Trigger) OSC1	2.0 0.85 Vdd 0.85 Vdd 0.85 Vdd 0.8 Vdd		Vdd Vdd Vdd Vdd	V V V V	$4.5V < VDD \le 5.5V$ HS, 20 MHz \le Fosc \le 40 MHz
D050	VHYS	Hysteresis of Schmitt Trigger inputs	0.15 Vdd*	—	_	V	
D060	lı∟	Input Leakage Current ^(2,3) I/O ports MCLR MCLR T0CKI OSC1	-1.0 -5.0 -3.0 -3.0	0.5 — 0.5 0.5 0.5	+1.0 +5.0 +3.0 +3.0 —	μΑ μΑ μΑ μΑ μΑ	For VDD \leq 5.5V: VSS \leq VPIN \leq VDD, pin at hi-impedance VPIN = VSS +0.25V VPIN = VDD VSS \leq VPIN \leq VDD VSS \leq VPIN \leq VDD, HS
D080	Vol	Output Low Voltage I/O ports		_	0.6	V	Iol = 8.7 mA, Vdd = 4.5V
D090	Vон	Output High Voltage⁽³⁾ I/O ports	Vdd - 0.7	_	_	V	Іон = -5.4 mA, Vdd = 4.5V

These parameters are characterized but not tested.

† Data in the Typical ("Typ") column is based on characterization results at 25°C. This data is for design guidance only and is not tested.

Note 1: Device operation between 20 MHz to 40 MHz requires the following: VDD between 4.5V to 5.5V, OSC1 pin externally driven, OSC2 pin not connected and HS oscillator mode and commercial temperatures. For operation between DC and 20 MHz, See Section 17.3.

2: The leakage current on the MCLR/VPP pin is strongly dependent on the applied voltage level. The specified levels represent normal operating conditions. Higher leakage current may be measured at different input voltage.

3: Negative current is defined as coming out of the pin.

19.3 Timing Parameter Symbology and Load Conditions

The timing parameter symbols have been created with one of the following formats:

1. TppS2ppS

2. Tp	pS	
Т		
F	Frequency	T Time
Lowe	ercase letters (pp) and their meanings:	
рр		
2	to	mc MCLR
ck	CLKOUT	osc oscillator
су	cycle time	os OSC1
drt	device reset timer	t0 T0CKI
io	I/O port	wdt watchdog timer
Uppe	ercase letters and their meanings:	
S		
F	Fall	P Period
н	High	R Rise
Ι	Invalid (Hi-impedance)	V Valid
L	Low	Z Hi-impedance

FIGURE 19-2: LOAD CONDITIONS FOR DEVICE TIMING SPECIFICATIONS -PIC16C54C/C55A/C56A/C57C/C58B-40



19.4 **Timing Diagrams and Specifications**



FIGURE 19-3: EXTERNAL CLOCK TIMING - PIC16C5X-40

EXTERNAL CLOCK TIMING REQUIREMENTS - PIC16C5X-40 TABLE 19-1:

AC Chara	cteristics	stics Standard Operating Conditions (unless otherwise specified) Operating Temperature $0^{\circ}C \le TA \le +70^{\circ}C$ for commercial						
Param No.	Symbol	Characteristic	Min	Тур†	Max Units		Conditions	
	Fosc	External CLKIN Frequency ⁽¹⁾	20	_	40	MHz	HS osc mode	
1	Tosc	External CLKIN Period ⁽¹⁾	25	_	_	ns	HS OSC mode	
2	Тсу	Instruction Cycle Time ⁽²⁾	_	4/Fosc	_	—		
3	TosL, TosH	Clock in (OSC1) Low or High Time	6.0*	_	_	ns	HS oscillator	
4	TosR, TosF	Clock in (OSC1) Rise or Fall Time	—	_	6.5*	ns	HS oscillator	

- * These parameters are characterized but not tested.
- † Data in the Typical ("Typ") column is at 5V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.
- Note 1: All specified values are based on characterization data for that particular oscillator type under standard operating conditions with the device executing code. Exceeding these specified limits may result in an unstable oscillator operation and/or higher than expected current consumption. When an external clock input is used, the "max" cycle time limit is "DC" (no clock) for all devices.

 - 2: Instruction cycle period (TCY) equals four times the input oscillator time base period.



TABLE 19-2:	CLKOUT AND I/O TIMING REQUIREMENTS - PIC16C5X-40

$ \begin{tabular}{lllllllllllllllllllllllllllllllllll$						
Param No.	Symbol	Characteristic	Min	Тур†	Max	Units
10	TosH2ckL	OSC1↑ to CLKOUT↓ ^(1,2)	—	15	30**	ns
11	TosH2ckH	OSC1↑ to CLKOUT↑ ^(1,2)	—	15	30**	ns
12	TckR	CLKOUT rise time ^(1,2)	—	5.0	15**	ns
13	TckF	CLKOUT fall time ^(1,2)	—	5.0	15**	ns
14	TckL2ioV	CLKOUT↓ to Port out valid ^(1,2)	—	—	40**	ns
15	TioV2ckH	Port in valid before CLKOUT ^(1,2)	0.25 TCY+30*	—	_	ns
16	TckH2iol	Port in hold after CLKOUT ^(1,2)	0*	—	_	ns
17	TosH2ioV	OSC1 [↑] (Q1 cycle) to Port out valid ⁽²⁾	—	—	100	ns
18	TosH2iol	OSC1 [↑] (Q2 cycle) to Port input invalid (I/O in hold time)	TBD	—	—	ns
19	TioV2osH	Port input valid to OSC1↑ (I/O in setup time)	TBD	—	—	ns
20	TioR	Port output rise time ⁽²⁾	—	10	25**	ns
21	TioF	Port output fall time ⁽²⁾	—	10	25**	ns

* These parameters are characterized but not tested.

- ** These parameters are design targets and are not tested. No characterization data available at this time.
- † Data in the Typical ("Typ") column is at 5V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

Note 1: Measurements are taken in RC Mode where CLKOUT output is 4 x Tosc.

2: Refer to Figure 19-2 for load conditions.

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FIGURE 19-5: RESET, WATCHDOG TIMER, AND DEVICE RESET TIMER TIMING - PIC16C5X-40

TABLE 19-3: RESET, WATCHDOG TIMER, AND DEVICE RESET TIMER - PIC16C5X-40

AC Charac	teristics	Standard Operating Conditions (unless otherwise specified)Operating Temperature $0^{\circ}C \le TA \le +70^{\circ}C$ (commercial)Operating Voltage VDD range is described in Section 19.1.						
Param No.	Symbol	Characteristic	Min	Тур†	Max	Units	Conditions	
30	TmcL	MCLR Pulse Width (low)	1000*	_	_	ns	VDD = 5.0V	
31	Twdt	Watchdog Timer Time-out Period (No Prescaler)	9.0*	18*	30*	ms	VDD = 5.0V (Comm)	
32	Tdrt	Device Reset Timer Period	9.0*	18*	30*	ms	VDD = 5.0V (Comm)	
34	Tioz	I/O Hi-impedance from MCLR Low	100*	300*	1000*	ns		

* These parameters are characterized but not tested.

† Data in the Typical ("Typ") column is at 5V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

FIGURE 19-6: TIMER0 CLOCK TIMINGS - PIC16C5X-40



TABLE 19-4: TIMER0 CLOCK REQUIREMENTS PIC16C5X-40

$\begin{tabular}{lllllllllllllllllllllllllllllllllll$							
Param No.	Symbol	Characteristic	Min	Тур†	Max	Units	Conditions
40	Tt0H	T0CKI High Pulse Width					
		- No Prescaler	0.5 TCY + 20*	—		ns	
		- With Prescaler	10*		—	ns	
41	Tt0L	T0CKI Low Pulse Width					
		- No Prescaler	0.5 TCY + 20*	—		ns	
		- With Prescaler	10*	_		ns	
42	Tt0P	T0CKI Period	20 or <u>Tcy + 40</u> * N	_	_	ns	Whichever is greater. N = Prescale Value (1, 2, 4,, 256)

* These parameters are characterized but not tested.

† Data in the Typical ("Typ") column is at 5V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested. NOTES:

20.0 DEVICE CHARACTERIZATION - PIC16LC54C 40MHz

The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only. The performance characteristics listed herein are not tested or guaranteed. In some graphs or tables, the data presented may be outside the specified operating range (e.g., outside specified power supply range) and therefore outside the warranted range.

"Typical" represents the mean of the distribution at 25°C. "Maximum" or "minimum" represents (mean + 3σ) or (mean - 3σ) respectively, where σ is a standard deviation, over the whole temperature range.





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FIGURE 20-4: VTH (INPUT THRESHOLD TRIP POINT VOLTAGE) OF I/O PINS vs. VDD



FIGURE 20-5: VTH (INPUT THRESHOLD TRIP POINT VOLTAGE) OF OSC1 INPUT (HS MODE) vs. VDD



PIC16C5X





TABLE 20-1: INPUT CAPACITANCE

Pin	Typical Capacitance (pF)				
FIII	18L PDIP	18L SOIC			
RA port	5.0	4.3			
RB port	5.0	4.3			
MCLR	17.0	17.0			
OSC1	4.0	3.5			
OSC2/CLKOUT	4.3	3.5			
тоскі	3.2	2.8			

All capacitance values are typical at 25° C. A part-to-part variation of ±25% (three standard deviations) should be taken into account.



FIGURE 20-9: IOL vs. VOL, VDD = 5 V



21.0 PACKAGING INFORMATION

21.1 Package Marketing Information

18-Lead PDIP



28-Lead Skinny PDIP (.300")



28-Lead PDIP (.600")



18-Lead SOIC



28-Lead SOIC



20-Lead SSOP



28-Lead SSOP





Example



Example



Example



Example



Example



Example



Package Marking Information (Cont'd)

18-Lead CERDIP Windowed

	XXXXXXXX XXXXXXXX YYWWNNN
--	---------------------------------

28-Lead CERDIP Windowed



Example



Example



Legen	d: XXX Y YY WW NNN @3 *	Customer-specific information Year code (last digit of calendar year) Year code (last 2 digits of calendar year) Week code (week of January 1 is week '01') Alphanumeric traceability code Pb-free JEDEC designator for Matte Tin (Sn) This package is Pb-free. The Pb-free JEDEC designator (e3) can be found on the outer packaging for this package.
Note:	be carrie	nt the full Microchip part number cannot be marked on one line, it will d over to the next line, thus limiting the number of available s for customer-specific information.

18-Lead Plastic Dual In-line (P) – 300 mil (PDIP)

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	Units		INCHES*			MILLIMETERS		
Dimensio	n Limits	MIN	NOM	MAX	MIN	NOM	MAX	
Number of Pins	n		18			18		
Pitch	р		.100			2.54		
Top to Seating Plane	А	.140	.155	.170	3.56	3.94	4.32	
Molded Package Thickness	A2	.115	.130	.145	2.92	3.30	3.68	
Base to Seating Plane	A1	.015			0.38			
Shoulder to Shoulder Width	E	.300	.313	.325	7.62	7.94	8.26	
Molded Package Width	E1	.240	.250	.260	6.10	6.35	6.60	
Overall Length	D	.890	.898	.905	22.61	22.80	22.99	
Tip to Seating Plane	L	.125	.130	.135	3.18	3.30	3.43	
Lead Thickness	С	.008	.012	.015	0.20	0.29	0.38	
Upper Lead Width	B1	.045	.058	.070	1.14	1.46	1.78	
Lower Lead Width	В	.014	.018	.022	0.36	0.46	0.56	
Overall Row Spacing §	eB	.310	.370	.430	7.87	9.40	10.92	
Mold Draft Angle Top	α	5	10	15	5	10	15	
Mold Draft Angle Bottom	β	5	10	15	5	10	15	

* Controlling Parameter § Significant Characteristic

Notes:

n

Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" (0.254mm) per side. JEDEC Equivalent: MS-001 Drawing No. C04-007

28-Lead Skinny Plastic Dual In-line (SP) - 300 mil (PDIP)





в

	Units		INCHES*		MILLIMETERS		
Dimensi	Dimension Limits			MAX	MIN	NOM	MAX
Number of Pins	n		28			28	
Pitch	р		.100			2.54	
Top to Seating Plane	А	.140	.150	.160	3.56	3.81	4.06
Molded Package Thickness	A2	.125	.130	.135	3.18	3.30	3.43
Base to Seating Plane	A1	.015			0.38		
Shoulder to Shoulder Width	Е	.300	.310	.325	7.62	7.87	8.26
Molded Package Width	E1	.275	.285	.295	6.99	7.24	7.49
Overall Length	D	1.345	1.365	1.385	34.16	34.67	35.18
Tip to Seating Plane	L	.125	.130	.135	3.18	3.30	3.43
Lead Thickness	С	.008	.012	.015	0.20	0.29	0.38
Upper Lead Width	B1	.040	.053	.065	1.02	1.33	1.65
Lower Lead Width	В	.016	.019	.022	0.41	0.48	0.56
Overall Row Spacing	§ eB	.320	.350	.430	8.13	8.89	10.92
Mold Draft Angle Top	α	5	10	15	5	10	15
Mold Draft Angle Bottom	β	5	10	15	5	10	15

* Controlling Parameter § Significant Characteristic

eВ

Dimension D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed

.010" (0.254mm) per side.

JEDEC Equivalent: MO-095

Drawing No. C04-070

- p -

Notes:

28-Lead Plastic Dual In-line (P) - 600 mil (PDIP)

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	Units		INCHES*		MILLIMETERS			
Dimer	ision Limits	MIN	NOM	MAX	MIN	NOM	MAX	
Number of Pins	n		28			28		
Pitch	р		.100			2.54		
Top to Seating Plane	А	.160	.175	.190	4.06	4.45	4.83	
Molded Package Thickness	A2	.140	.150	.160	3.56	3.81	4.06	
Base to Seating Plane	A1	.015			0.38			
Shoulder to Shoulder Width	E	.595	.600	.625	15.11	15.24	15.88	
Molded Package Width	E1	.505	.545	.560	12.83	13.84	14.22	
Overall Length	D	1.395	1.430	1.465	35.43	36.32	37.21	
Tip to Seating Plane	L	.120	.130	.135	3.05	3.30	3.43	
Lead Thickness	С	.008	.012	.015	0.20	0.29	0.38	
Upper Lead Width	B1	.030	.050	.070	0.76	1.27	1.78	
Lower Lead Width	В	.014	.018	.022	0.36	0.46	0.56	
Overall Row Spacing	§ eB	.620	.650	.680	15.75	16.51	17.27	
Mold Draft Angle Top	α	5	10	15	5	10	15	
Mold Draft Angle Bottom	β	5	10	15	5	10	15	

* Controlling Parameter § Significant Characteristic

Notes:

Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" (0.254mm) per side.

JEDEC Equivalent: MO-011 Drawing No. C04-079

18-Lead Plastic Small Outline (SO) - Wide, 300 mil (SOIC)

For the most current package drawings, please see the Microchip Packaging Specification located Note: at http://www.microchip.com/packaging



	Units		INCHES*			MILLIMETERS		
Dimensi	on Limits	MIN	NOM	MAX	MIN	NOM	MAX	
Number of Pins	n		18			18		
Pitch	р		.050			1.27		
Overall Height	А	.093	.099	.104	2.36	2.50	2.64	
Molded Package Thickness	A2	.088	.091	.094	2.24	2.31	2.39	
Standoff §	A1	.004	.008	.012	0.10	0.20	0.30	
Overall Width	E	.394	.407	.420	10.01	10.34	10.67	
Molded Package Width	E1	.291	.295	.299	7.39	7.49	7.59	
Overall Length	D	.446	.454	.462	11.33	11.53	11.73	
Chamfer Distance	h	.010	.020	.029	0.25	0.50	0.74	
Foot Length	L	.016	.033	.050	0.41	0.84	1.27	
Foot Angle	φ	0	4	8	0	4	8	
Lead Thickness	С	.009	.011	.012	0.23	0.27	0.30	
Lead Width	В	.014	.017	.020	0.36	0.42	0.51	
Mold Draft Angle Top	α	0	12	15	0	12	15	
Mold Draft Angle Bottom	β	0	12	15	0	12	15	

* Controlling Parameter § Significant Characteristic

Notes:

Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" (0.254mm) per side. JEDEC Equivalent: MS-013 Drawing No. C04-051

28-Lead Plastic Small Outline (SO) - Wide, 300 mil (SOIC)

For the most current package drawings, please see the Microchip Packaging Specification located Note: at http://www.microchip.com/packaging







	Units		INCHES*		MILLIMETERS		
Dimensi	on Limits	MIN	NOM	MAX	MIN	NOM	MAX
Number of Pins	n		28			28	
Pitch	р		.050			1.27	
Overall Height	Α	.093	.099	.104	2.36	2.50	2.64
Molded Package Thickness	A2	.088	.091	.094	2.24	2.31	2.39
Standoff §	A1	.004	.008	.012	0.10	0.20	0.30
Overall Width	Е	.394	.407	.420	10.01	10.34	10.67
Molded Package Width	E1	.288	.295	.299	7.32	7.49	7.59
Overall Length	D	.695	.704	.712	17.65	17.87	18.08
Chamfer Distance	h	.010	.020	.029	0.25	0.50	0.74
Foot Length	L	.016	.033	.050	0.41	0.84	1.27
Foot Angle Top	¢	0	4	8	0	4	8
Lead Thickness	С	.009	.011	.013	0.23	0.28	0.33
Lead Width	В	.014	.017	.020	0.36	0.42	0.51
Mold Draft Angle Top	α	0	12	15	0	12	15
Mold Draft Angle Bottom	β	0	12	15	0	12	15

* Controlling Parameter § Significant Characteristic

Notes:

Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" (0.254mm) per side. JEDEC Equivalent: MS-013 Drawing No. C04-052

20-Lead Plastic Shrink Small Outline (SS) - 209 mil, 5.30 mm (SSOP)

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	Units INCHES*			MILLIMETERS			
Dimensio	on Limits	MIN	NOM	MAX	MIN	NOM	MAX
Number of Pins	n		20			20	
Pitch	р		.026			0.65	
Overall Height	Α	.068	.073	.078	1.73	1.85	1.98
Molded Package Thickness	A2	.064	.068	.072	1.63	1.73	1.83
Standoff §	A1	.002	.006	.010	0.05	0.15	0.25
Overall Width	Е	.299	.309	.322	7.59	7.85	8.18
Molded Package Width	E1	.201	.207	.212	5.11	5.25	5.38
Overall Length	D	.278	.284	.289	7.06	7.20	7.34
Foot Length	L	.022	.030	.037	0.56	0.75	0.94
Lead Thickness	С	.004	.007	.010	0.10	0.18	0.25
Foot Angle	ф	0	4	8	0.00	101.60	203.20
Lead Width	В	.010	.013	.015	0.25	0.32	0.38
Mold Draft Angle Top	α	0	5	10	0	5	10
Mold Draft Angle Bottom	β	0	5	10	0	5	10

* Controlling Parameter

§ Significant Characteristic

Notes:

Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" (0.254mm) per side. JEDEC Equivalent: MO-150 Drawing No. C04-072

28-Lead Plastic Shrink Small Outline (SS) - 209 mil, 5.30 mm (SSOP)

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging









	Units		INCHES			MILLIMETERS*		
Dimensio	MIN	NOM	MAX	MIN	NOM	MAX		
Number of Pins	n		28			28		
Pitch	р		.026			0.65		
Overall Height	Α	.068	.073	.078	1.73	1.85	1.98	
Molded Package Thickness	A2	.064	.068	.072	1.63	1.73	1.83	
Standoff §	A1	.002	.006	.010	0.05	0.15	0.25	
Overall Width	E	.299	.309	.319	7.59	7.85	8.10	
Molded Package Width	E1	.201	.207	.212	5.11	5.25	5.38	
Overall Length	D	.396	.402	.407	10.06	10.20	10.34	
Foot Length	L	.022	.030	.037	0.56	0.75	0.94	
Lead Thickness	С	.004	.007	.010	0.10	0.18	0.25	
Foot Angle	¢	0	4	8	0.00	101.60	203.20	
Lead Width	В	.010	.013	.015	0.25	0.32	0.38	
Mold Draft Angle Top	α	0	5	10	0	5	10	
Mold Draft Angle Bottom	β	0	5	10	0	5	10	

* Controlling Parameter § Significant Characteristic

Notes:

Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" (0.254mm) per side.

JEDEC Equivalent: MS-150 Drawing No. C04-073

18-Lead Ceramic Dual In-line with Window (JW) - 300 mil (CERDIP)

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	Units			INCHES*			MILLIMETERS		
Dimensior	n Limits	MIN	NOM	MAX	MIN	NOM	MAX		
Number of Pins	n		18			18			
Pitch	р		.100			2.54			
Top to Seating Plane	А	.170	.183	.195	4.32	4.64	4.95		
Ceramic Package Height	A2	.155	.160	.165	3.94	4.06	4.19		
Standoff	A1	.015	.023	.030	0.38	0.57	0.76		
Shoulder to Shoulder Width	Е	.300	.313	.325	7.62	7.94	8.26		
Ceramic Pkg. Width	E1	.285	.290	.295	7.24	7.37	7.49		
Overall Length	D	.880	.900	.920	22.35	22.86	23.37		
Tip to Seating Plane	L	.125	.138	.150	3.18	3.49	3.81		
Lead Thickness	С	.008	.010	.012	0.20	0.25	0.30		
Upper Lead Width	B1	.050	.055	.060	1.27	1.40	1.52		
Lower Lead Width	В	.016	.019	.021	0.41	0.47	0.53		
Overall Row Spacing §	eВ	.345	.385	.425	8.76	9.78	10.80		
Window Width	W1	.130	.140	.150	3.30	3.56	3.81		
Window Length	W2	.190	.200	.210	4.83	5.08	5.33		

* Controlling Parameter § Significant Characteristic JEDEC Equivalent: MO-036

Drawing No. C04-010
28-Lead Ceramic Dual In-line with Window (JW) - 600 mil (CERDIP)

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	Units	INCHES*		MILLIMETERS			
Dimensior	Limits	MIN	NOM	MAX	MIN	NOM	MAX
Number of Pins	n		28			28	
Pitch	р		.100			2.54	
Top to Seating Plane	Α	.195	.210	.225	4.95	5.33	5.72
Ceramic Package Height	A2	.155	.160	.165	3.94	4.06	4.19
Standoff	A1	.015	.038	.060	0.38	0.95	1.52
Shoulder to Shoulder Width	Е	.595	.600	.625	15.11	15.24	15.88
Ceramic Pkg. Width	E1	.514	.520	.526	13.06	13.21	13.36
Overall Length	D	1.430	1.460	1.490	36.32	37.08	37.85
Tip to Seating Plane	L	.125	.138	.150	3.18	3.49	3.81
Lead Thickness	С	.008	.010	.012	0.20	0.25	0.30
Upper Lead Width	B1	.050	.058	.065	1.27	1.46	1.65
Lower Lead Width	В	.016	.020	.023	0.41	0.51	0.58
Overall Row Spacing §	eB	.610	.660	.710	15.49	16.76	18.03
Window Diameter	W	.270	.280	.290	6.86	7.11	7.37

Sontolling Parameter
 Significant Characteristic
 JEDEC Equivalent: MO-103
 Drawing No. C04-013

APPENDIX A: COMPATIBILITY

To convert code written for PIC16CXX to PIC16C5X, the user should take the following steps:

- 1. Check any CALL, GOTO or instructions that modify the PC to determine if any program memory page select operations (PA2, PA1, PA0 bits) need to be made.
- 2. Revisit any computed jump operations (write to PC or add to PC, etc.) to make sure page bits are set properly under the new scheme.
- 3. Eliminate any special function register page switching. Redefine data variables to reallocate them.
- 4. Verify all writes to STATUS, OPTION, and FSR registers since these have changed.
- 5. Change RESET vector to proper value for processor used.
- 6. Remove any use of the ADDLW, RETURN and SUBLW instructions.
- 7. Rewrite any code segments that use interrupts.

APPENDIX B: REVISION HISTORY

Revision KE (January 2013)

Added a note to each package outline drawing.

PIC16C5X

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PART NO.	- <u>xx</u>	Ť	<u>/xx</u>	<u>xxx</u>	Exa	mple	s:
Device	Frequency Range/OSC Type PIC16C54 PIC16C54A PIC16C54C PIC16C55A PIC16C56 PIC16C56A PIC16C56A PIC16C56A PIC16C57C PIC16C57C PIC16C58B PIC16C58B	PIC16C54T PIC16C54T PIC16C54AT PIC16C54AT PIC16C554C PIC16C55T PIC16C55T PIC16C55AT PIC16C55AT PIC16C55AT PIC16C55AT PIC16C57CT PIC16C57CT PIC16C57CT PIC16C57CT PIC16C57CT PIC16C578BT PIC16C58BT	$\begin{array}{c} (2) \\ (1) \\ (2) \\$	Pattern	a) b) c) d)	PDIP QTP PIC10 packa PIC10 cial te dard PIC1 temp MHz #123	6C55A - 04/P 301 = Commercial Temp., package, 4 MHz, standard VDD limits, pattern #301 6LC54C - 04I/SO Industrial Temp., SOIC age, 200 kHz, extended VDD limits 6C57 - RC/SP = RC Oscillator, commer- emp, skinny PDIP package, 4 MHz, stan- VDD limits 6C58BT -40/SS 123 = commercial b, SSOP package in tape and reel, 4 , extended VDD limits, ROM pattern c C = normal voltage range LC = extended
Frequency Range/ Oscillator Type	04 200 KHz (LI 10 10 MHz (HS 20 20 MHz (HS 50 40 MHz (HS 50 MHz (HS	Crystal ystal/Resonator Crystal P) or 2 MHz (XT an 9) or 4 MHz (XT an 6 only) 6 only) 6 only) 7 type for JW packat re for 16C54/55/56	d RC) ages ⁽³⁾ /57 devices on all other device	5		3:	T = in tape and reel - SOIC and SSOP packages only JW Devices are UV erasable and can be programmed to any device configura- tion. JW Devices meet the electrical requirements of each oscillator type, including LC devices. b = Blank
Temperature Range	$b^{(4)} = 0^{\circ}C$ $I = -40^{\circ}C$ $E = -40^{\circ}C$	to +85°C					
Package	JW = 28-pin DIP ⁽³⁾ P = 28-pin SO = 300 m SS = 209 m SP = 28-pin	Waffle Pack 600 mil/18-pin 30(il SOIC il SSOP 300 mil Skinny PE for additional packa) mil PDIP DIP				
Pattern		/l code (factory spe lank for OTP and V					

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